Scheme and Syllabus

of

B. Tech. VLSI Design and Technology

(2024-2025 onwards)



Offered by:

Department of Electronics & Communication Engineering

NATIONAL INSTITUTE OF TECHNOLOGY DELHI

Delhi-110036, INDIA

(An autonomous Institute under the aegis of Ministry of Education, Govt. of India)

*Approved in the 3rd Meeting of Board of Studies of the Dept. of ECE, held on February 23, 2024, further in line with the recommendation of the 4th Meeting of Board of Studies of the Dept. of ECE held on January 17, 2025 and finally in line with the recommendation of the Honourable Senate in the 18th Senate Meeting held on February 12, 2025.

Department of Electronics and Communications Engineering National Institute of Technology Delhi

1.1 About the Department

Department of Electronics and Communication Engineering (ECE), National Institute of Technology Delhi was established in 2010, immediately with the beginning of the Institute under the aegis of the Ministry of Human Resource and Development (MHRD), Govt. of India. Currently, the Department offers two Undergraduate Programs B. Tech (ECE) & B. Tech (VLSI Design and Technology). The department offers two postgraduate programs, one of which is M. Tech. ECE and the other is M. Tech. ECE (VLSI). The Department also offers a Ph.D. and Post-Doctoral Fellowship (PDF) Programme in relevant areas. The department has excellent laboratories and research facilities in electronic devices and circuits, electronic measurement and instrumentation, microprocessor and microcontroller, microwave and antenna design, VLSI design, optical fibre and optical devices, multimedia, and advanced communication and design automation and simulation laboratory. The Department has received projects, grants, and fellowships from the Ministry of Electronics and Information Technology (MeitY), the Department of Science and Technology (DST)-SERB, and other funding agencies. The Department has active collaborations with academic Institutes & research institutes in India and abroad.

The Department of ECE has a blend of young and experienced dynamic faculty members and is committed to providing quality education and research in the field. Faculty members of the department have excellent academic & research credentials and have published numerous peer-reviewed journal articles/papers, Books, Book Chapters, etc., in the diversified field and have adequate experience in advanced research. The department of ECE provides a creative learning environment for students to excel in technical education. Here, the students learn to face the challenges related to emerging technologies in electronics and communication engineering. The department of ECE promotes a self-learning attitude, entrepreneurial skills, and professional ethics. The department hopes to achieve the national goals and objectives of industrialization and self-reliance. As a result, it hopes to produce graduates with strong academic and practical backgrounds so that they can fit into the industry immediately upon graduation.

1.2 Vision

Create an educational environment to prepare the students to meet the challenges of the modern electronics and communication industry through state-of-the-art technical knowledge and innovative approaches beneficial to society.

1.3 Mission

- To promote teaching and learning by engaging in innovative research and offering state-ofthe-art undergraduate, postgraduate, and doctoral programs.
- To cultivate an entrepreneurial environment and industry interaction, leading to the emergence of creators, innovators, and leaders.
- To promote co-curricular and extra-curricular activities for the overall personality development of the students.
- Building of responsible citizens through awareness and acceptance of ethical values.

B. Tech. in VLSI Design and Technology

2.1 Preamble

B. Tech. (VLSI Design and Technology) program offered at NIT Delhi is designed to equip students with a unique blend of skill sets that include:

- Strong theoretical foundation
- Predominantly practice-oriented approach with access to well-equipped and specialized laboratories and supervised internship
- Hands-on technical training
- Life skills orientation
- Hard and soft skills
- Business perspective, along with an emphasis on innovation and entrepreneurship

2.2 Salient Features

- Minimum Credits requirements for completion of B.Tech. Program is 160.
- The Curriculum is based on the National Education Policy (NEP) 2020 guidelines.
- The curriculum has embedded the Multi Exit/ Multi Entry in the B. Tech. program.
- Students are provided with a major degree and a minor degree.
- The curriculum is designed to meet the prevailing and ongoing industrial requirements.
- The curriculum includes Project-based Education with Projects every year.
- The flexible curriculum offers a Choice Based Credit System (CBCS).
- The curriculum inherits Value-based Education and offers Interdisciplinary/ Multidisciplinary Courses.
- The Curriculum offers Digital Pedagogy & Flipped Learning with adequate motivation for Entrepreneurship/ Start-ups.
- The curriculum aims to develop the students holistically.

2.3 Cardinal Mentions

- Students exiting after completing 1st Year, 2nd Year, and 3rd Year will be awarded a Certificate, Diploma, and Advanced Diploma in VLSI Design and Technology, respectively. The minimum Credit requirement for a Certificate is 40 Credits, a Diploma is 80 Credits, and an Advanced Diploma is 120 Credits respectively.
- The students can opt for a Minor Degree across any specialization offered in the Institute from the 5th Semester, e.g., a student pursuing B. Tech. (VLSI Design and Technology) may opt for Minor Degrees offered by the different Departments in the Institute depending upon his/her interest.
- The students opting for a Minor Degree will have to earn additional credits for the Minor Degree as per Institute norms, which may vary from time to time.

2.4 **Program Educational Objectives (PEOs)**

PEO-1	To design and develop innovative and cost-effective electronic systems exhibiting strong foundations and core competencies in microelectronics, embedded systems, and chip design.
PEO-2	To adapt the emerging technologies, provide solutions to global challenges, pursue higher studies, industrial and R&D requirements, become entrepreneurs.
PEO-3	To develop the aptitude for innovation, teamwork, and leadership with effective communication skills to work in a multidisciplinary and multicultural environment.
PEO-4	To exhibit strong professional ethics and values for social and environmental sustainability with a focus on the welfare of humankind.

2.5 **Program Outcomes (POs)**

P0-1	Engineering Knowledge : Apply the knowledge of mathematics, science, engineering fundamentals, and an engineering specialization to the solution of complex engineering problems.
PO-2	Problem Analysis: Identify, formulate, review research literature, and analyze complex engineering problems reaching substantiated conclusions using first principles of mathematics, natural sciences, and engineering sciences.
PO-3	Design/Development of Solutions: Design solutions for complex engineering problems and design system components or processes that meet the specified needs with appropriate consideration for the public health and safety, and the cultural, societal, and environmental considerations
P0-4	Conduct Investigations of Complex Problems: Use research-based knowledge and research methods including design of experiments, analysis and interpretation of data, and synthesis of the information to provide valid conclusions.
PO-5	Modern Tool usage: Create, select, and apply appropriate techniques, resources, and modern engineering and IT tools including prediction and modelling to complex engineering activities with an understanding of the limitations.
PO-6	The Engineer and Society: Apply reasoning informed by the contextual knowledge to assess societal, health, safety, legal and cultural issues and the consequent responsibilities relevant to the professional engineering practice.
P0-7	Environment and Sustainability: Understand the impact of the professional engineering solutions in societal and environmental contexts, and demonstrate the knowledge of, and need for sustainable development.
PO-8	Ethics: Apply ethical principles and commit to professional ethics and responsibilities and norms of the engineering practice.
P0-9	Individual and Team Work: Function effectively as an individual, and as a member or leader in diverse teams, and in multidisciplinary settings.
PO-10	Communication: Communicate effectively on complex engineering activities with the engineering community and with society at large, such as, being able to comprehend and write effective reports and design documentation, make effective presentations, and give and receive clear instructions.
P0-11	Project Management and Finance: Demonstrate knowledge and understandin5g of the engineering and management principles and apply these to one's own work, as a member and leader in a team, to manage projects and in multidisciplinary environments.
P0-12	Life-long learning: Recognize the need for, and have the preparation and ability to engage in independent and life-long learning in the broadest context of technological change.

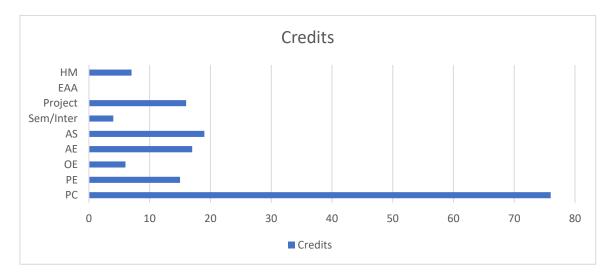
2.6 Program Specific Objectives (PSOs)

PSO -1	Capability to design integrated circuits (ICs) to develop innovative and cost-effective electronic systems for a sustainable semiconductor ecosystem.
PSO -2	An ability to use acquired technical knowledge for a successful career and contribute to research and entrepreneurship, especially in the IC design and technology domain.

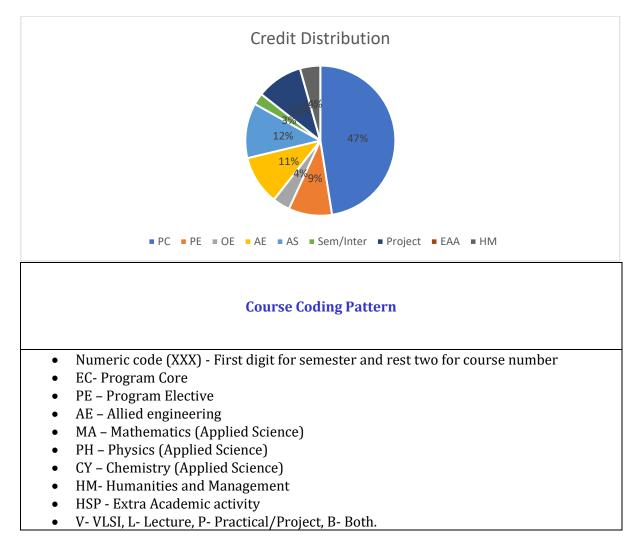
Sl	Categor		/ear	2 nd 1	Year	3rd y	Year	4 th Y	Year	Tot
N o.	y of Courses	Semes ter I	Semes ter II	Semes ter III	Semes ter IV	Semes ter V	Semes ter VI	Semes ter VII	Semes ter VIII	al
1.	Program Core		08	12	20	17	14	05	0	76
2.	Program Elective s					03	03	09		15
3.	Open Elective s						03	03		06
4.	Allied Enginee ring	08	04	05						17
5.	Applied Sciences	08	08	03						19
6.	Seminar / Summer Internsh ips/ Indepen dent Study and Seminar								04	04
7.	Project								16	16
8.	Extra Academi c Activity									
9.	Humanit ies	04						03		07
	Total	20	20	20	20	20	20	20	20	160

3.1 Semester-wise Credit Structure

3.2 Credits Distribution



3.3 Credits Distribution (%)



Teaching Scheme For B. Tech VLSI Design & Technology

	Semester I											
Course Code	Course Name	Туре	L	Т	Р	Credit						
MAVL101	Mathematics-I	Applied Sciences	3	1	0	4						
CYVB 102	Engineering Chemistry	Applied Sciences	3	0	2	4						
CELB 101	Environmental Sciences	Allied Engineering (CE)	2	0	0	2						
MEVP 102	Engineering Graphics and Design	Allied Engineering (ME)	1	0	2	2						
EEVB 103	Basics of Electrical and Electronics Engineering	Allied Engineering (EE)	3	0	2	4						
HMVB 101	Human Values and Ethics	Humanities and Management	2	0	2	3						
HMVP 102	Technical Communication	Humanities and Management	0	0	2	1						
	Total Credits		13	1	12	20						

	Semester II										
Course Code	Course Name	Туре	L	Т	Р	Credit					
MAVL 203	Mathematics - II	Applied Sciences	3	1	0	4					
PHVB 204	Engineering Physics	Applied Sciences	3	0	2	4					
CSVB 204	Problem Solving and Computer Programming	Allied Engineering (CSE)	3	0	2	4					
MAVL 205	Probability Theory and Stochastic Process	Applied Science	3	0	0	3					
ECVL 201	Basics of Semiconductor Materials	Program Core	3	1	0	4					
HSPB 151	Holistic Health & Sports	Extra Academic Activity	0	0	2	1					
	Total Credits	•	15	2	6	20					

	Semester III										
Course Code	Course Name	Туре	L	Т	Р	Credit					
ECVB 302	Electronic Devices and Circuits	Program Core	3	0	2	4					
ECVB 303	Signals and Systems	Program Core	3	0	2	4					
ECVB 304	Digital Electronics	Program Core	3	0	2	4					
EEVL 305	Network Analysis and Control Theory	Allied Engineering (EE)	3	1	0	4					
CSVB 306	Data Structure and Programming	Allied Engineering (CSE)	3	0	2	4					
	Total Credits		15	1	8	20					

	Semester IV										
Course Code	Course Name	Туре	L	Т	Р	Credit					
ECVB 405	Micro Fabrication	Program Core	3	0	0	3					
	Technology										
ECVB 406	Digital System Design	Program Core	3	0	2	4					
ECVB 407	Analog Communication	Program Core	3	0	2	4					
ECVB 408	Microprocessors and	Program Core	3	0	2	4					
	Microcontrollers										
ECVB 409	Digital Signal Processing	Program Core	3	0	2	4					
ECVP 410	Mini Project	Program Core	0	0	2	1					
	Total Credits		15	0	10	20					

Summer Internship (6-8 weeks) is mandatory during the summer vacation in between semester IV and V for each student to continue the programme and the corresponding evaluation will take place in the next semester (semester V).

	Semester V										
Course Code	Course Name	Туре	L	Т	Р	Credit					
ECVB 511	Digital Communication	Program Core	3	0	2	4					
ECVB 512	Digital VLSI Design	Program Core	3	0	2	4					
ECVB 513	Semiconductor Packaging	Program Core	3	0	0	3					
	and Testing										
ECVB 514	Algorithm for VLSI Design	Program Core	3	0	0	3					
PEVL XXX	Elective-I	Program Elective	3	0	0	3					
ECVP 515	Programming Lab	Program Core	0	0	4	2					
ECVP 516	Seminar/ Summer	Program Core	0	0	2	1					
	Internship-I										
	Total Credits		15	0	10	20					

	Semester VI										
Course Code	Course Name	Туре	L	Т	Р	Credit					
ECVB 617	Embedded and Real-Time Operating Systems	Program Core	3	0	2	4					
ECVB 618	Analog VLSI Design	Program Core	3	0	2	4					
PEVL XXX	Elective-II	Program Elective	3	0	0	3					
PEVL XXX	Elective-III	Program Elective	3	0	0	3					
OEVL	Open Elective-I / MOOCs	Open Elective	3	0	0	3					
ECVP 619	Minor Project	Program Core	0	0	4	2					
ECVP 620	Project-based learning	Program Core	0	0	2	1					
	Total Credits		15	0	10	20					

Summer Internship (6-8 weeks) is mandatory during the summer vacation in between semester VI and VII for each student to continue the programme and the corresponding evaluation will take place in the next semester (semester VII).

	Semester VII										
Course Code	Course Name	Туре	L	Т	Р	Credit					
ECVL 721	Low Power VLSI Design	Program Core	3	0	0	3					
ECVL 722	VLSI Verification & Testing	Program Core	3	0	2	4					
PEVL XXX	Elective-IV	Program Elective	3	0	0	3					
PEVL XXX	Elective-V	Program Elective	3	0	0	3					
OEVL XXX	Open Elective-II / MOOCs	Open Elective	3	0	0	3					
HMVL 703	Engineering Economics and	Humanities and	3	0	0	3					
	Accounting	Management									
ECVP 723	Seminar/ Summer Internship-II	Program Core	0	0	2	1					
	Total Credits		18	0	4	20					

	Semester VIII										
Course Code	Course Name	Туре	L	Т	Р	Credit					
ECVP 824	Major Project/Internship	Program Core	-	-	-	16					
ECVP 825	Independent Study &	Program Core	-	-	8	4					
	Seminar										
	Total Credits					20					

*Open electives are such subjects which will be offered by other departments. ECE department students have to opt open electives from CSE, EE and other departments.

List of Electives

Bouquet 1: Elective-I

S. No.	Course Code	Course Title	L	Т	Р	Credits
1.	PEVL 501	Semiconductor Device Modelling	3	0	0	3
2.	PEVL 502	Introduction to Machine Learning	3	0	0	3
3.	PEVL 503	Internet of Things	3	0	0	3
4.	PEVL 504	Wireless Communication	3	0	0	3
5.	PEVL 505	Digital Signal Processor and Architecture	3	0	0	3
6.	PEVL 506	Antenna Theory and Design	3	0	0	3

Bouquet 2: Elective-II and Elective III

S. No.	Course Code	Course Title	L	Т	Р	Credits
1.	PEVL 607	Introduction to MEMS	3	0	0	3
2.	PEVL 608	Nano Electronics	3	0	0	3
3.	PEVL 609	Cyber Security	3	0	0	3
4.	PEVL 610	ASIC and FPGA Design	3	0	0	3
5.	PEVL 611	Radar Engineering	3	0	0	3
6.	PEVL 612	Advance Neural Network	3	0	0	3
7.	PEVL 613	VLSI Interconnects	3	0	0	3
8.	PEVL 614	AI and Machine Learning for IC	3	0	0	3
9.	PEVL 615	VLSI for Communications	3	0	0	3
10.	PEVL616	Memory Devices and circuits	3	0	0	3

Bouquet 3: Elective-IV and Elective V

S. No.	Course Code	Course Title	L	Т	Р	Credits
1.	PEVL 717	CAD for VLSI	3	0	0	3
2.	PEVL 718	Thin Films Characterization	3	0	0	3
3.	PEVL 719	Mixed Signal IC design	3	0	0	3
4.	PEVL 720	Bio-Medical Electronics	3	0	0	3
5.	PEVL 721	RF Microelectronics	3	0	0	3
6.	PEVL 722	High-Speed Interfacing Circuits	3	0	0	3
7.	PEVL 723	Digital Image Processing	3	0	0	3
8.	PEVL 724	Flexible Electronics	3	0	0	3
9.	PEVL 725	Quantum Computing	3	0	0	3
10.	PEVL 726	Solar Cell Technology	3	0	0	3
11.	PEVL 727	Ad-hoc Sensor Networks	3	0	0	3
12.	PEVL 728	Full Custom Design	3	0	0	3
13.	PEVL 729	Advance Semiconductor Manufacturing	3	0	0	3
14.	PEVL 730	Data Converters	3	0	0	3
15.	PEVL 731	Reconfigurable Computing System and Applications	3	0	0	3

Open Elective-I

S. No.	Course Code	Course Title	L	Т	Р	Credits
1.	0EVL 601	Growth, Fabrication and Manufacturing	3	0	0	3
		of Electronic Devices				
2.	0EVL 602	Electronic Materials	3	0	0	3
3.	0EVL 603	Basics of IC Design	3	0	0	3

Open Elective-II

S. No.	Course Code	Course Title	L	Т	Р	Credits
1.	0EVL 704	Data Communication and Networking	3	0	0	3
2.	0EVL 705	Micro-Electronics and VLSI Technology	3	0	0	3
3.	OEVL 706	Embedded and real time operating systems	3	0	0	3

Proposed List of Massive Open Online Courses (MOOCs):

Students can opt for the MOOCs related to VLSI/Embedded Systems. A suggestive list is given below, and students need to opt for MOOCs related to a UG Degree. The Chairman DBoS may vary the following list of subjects as per the student's and teaching requirements.

S. No.	Suggested MOOCs	Course Duration	Credit points	Category
1.	VLSI Design Flow: RTL to GDS	12 Weeks	3	ECE/VLSI
2.	Semiconductor Devices and Circuits	12 Weeks	3	ECE / VLSI Design
3.	Real-Time Digital Signal Processing	12 Weeks	3	ECE / Communication and signal processing
4.	Photonic Crystals: Fundamentals & Applications	12 Weeks	3	ECE / Photonics
5.	Phase-Locked Loops	12 Weeks	3	ECE / VLSI Design
6.	Microelectronics: Devices to Circuits	12 Weeks	3	ECE / VLSI Design
7.	Fundamentals of Nano and Quantum Photonics	12 Weeks	3	ECE / Photonics
8.	Enclosure Design of Electronics Equipment	12 Weeks	3	ECE
9.	Design of Photovoltaic Systems	12 Weeks	3	ECE

SEMESTER-I

Course Code: MAVL 101		Scien		HM Course: (Y/N)	PC Course:	(Y/N)	PE	Course	: (Y/N	J)
		Y		N	N		N			
Type of Co	ourse	Theor	y Course/	Lab Course						
Course Tit	tle	MATH	IEMATICS	- I						
Course Co	ordinato	r								
Course Ob	jectives	To bui Geom		ental knowledge t	o solve mathe	ematical	probl	ems of c	alculı	us and
Course Ou	tcomes	·					Cog	nitive L	evels	
CO1		g the engin		of calculus mainly oblems mathemat				Under (Leve		
CO2	Understa	and the fun	damentals	s of series and seq	uence theore	ms.		Under (Leve		
CO3	Apply th domain.	e differen	tial equati	ions to calculus i	in the multiv	ariable		App (Leve	-	
CO4	Apply the domain.	ne Integra	l equation	ns to calculus ir	n the multiv	ariable		App (Leve	-	
Semester		1 st			Autur	nn	•	•		
Contact H	ours	Lectu	re T	utorial	Practical	Credit	ts	Total Hours	Теа	ching
Contact II	ours	3	1		0	4		48		
Prerequis codes wi names Equivalen codes proposed old course	th cour t cour as p course a	se se er								
Text Book			_							
1.	Tit			ring Mathematics						
		thor blichor	Reena G	0	Composite					
		blisher ition	2022	Book Publishing (Joinpany					
2.	Tit		Reena G	arg						
		thor		ed Engineering Ma	athematics					
		blisher		Book Publishing (
	Ed	ition	2021	<u> </u>	1 0					
Reference			1							
1.	Tit			and Analytic geo	-					
		thor		mas and R.L. Finn	ley					
		blisher ition								
Course Contents	UN Ba im Ap	I IT I: sic Calculu proper in plications	s: Curvatu tegrals; B of definite	are, evolutes and i Beta and Gamma e integrals to eva able Calculus (Dif	a functions lluate surface	and th e areas a	eir p and v	oropertie olumes	es; of	9

	value theorems and applications; Extreme values of functions; Linear approximation; Indeterminate forms and L'Hospital's rule.	
	UNIT II: Sequences and series: Limits of sequence of numbers, Calculation of limits, Infinite series; Tests for convergence; Power series, Taylor and Maclaurin series; Taylor theorem, convergence of Taylor series, error estimates.	9
	UNIT III: Multivariable Calculus (Differentiation): Limit, continuity and partial derivatives, directional derivatives, gradient, total derivative; Tangent plane and normal line; Maxima, minima and saddle points; Method of Lagrange multipliers.	9
	UNIT IV: Multivariable Calculus (Integration): Multiple Integration: Double integrals (Cartesian), change of order of integration in double integrals, change of variables (Cartesian to polar), Applications: areas and volumes, Centre of mass and Gravity (constant and variable densities); Triple integrals (Cartesian), orthogonal curvilinear coordinates, Simple applications involving cubes, sphere and rectangular parallelepipeds; Scalar line integrals, vector line integrals, Gradient, curl and divergence, Theorems of Green, Gauss and Stokes.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course (Code: (CYVB	Open E		HM Course:	DC Cou	rse: (Y/N)	DE	Course:	(Y/N)	
102			Course:	(Y/N)	(Y/N)						
			Y		N	Ν		Ν			
Type of C			Theory Course and Lab Course ENGINEERING CHEMISTRY								
Course T			ENGINE	ERING C	HEMISTRY						
Course Co						6.1			,		
Course O			To provi	de funda	amental knowledg	ge of cher	nical structur				
Course O					· · · · · · · · · · · · · · · · · · ·	1 .	1			ve Levels	
C01					ing in the molecu		-		(Le	erstand vel-II)	
CO2		-			lectromagnetic ra			-		alyze	
					vels in various spe			5.	•	/el-IV)	
CO3	To un	dersta	nd thermo	odynam	ic and electrocher	nical con	cepts.			alyze	
604	TT -								•	vel-IV)	
CO4					operties such a			iai,		pply	
		onega		iation st	ates and electron				(Lev	/el-III)	
Semester			1 st				utumn	<u>.</u>			
Contact H	lours		Lecture	T	ıtorial	Practic	al Credits		Total Hours	Teaching	
			3	0		2	4		48		
Prerequi codes w				·							
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proposed		-									
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Text Boo	ks										
1.		Title		Inorga	nic Chemistry: Pri	nciples o	f Structure ai	nd Re	eactivity		
		Autho	r J. E. Huheey								
		Publis	her	Pearso	n						
		Editio	n	4 th							
2.		Title		Concise Inorganic Chemistry							
		Autho		J. D. Le							
	Ļ	Publis		Wiley I	ndia						
-		Editio	n	5th							
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1.	F	Title			al Chemistry						
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Course				1001							
Contents				ing· Va	lence hond theo	rv and	its limitation	ns d	lirection	al	
Jontents				•		-					
	Itents Chemical Bonding: Valence bond theory and its limitations, directional characteristics of covalent bond, various types of hybridization and shapes of simple inorganic molecules and ions, valence shall electron pair repulsion (VSEPR) theory. Crystal Field Theory (CFT), comparison of the stability of octahedral and tetrahedral complexes on the basis of crystal field stabilization energy (CFSE), factor affecting the magnitude of CFSE, application of crystal								repulsio tability o abilizatio	n 10 of n	

	field theory. Jahn-Teller effect definition and example from d ⁹ and high spin d ⁴									
	systems.									
	UNIT II:									
	Spectroscopic techniques and applications: Principles of spectroscopy and selection rules. Electronic spectroscopy. Fluorescence and its applications. Vibrational and rotational spectroscopy of diatomic molecules and applications. Nuclear magnetic resonance and magnetic resonance imaging.	10								
	UNIT III:									
	Use of free energy in chemical equilibria: Thermodynamic functions: energy, entropy and free energy. Estimations of entropy and free energies. Free energy and EMF. Cell potentials, oxidation reduction reaction, Nernst equation and applications.	08								
	UNIT IV:									
	Periodic properties: Effective nuclear charge, penetration of orbitals, variations of s, p, d and f orbital energies of atoms in the periodic table, electronic configurations, atomic and ionic sizes, ionization energies, electron affinity and electronegativity, polarizability, oxidation states, coordination numbers and geometries, hard soft acids and bases.									
Course	Continuous Evaluation 25%									
Assessment	Mid Semester 25%									
nssessment	End Semester 50%									
Tentative List	1. To find the strength in grams per litre of the given solution of sodium hy	drovida								
of	with the help of stander oxalic acid solution.	uioxiue								
Experiments	2. ESTIMATION OF WATER HARDNESS BY EDTA METHOD									
Experiments	 (a) To determine the strength of calcium ion in given CaCO₃ solu Complexometric Titrations. 	ition by								
	(b) To determine the strength of magnesium ion in given MgSO ₄ solu	ution by								
	Complexometric Titrations.	o ve o tri o								
	(c) To determine the total hardness of given water sample by Complex Titrations.	ometric								
	3. To determination the strength of ferrous ammonium sulphate with the	help of								
	$K_2Cr_2O_7$ solution.									
	4. To synthesize copper ammonium complex.									
	5. To synthesize $[Cu(H_2O)_6](ClO_4)_2$ complex.									
	6. Order of a reaction (redox).									
	7. Blue printing.									
	8. Acid-base titration using pH meter.									
	9. Acid-base titration by conductometry.									

Course (101	Code: CE	ELB	Allied Enginee Course:	•	HM Course: (Y/N)	PC (Course:	(Y/N)	PE Course	e: (Y/N)
			Y		N	N			N	
Type of C					ab Course					
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Course Co										
Course O	bjectives	5	-	ide funda problems	mental knowledge	e envi	ronmen	tal scien		
Course O	utcomes	1							Cognitive	Levels
C01	Gain a aspects	-	prehensiv	ve unders	standing of the Env	vironi	nental S	cience		rstand rel-II)
CO2	Develo	p aw	areness	of enviro	nment related issu	es.				llyze el-IV)
CO3			t the ethi vironme		noral responsibilit	ties of	the eng	ineers	Unde	rstand rel-II)
CO4					olve environment	al issu	ies.		Unde	rstand rel-II)
Semester	•		1 st				Autum	n		
			Lecture	T	utorial	Pra	ctical	Credit	s Total	Teaching
Contact H	Iours								Hours	8
			2	0		0		2	24	
Prerequi codes w names	ith cou	rse								
Equivaler codes	as p	per								
proposed and old c		rse								
Text Boo										
1.		ſitle		Introdu	ction to Environm	ental	Enginee	ring		
	A	Autho	or		zie L. Davis and Da					
	F	Publi	sher	Tata Mc	Graw-Hill Educati	on Pri	vate Lin	nited		
		Editic	on		tion 2010					
2.		Title			ction to Environm	ental	Enginee	ring and	Science	
		Autho			M. Masters					
		<u>ubli</u>			Education					
D (Editio	on	2 nd editi	on 2007					
Referenc	1			F		1				
1.		<u>Fitle</u>			mental Science an			5		
		Autho Publis								
		Editic			on 2004					
Course		JNIT			011 2004					
Contents				arv natu	re of environme	ntal «	studies	Definiti	on scope a	and
Soments			-	-	iblic awareness.	iitui i	, cuuico,	Denniti	on, scope a	
		-		-	and function of a	n eco	system.	Produc	ers, consum	ers 12
		-			rgy flow in the eco		-			
					ecological pyramid					
	f	eatu	res, stru	cture and	d function of the	follo	wing e	cosysten	ns: - a. For	est

	ecosystem b. Grassland ecosystem c. Desert ecosystem d. Aquatic ecosystems, Biogeochemical cycles	
	UNIT II: Biodiversity and its conservation Introduction – Definition: genetic, species and ecosystem diversity. Biogeographical classification of India. Value of biodiversity: consumptive use, productive use, social, ethical, aesthetic and option values. Biodiversity at global, National and local levels. India as a mega- diversity nation, Hot-sports of biodiversity. Threats to biodiversity: habitat loss, poaching of wildlife, man-wildlife conflicts. Endangered and endemic species of India. Conservation of biodiversity: In-situ and Ex-situ conservation of biodiversity	8
	UNIT III: Environmental Pollution Definition, Cause, effects and control measures of: a. Air pollution b. Water pollution c. Soil pollution d. Marine pollution e. Noise pollution f. Thermal pollution g. nuclear hazards, Causes, effects and control measures of urban and industrial wastes. Pollution case studies. Solid waste Management.	8
	UNIT IV: Social Issues and the Environment, From Unsustainable to Sustainable development, Urban problems related to energy, Water conservation, rain water harvesting, watershed management, Resettlement and rehabilitation of people; its problems and concerns. Climate change, global warming, acid rain, ozone layer depletion and Eutrophication.	8
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course MEVP 102	Code:	Open Course: (Elective	HM Course: (Y/N)	DC C	Course:	(Y/N)	DE	Course	: (Y/N)	
MLVF 102	<u> </u>	Y	<u>1/NJ</u>	N N	N			N			
Type of C	nurse	Theory Co	ourse/La	- ·	11			IN			
Course Ti		<u> </u>	ENGINEERING GRAPHICS & DESIGN								
Course	uc	LITUITUL		II IIICS & DESIG	•						
Coordina	tor										
Course Ol		The obied	tive of th	is Course is to pro	ovide	the bas	ic know	ledge	about E	Ingineering	
	,,	Drawing.		r				0		0 0	
Course Ou	utcomes							Cog	nitive L	evels	
C01	To Under	stand the c	and the concept of Engineering Graphics. Understar (Level-II)								
CO2		e concept cal shapes.	of engine	ering drawing to	o drav	w the v	various		Apı (Leve	-	
CO3		•	are given i	n projections, tec	hnical	l drawir	ıg.		Ap		
	FF-5			1 - , ,			υ,		(Leve	-	
CO4	Design te	eam projec	ct that ill	ustrates Geomet	ry an	d topol	ogy of		Eval		
	engineere	ed compone	ents using	CAD.	-	-			(Leve	el-V)	
Semester		1 st				Autun	nn				
		Lecture	Тι	itorial	Prac	ctical	Credit	S	Total	Teaching	
Contact H	ours								Hours	8	
		1	0		2		2		24		
Prerequis	site						1				
course co											
course na	mes										
Equivaler	nt course										
codes	as per										
proposed											
and old co											
Text Bool	KS										
1.		Title Engineering Graphics & Design									
		Author		radeep Jain	. .						
		Publisher	· K	hanna Book Publi	shing						
2		Edition				Decla					
2.		Title		ngineering Graph							
		Author		in, Maheshwari, (
		Publisher	K	hanna Book Publi	sning						
Reference	Rooks	Edition									
Reference	DUUKS										
1		Title	E.	ngingering Drowi	Title Engineering Drawing						
1.						DD In	مام				
1.		Author	N	.D.Bhatt, V.M. Pan	chal &	&P.R., In	gle				
1.		Author Publisher	N		chal &	&P.R., In	gle				
	ontents	Author Publisher Edition	N	.D.Bhatt, V.M. Pan	chal &	&P.R., In	gle				
1. Course Co	ontents	Author Publisher Edition UNIT I:	· E	.D.Bhatt, V.M. Pan ngineering Drawi	ng		~	ving:	Principl	es	
	ontents	Author Publisher Edition UNIT I: Introduc	N E tion to E	.D.Bhatt, V.M. Pan ngineering Drawi ngineering Grap	ng hics &	& Desig	n: Draw	-	-		
	ontents	Author Publisher Edition UNIT I: Introduc of Engin	tion to Endering G	D.Bhatt, V.M. Pan ngineering Drawi ngineering Grap raphics and the	hics &	& Desig	n: Draw ce, usag	ge of	Drawi	ng	
	ontents	Author Publisher Edition UNIT I: Introduc of Engin instrume	tion to Entropy of the second	.D.Bhatt, V.M. Pan ngineering Drawi ngineering Grap	hics &	& Desig gnificant phics:	n: Draw ce, usag Enginee	ge of ering	Drawi Graphi	ng .cs	
	ontents	Author Publisher Edition UNIT I: Introduc of Engin instrume	tion to En eering G nts, Lette - Spatial	D.Bhatt, V.M. Panngineering Drawi ngineering Grap raphics and the ering. Computer	hics & hics & ir sig Gra s; Ort	& Desig gnifican phics: chograp	n: Draw ce, usag Enginee hic Proj	ge of ering ectio	Drawi Graphi ns; Moc	ng cs lel 6	
	ontents	Author Publisher Edition UNIT I: Introduc of Engin instrumer Software Viewing; Assembly	tion to En eering Grants, Letto - Spatial Co-ordin r; Model	D.Bhatt, V.M. Pan ngineering Drawi ngineering Grap raphics and the ering. Computer Transformations nate Systems; Viewing; Animat	hics & hics & ir sig Gra s; Ort Multi	& Desig gnifican phics: hograp -view	n: Draw ce, usag Enginee hic Proj Projecti	ge of ering ectio ion;	Drawi Graphi ns; Moc Explod	ng cs lel 6 ed	
	ontents	Author Publisher Edition UNIT I: Introduc of Engin instrume Software Viewing;	tion to En eering Grants, Letto - Spatial Co-ordin r; Model	D.Bhatt, V.M. Pan ngineering Drawi ngineering Grap raphics and the ering. Computer Transformations nate Systems; Viewing; Animat	hics & hics & ir sig Gra s; Ort Multi	& Desig gnifican phics: hograp -view	n: Draw ce, usag Enginee hic Proj Projecti	ge of ering ectio ion;	Drawi Graphi ns; Moc Explod	ng cs lel 6 ed	

	Engineering Scales & Curves: Types of scales-Plain scale, Diagonal scale,	
	Conic sections, Cycloid, Epicycloid, Hypocycloid, Spiral and Involute.	
	Orthographic Projections: Principles of Orthographic Projections-	
	Conventions - Projections of Points, Lines and Plane.	
	UNIT-III	
	Projections of Solids: Auxiliary Views; Draw simple annotation,	
	dimensioning and scale. Floor plans.	
	Sections and Sectional Views of Right Angular Solid Prism, Cylinder,	
	Pyramid, Cone – Auxiliary Views, Sectional views of Right Regular Solids-	6
	Prism, Pyramid, Cylinder and Cone.	6
	Isometric Projections: Principles of Isometric projection – Isometric	
	Scale, Isometric Views of lines, Planes, Simple and compound Solids;	
	Conversion of Isometric Views to Orthographic Views and Vice-versa,	
	Conventions.	
	UNIT-IV	
	CAD Modelling: Overview of Computer Graphics, theory of CAD,	
	important commands and their uses.	
	Customisation & CAD Drawing, setting up of Modules and drawing limits;	
	ISO and ANSI standards, tolerance; Annotations, Layering, applying	6
	annotations to drawings; Printing documents; orthographic projection	Ū
	techniques; Drawing sectional views of different objects, CAD modelling	
	of parts and assemblies, surface, and wireframe models, Dimensioning	
	guidelines, tolerance techniques; dimensioning and scale multi views of	
	dwelling.	
Course	Continuous Evaluation 25%	
Assessment	Mid Semester 25%	
	End Semester 50%	

Course C 103	ode: EEVB	Allied Engineering Course: (Y/N)	HM Course: (Y/N)	PC C	Course:	(Y/N)	PE	Course	: (Y/N)		
		Y	Y N N N								
Type of Co			Theory Course/ Lab Course BASICS OF ELECTRICAL AND ELECTRONICS ENGINEERING								
Course Ti		BASICS OF ELE	CTRICAL AND ELE	ECTRO	DNICS E	NGINEE	RING				
Course Co	ordinator										
Course Ob	ojectives		f this Course is to p t of the field of Elec				vith a	n introd	luctory and		
Course Ou	itcomes						Cogr	nitive L	evels		
C01	Understand operation.	l basics of semic	onductor theory an	ıd prii	nciple o	f diode		Under (Leve			
CO2	To study t amplifiers.	he design and	operation of rectif	fiers a	and tra	nsistor		App (Leve	-		
CO3	To study an	d apply circuit th	eorems to AC and	DC cir	cuits.			Арр			
	C C							(Leve	-		
CO4	Understand	and analyses	the working prin	ciples	of ele	ectrical		Anal			
	machines.							(Leve	l-IV)		
Semester		1 st			Autun	nn					
Contact H	ours	Lecture	Futorial	Pra	ctical	Credit		Total Hours	Teaching		
Contact II	ours	3)	2		4		48			
Prerequis	site course	5	J	2		Т		10			
	ith course										
names	the course										
Equivalen	t course										
codes	as per										
proposed	course										
and old co	ourse										
Text Book	KS .										
1.	Title	Basic Electr	rical Engineering								
	Author	Ritu Sahdev									
	Publishe	er Khanna Bo	ok Publishing								
	Edition	2022	<u> </u>								
2.	Title	Basic Electi	rical Engineering								
	Author		and D. P. Kothari								
	Publishe	er McGraw-Hi	ll Education								
	Edition	2001									
Reference	Books										
1.	Title	Engineerin	g Circuit Analysis,								
	Author	Hayt and K	imberly								
	Publishe	er Tata McGra	w Hill								
	Edition	8 th edition 2	2013								
Course	UNIT I:										
Contents		•	s, metals, and semi								
			nd Ge, conductivity								
		ductors: n-typ			conduct				ⁱⁿ 9		
			ism in current flow						on,		
			ls: Element semi				-				
	-	-	d quaternary com	-					N-		
	I lunction	ulode. Diode equ	uvalent circuit, dio	ue as :	a Switch	i, aiode t	esting	<u>۲</u> .			

	UNIT II: Rectifiers: Half wave, center tapped and bridge full-wave, Zener diode regulator and voltage multiplier, clipping and clamping circuits. TRANSISTORS: Construction and characteristics of BJT, Transistor configuration: CB, CE, CC configuration, Transistor at low frequency, small signal low-frequency transistor model(h-parameters), Analysis of transistor amplifier using h- parameters, Transistor biasing and bias stabilization: Operating point, Stability factor, Analysis of fixed bias, collector to base bias, Emitter resistance bias circuit	9
	and self-bias circuit, Bias compensation techniques. UNIT III: Voltage and current sources, dependent and independent sources, source conversion, DC circuit's analysis using mesh & nodal method, Thevenin's& superposition theorem, star-delta transformation. 1-phase AC circuits under sinusoidal steady-state, active, reactive, and apparent power, physical meaning of reactive power, power factor, 3-phase balanced and unbalanced supply, star and delta connections.	9
	UNIT IV: Transformers: Magnetic Circuits: Review of laws of electromagnetism, Flux, MMF and their relation, analysis of the magnetic and electric circuit. Single-phase transformer: Basic concepts, constructional features, EMF equation, voltage, current, and impedance transformation, Equivalent circuits. Electrical Machines: DC Machines: Constructional features, working principle, emf equation, types of dc machines, and their characteristics. Induction Machines: Constructional features, working principle, emf equation, the concept of slip and torque-slip characteristics. Synchronous Machines: Constructional features, working principle and emf equation.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	
Tentative List of Experiment s	1. To verify KCL and KVL	

Course Co	ode: H	MVB	-	n Electi		M Course	PC	Course:	(Y/N)	PE	E Course:	(Y/N)
101				se: (Y/N	· ·	Y/N)	_					
			N	_	Y		Ν			N		
Type of Co			Theory Course/ Lab Course									
Course Ti			HUMAN VALUES AND ETHICS									
Course Co			T					1.1.1.1.		1.1.		
Course Ol			To gi	ve the fu	indame	ental knowled	ge of e	ethical p	ractice a			
Course Ou										Cog	gnitive Le	
CO1				5		d Organization					Unders (Leve	l-II)
CO2	Unde	erstand	l the e	notion, f	feeling,	authority and	d respo	onsibilit	у.		Unders (Leve	
CO3	Deve	lop the	e mora	l and eth	nical va	lues.					App (Leve)	•
CO4	Analy	vze the	policy	of hum	an resc	ources.					Anal	
	1 mai	y Ze the	pone.	, or mann		, ai ees.					(Leve	•
Semester			1 st					Autur			(LEVE)	
Semester					T							
	-		Lect	ure	Tuto	rial	Pra	ctical	Credit	S	Total	Teaching
Contact H	ours		-				-				Hours	
<u> </u>			2		0		2		3		48	
Prerequis												
codes w	ith co	ourse										
names												
Equivaler codes		ourse										
proposed	as	per ourse										
and old co		Juise										
Text Book												
1.	1.5	Title		Organiz	ationa	Behaviour: 1	ovt ar	d Cases				
1.		Autho	Organizational Behaviour: Text and Cases or A.K. Chitale, R.P. Mohanty and N.R. Dubey									
		Publi										
		Editio										
2.		Title	Text & Cases in Human Resources Management									
		Autho										
		Publi										
		Editio										
Reference	e Book	S										
1.		Title		Enginee	ering Et	thics includes	Huma	ın Value	S			
		Autho	or			an, S. Nataraja				ır		
		Publi	sher	PHI Lea	rning I	Pvt. Ltd						
		Editio	on	2011	-		-					
Course		UNIT	I:		-		-					
Contents						n and Orga						
						l Structures, I						
						ineering Eth						
						d definition,						
						of Personalit		-				`S,
				ital Fact	ors, Psy	ychological Fa	actors;	Big Five	e Persona	ality	traits.	
		UNIT						<u> </u>		F		
			0			Feelings; Din						
						tional Intellige						
		Kespo	JUSIDI	ity and I	Accoun	tability: Mea	uing 0	i Authol	ity, kes	pons	ionity an	u

	Accountability, Balance between Authority, Responsibility and Accountability.	
	UNIT III:	
	Moral Development; Variety of Moral Issues; Moral Dilemma; Moral	9
	Autonomy; Theories of Moral Development- Cognitive Moral Development; Concept of moral Relativism and Moral Imperialism; Encouragement and	
	Approaches to Ethical Behaviour.	
	UNIT IV:	
	Human Resource Policies& Procedures- Introduction, Importance of Policies,	9
	Policy Formation, Human Resources Planning. Decision-making & Ethics.	
Course	Continuous Evaluation 25%	
Assessment	Mid Semester 25%	
	End Semester 50%	
List of	1. Management Activities and Games	
Experiments :	2. Case Studies	
	3. Group Discussion	
	4. Debate	
	5. Presentation Skit	

Course Code: HMVP 102		Allied Engineer (Y/N)	ing:	HM Course: (Y/N)	PC (Course:	(Y/N)	PE	Course	: (Y/N)
		N	Y N N							
Type of Co		Theory Course/ Lab Course								
Course Ti	tle	TECHNICAL COMMUNICATION								
Course Co	ordinator									
Course Ob		To develo	p the te	echnical communi	catio	n skills a	among tł	-	<u> </u>	
Course Ou								Cog	gnitive L	
C01	Understand	d basic gran	ımar pi	rinciples and sent	ence o	constru	ction.		Under (Leve	
CO2	Demonstra job applica		d coher	ent passages and	effec	tive let	ters for		Under (Leve	
CO3	Develop te	chnical repo	orts and	l interpret graphs					Apj (Leve	
CO4	Analyze the	e reading co	mpreh	ension.					Anal (Leve	-
Semester		1 st				Autur	nn			*
Contact H	ours	Lecture	T	utorial	Pra	ctical	Credit	ts	Total Hours	Teaching
	0 000 0	0	0		2		1		12	
codes wi names Equivalen codes proposed and old co	as per course									
Text Book	(S									
1.	Title		English for Engineers and Technologists							
	Auth			Jniversity						
	Publi			Blackswan						
2	Editi Title	on	1 st edit			otion				
2.	Auth	or		ve Technical Com , M Rizvi.	munic	auon.				
	Publi			, M Rizvi. IcGraw-Hill						
	Editi		2006							
Reference			1000							
1.	Title		Techni	ical Communicatio	on: Pr	inciples	and Pra	ctice		
	Auth	or		kshi Raman and S		-				
	Publi	sher	Oxford	l University Press						
	Editi	on	2 nd Edi	tion, 2011						
Course Contents	UNIT	ĨI:								
	Build and s in va	ling (synony suggestions ried context	vms and for effe	Correction of se d antonyms): Idion ective employmen struction - strateg	ns an t	d Phras	al verbs-	-patt	erns of u	ise 8

	sentences removing ambiguity - editing long sentences for brevity and clarity	
	UNIT II:	
	Paragraph-writing: Definition of paragraph and types- features of a good paragraph- Unity of theme- coherence- linking devices- direction- patterns of development. Note-making - definition- the need for note-making - its benefits - various note formats- like tree diagram, block or list notes, tables, etc. Letter-Writing: Its importance in the context of other channels of communication- qualities of effective letters-types -personal, official, letters for various purposes- emphasis on letter of application for jobs - cover letter and resume types -examples and exercises	8
	UNIT III:	
		8
	Reading techniques: Definition- Skills and sub-skills of reading- Skimming and	
	Scanning- their uses and purposes- examples and exercises. UNIT IV:	
	Reading Comprehension - reading silently and with understanding- process of	
	comprehension types of comprehension questions. (technical paper reading,	
	patents)	8
	Features of Technical English - description of technical objects and process- Report- Writing definition- purpose -types- structure- formal and informal reports- stages in developing report- proposal, progress and final reports- examples and exercises.	
Course	Continuous Evaluation 25%	
Assessment	Mid Semester 25%	
	End Semester 50%	
Tentative list	1. English Sound System -vowels, consonants, Diphthongs, phonetic symbol	s- using
of Practice:	dictionary to decode phonetic transcription Received Pronunciation, its va	lue and
	relevance- transcription of exercises-	
	2. Stress and Intonation – word and sentence stress - their role and importance in	n spoken
	English	
	3. Intonation in spoken English -definition, patterns of intonation- –falling, risi	ng, etc
	use of intonation in daily life-exercises 4. Introducing oneself in formal and social contexts- Role plays their uses in dev	aloning
	fluency and communication in general.	eioping
	5. Oral presentation - definition- occasions- structure- qualities of a good prese	entation
	with emphasis on body language and use of visual aids.	
	6. Listening Comprehension -Challenges in listening, good listening trait	s, some
	standard listening tests- practice and exercises.	, ,
	7. Debate/ Group Discussions-concepts, types, Do's and don'ts- intensive practi	ce.

SEMESTER-II

Course 203	Code: M	AVL	Applied Science		HM Course: (Y/N)	PC C	course:	(Y/N)	PE	Course:	(Y/N)
			Course: (Y	(/N)							
			Y								
	Course		Theory Course/Lab Course								
Course			MATHEMATICS- II								
	Coordina										
Course Objectives			To provide	funda	mental knowledg	e to s	olve lin	ear and di	ffere		
Course Outcomes								1. 1		<u> </u>	ve Levels
CO1				tics fu	ndamental neces	sary	to form	iulate, sol	ve		erstand
CO2		ering problems. nathematical tools for the solutions of differential equ					untiona th	at		evel-II)	
02			l processes.	lor un	le solutions of al	neren	iuai equ	uations th	iat		pply vel-III)
CO3				s for	the solutions o	f con	nlov 1	variable f	or		pply
05	different			5 101	the solutions o		ipiez v	allable I	01		vel-III)
CO4				s for	the solutions o	f con	nnlex x	variable f	or		pply
	integrati				the bolutions o		-prov v		51		vel-III)
Semest	Ŭ		2nd				Sprin	σ		(
Semest			Lecture	т	ıtorial	Dro	ctical	Credits		Total	Teaching
Contact	Hours		Lecture	11	1101141	FId	litai	creuits		Hours	Teaching
contact	. IIUui S		3	1		0		4		48	
Prerea	uisite co	urse	0	1		Ū		1		10	
-	with co										
names											
Equival	ent co	urse									
codes	as	per									
propos		urse									
and old											
Text Bo		m 1									
1.		Title			eering Mathemat	ICS					
		Autho			a Garg	- C					
		Publis Editic		2022	na Book Publishir	ig Cor	npany				
2.		Title	011		nced Engineering	Math	omotico				
۷.		Autho)r		a Garg	Matil	ematics)			
		Publis			na Book Publishir	og Cor	nnany				
		Editic		2021			iipaiiy				
Referer	ice Books		•••	2021							
1.		, Title		Adva	nced Engineering	Math	ematics	6			
		Autho	or		n Kreyszig						
		Publis			Wiley & Sons						
		Editic			dition, 2006						
Course		UNIT									
Conten				-	s of Equations; Lii		-				
					of a matrix, rank			-			Y Y
		equat		metrio				orthogon		matrice	es;
					lues and eigenv				ansf	formatio	n;
		_		t matri	ices; Cayley-Hami	Iton T	heoren	n.			
		UNIT			lifforantial agent	long	Event	linear ar	ם ה	ownersite	, 9
1		rirst	irst order ordinary differential equations: Exact, linear and Bernoulli's								

	equations. Equations not of first degree: equations solvable for p, equations Solvable for y, equations solvable for x and Clairaut's type. Ordinary differential equations of higher orders: Second order linear differential equations with variable coefficients: Euler-Cauchy equations, solution by variation of parameters; Power series solutions: Legendre's equations and Legendre polynomials, Frobenius method, Bessel's equation and Bessel's functions of the first kind and their properties.	
	UNIT III: Complex Variable – Differentiation: Differentiation, Cauchy-Riemann equations, analytic functions, harmonic functions, finding harmonic conjugate; elementary analytic functions (exponential, trigonometric, logarithm) and their properties; Conformal mappings, Mobius transformations and their properties.	9
	UNIT IV: Complex Variable – Integration: Contour integrals, Cauchy-Goursat theorem (without proof), Cauchy Integral formula (without proof), Liouville's theorem and Maximum-Modulus theorem (without proof); Taylor's series, zeros of analytic functions, singularities, Laurent's series; Residues, Cauchy Residue theorem (without proof), Evaluation of definite integral involving sine and cosine, Evaluation of certain improper integrals using the Bromwich contour.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course C 204	ode: PHVB	Open Elect Course: (Y/I		e: DC Course:	: (Y/N) I	DE Course: (Y/N)				
		Y	N	N	Ν	1				
Type of C	ourse	Theory Cour	se/ Lab Course	·						
Course Ti		ENGINEERING PHYSICS								
Course Co	ordinator									
Course Ol	ojectives	To provide fu	undamental knowle	dge of classical	physics and	d quantum mechanics				
Course Or	utcomes					Cognitive Levels				
C01	To underst medium.	and the conce	pts of Electrostatics	s in vacuum an	d dielectric	Understand (Level-II)				
CO2	Analyze the	e magneto stat	ic in linear magneti	c medium.		Analyze (Level-IV)				
CO3	Apply the differential	•	w and Maxwell's	equation in in	itegral and					
CO4			ots of semiconducto	r physics.		Understand				
		1		1 9		(Level-II)				
Semester		2 nd		Sprin	g	· · · · ·				
Contact H		Lecture	Tutorial	Practical	Credits	Total Teaching Hours				
Contact n	ours	3	0	2	4	48				
-	site course ith course	5	0		1	TU				
names	ten course									
Equivaler	nt course									
codes	as per									
proposed	1									
and old co										
Text Bool	KS									
1.	Title	Introduction to Electrodynamics								
	Autho	r D. J. Griffiths								
	Publi	sher Ad	dison Wesley							
	Editio	on 3 rd	n 3 rd ed. (1999)							
2.	Title		Physics							
	Autho		lliday and Resnick							
	Publi	,	n Wiely							
2	Editio		edition 2006							
3.	Title		inciples of Electroni	c Materials and	Devices					
	Autho Publi		D. Kasap ta-McGraw Hill							
	Editio		edition 2017							
Reference		JII 4 ^{III}								
1.	Title	FL	ectricity, magnetisr	n and light						
1.	Autho		Saslow	n anu ligilt						
	Publi		ademic press							
	Editio		-							
Course	UNIT		~-							
Contents		rostatics in v	acuum:							
			ectrostatic potentia	l for a charge o	distribution	; Divergence				
			rostatic field; La							
			ial and uniqueness			-				
			on and thermal cond							

	field and electrostatic potential; Energy of a charge distribution and its expression in terms of electric field. Electrostatics in a linear dielectric medium: Electrostatic field and potential of a dipole; Bound charges due to electric polarization; Electric displacement; boundary conditions on displacement; Solving simple electrostatics problems in the presence of dielectrics – Point charge at the centre of a dielectric sphere, charge in front of a dielectric slab, dielectric slab and dielectric sphere in uniform electric field.	
	UNIT II: Magnetostatics:	
	Bio-Savart law, Divergence and curl of static magnetic field; vector potential and calculating it for a given magnetic field using Stokes' theorem; the equation for the vector potential and its solution for given current densities. Magnetostatics in a linear magnetic medium: Magnetization and associated bound currents; auxiliary magnetic field H; Boundary conditions on B and H. Solving for magnetic field due to simple magnets like a bar magnet; magnetic susceptibility and ferromagnetic, paramagnetic and diamagnetic materials; Qualitative discussion of magnetic	08
	field in the presence of magnetic materials.	
	UNIT III: Faraday's law: Faraday's law in terms of EMF produced by changing magnetic flux; Lenz's law; Differential form of Faraday's law and calculating electric field due to changing magnetic fields in quasi-static approximation; Energy stored in a magnetic field; Magnetic field due to time-dependent electric field and Maxwell's equations: Continuity equation for current densities; Displacement current and magnetic field arising from time-dependent electric field; Calculating magnetic field due to changing electric fields in quasistatic approximation; Maxwell's equation in vacuum and non-conducting medium; Energy in an electromagnetic field; Flow of energy and Pointing vector with examples.	08
	UNIT IV Semiconductor physics: Introduction to semiconductors; Energy bands; Quantum theory and fundamentals of band structure; Fermi-Dirac distribution; Density of states; Doping and intrinsic carrier concentration; Equilibrium carrier concentration; Temperature-dependence of carrier concentration; High doping effects; Carrier scattering and mobility; Introduction to diffusion; Drift-diffusion and trap statistics; basics of semiconductor opto-electronics	08
Course Assessment	Continuous Evaluation 25% Mid Semester 25%	
	End Semester 50%	
Tentative List of Experiments-	Experiments on electromagnetic induction and electromagnetic braking LC circuit and LCR circuit Determination of semiconductor bandgap Determination of Planck's constant using LED Basic experiments with PN junction diode, Zener diode, and LED Resonance phenomena in LCR series and parallel circuits Magnetic field from Helmholtz coil	
	Magnetic field from Heinfiloldz con Measurement of Lorentz force in a vacuum tube	

Course C	Code: CSV	B Allied		HM	Course:	PC	Course:	(Y/N)	PE Cours	e: (Y/N)
204		Engineer	•	(Y/N)						
		Course: (Y/N)							
		Y		N		Ν			N	
Type of C		Theory Co								
Course Ti		PROBLEM	I-SOL	VING AN	D COMPU	TER	PROGR	AMMING		
	ordinato						-			
Course Ol	bjectives	To give the between t			l knowled	lge of	f compu	ter archite	ecture and	interaction
Course Ou	utcomes								Cogniti	ve Levels
		nd compute	-			-				lerstand
CO1		ner interface with the goal of improving students' abilities to						D (L	evel II)	
		pout the execu			<u> </u>					
CO2		write system	softw	vare, and	l enhance	the p	performa	ance of the		Apply
		s they write.					-		,	evel III)
CO3	-	the basis for o		-			-	g Systems		nalyze
		r Networks or								evel IV)
CO4		e programm		-	y teachin	g th	e basic	concept		valuate
	•	ng all compute	er syst	ems.					(L	evel V)
Semester		2 nd						9	Spring	
		Lecture	Т	utorial		Pra	ctical	Credits	Total	Teaching
Contact H	ours								Hours	
		3	0			2		4	48	
Prerequis	site cours	e								
codes w	ith cours	e								
names										
Equivaler	nt cours	e								
codes	as pe									
proposed		e								
and old co										
Text Book										
1.	Tit	-	Computer Systems: A Programmer's Perspective					ve		
		thor	5							
		blisher								
0		ition	3 rd	1-			.1	. .		
2.	Tit		Advanced Programming in the Unix Environment							
Autho										
		blisher								
Deferre		ition	on 1992							
Reference			D1	low C-1		~~~	min = C			
1. Tit			Problem Solving & Programming Concepts Maureen Sprankle, Jim Hubbard							
		thor			ankie, jim	Hubi	bard			
		blisher								
Courses	Edition 9 th edition 2011 urse UNIT I:									
Course		IT I: roduction to evolution of computers, computational Physics, transistors,								
Contents					-		-	-		u u
	-	• • •	olithography, Moore's Law, bits, bytes, and logic, Introduction to CPU, ramming Languages.							
		igramming La	nguag	es.						
			uro	and F-	ogution.	Dom	rocontin	a and .	noninulati	ng 9
		•	am Structure and Execution: Representing and manipulating 9 mation: information storage, integer representations, integer Arithmetic							
		d floating poin								
	an	a nouting poin	165 1410		ever repre	Juna		Programs	11 1130011	

	perspective, program encodings, data formats, accessing information, arithmetic and logical operations, control flow, procedures, array allocation and access, heterogeneous data structures. Processor Architecture: microarchitecture, X-86-64 Extending IA32 to 64 bits, instruction set architecture, logical design and hardware control language HCL, implementations Program Optimization: Capabilities of operating compilers, expressing program performance, eliminating loop inefficiencies, reducing procedure calls, memory performance Memory Hierarchy: Storage technologies, locality, memory hierarchy, cache memories, impact of caches on program performance.	
	UNIT III: Linking: Compiler Drives, Static linking, object files, relocatable object files, symbols and symbol tables, symbol resolution, relocation, executable object files, loading executable object field, dynamic linking with shared libraries. Exceptional Control flow: Exceptions, process, system call error handling, process control, signals. Virtual memory: Physical and virtual addressing, addressing space, VM as a tool for caching, memory management, address translation, memory mapping, dynamic memory allocation, garbage collection, common memory related bugs.	9
	UNIT IV: Interaction and communication between programs: System-level input output: Introduction to operating systems, types, Unix I/O, opening and closing files, reading and writing files, reading file metadata, sharing files, I/O redirection, standard I/O, Networking Programming: Client server programming model, Networks, Global IP Internet, Sockets Interface, Web servers, Concurrency, Distributed Systems. Introduction to AI, Security needs, Management Information System, Cloud and Quantum Computing etc.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course Code: MAVL 205		AVL	Applied Science Course: (Y	/N)	HM Course: (Y/N)	PC (Course:	(Y/N)	PE Course: (Y/N)			N)
			Y	<u>/··)</u>	N	N			N			
Type of C	Type of Course		Theory Co	urse/I	ab Course							
Course Ti	itle		PROBABI	LITY T	HEORY AND STO	OCHA	STIC PR	OCESSE	S			
Course Co	oordinat	or										
Course O	bjectives	5	-		undamentals and time invariant sy			of rando	om pr	ocess a	nd ra	andom
Course O	utcomes		Ť		-				Cogr	nitive L	evels	5
C01	Unders	stand	l representa	tion of	random signals				Understand (Level II)			1
CO2	Examir	ne th	e characteri	stics of	frandom process	es				App (Leve		
CO3	Make u	ise of	f theorems r	elated	to random signal	S				Anal	-	
					5					(Leve	el IV)	
CO4	To Ass	ess tl	he propagat	ion of 1	random signals in	ı LTI s	ystems.			Evalı	uate	
										(Leve	el V)	
Semester	•		3 rd				Autur	nn				
Contact H	lours		Lecture	Τι	ıtorial	Pra	ctical	Credit	lits Total T Hours		Теа	ching
Gomtaot	louis		3	0		0		3		48		
Prerequis codes w names Equivaler	rith cou	rse										
codes proposed and old co	as l cou	per										
Text Boo												
1.	1	ſitle		Probability and Random Processes with Applications to Signal Processing								
		Autho	,									
		ubli										
0		Editic	n									
2.		<u>Fitle</u>	Probability, Random Variables and Stochastic Processes									
		Autho										
		Editic										
Reference		Juitit	/11	rourt								
1.		Title		Intro	duction to Probab	oility '	Cheory v	with Stor	hasti	r Proces	Ses	
Autho Publi Editio			or	Introduction to Probability Theory with Stochastic Processes K. L. Chung								
Course												
Contents	ι ι	JNIT	I:									
	6	_	and set operations; Probability space; Conditional probab						hility a	J D		0
			-					-	Juney e	and Bay	es	9
	t	heor	em; Combin		Probability space probability and s			-	Jinty t	and Bay	es	9
	t I	heor J NIT	em; Combin II:	atoria		sampl	ing moo	lels.	-			9

	example distributions	
	UNIT III: Joint distributions, functions of one and two random variables, moments of random variables; Conditional distribution, densities and moments; Characteristic functions of a random variable; Markov, Chebyshev and Chernoff bounds;	9
	UNIT IV: Random sequences and modes of convergence (everywhere, almost everywhere, probability, distribution and mean square); Limit theorems; Strong and weak laws of large numbers, central limit theorem. Random process. Stationary processes. Mean and covariance functions. Ergodicity. Transmission of random process through LTI. Power spectral density.	9
Course	Continuous Evaluation 25%	
Assessment	Mid Semester 25% End Semester 50%	

Course Code: ECVL 201		Open El	ective	HM Course:	PC Course:	(Y/N)	PE Course: (Y/N)			
		Course: (Y/N)	(Y/N)	Y					
		N			Ν					
Type of Course				lab Course						
Course Tit		BASICS O	F SEMI	CONDUCTOR MA	TERIALS					
Course Co										
Course Ob		To give fu	ndame	ntal knowledge of	electrical cir	cuits and	l p-n junction devices			
Course Ou							Cognitive Levels			
CO1	To underst crystals.	and the fo	ormatio	n and properties	s of semicor	nductor	Understand (Level II)			
CO2	To associat semiconduo			band structure to devices.	o the prope	rties of	Apply (Level III)			
CO3				nd transport in se	emiconducto	rs	Analyze			
604	To constant	at an avar	hand	diagnama of any	i aan du atan	hotoro	(Level IV)			
CO4		ict energy	Danu	diagrams of sem	liconductor	netero-	Evaluate			
_	structures						(Level V)			
Semester		2 nd	<u> </u>		Autun	nn				
		Lecture	Тι	ıtorial	Practical	Credits	0			
Contact H	ours						Hours			
		3	1		0	4	36			
Prerequis	ite course	Engineeri	ng Phys	sics (BSB 102)						
codes wi	th course									
names										
Equivalen	t course									
codes	as per									
proposed	course									
and old co	ourse									
Text Book	S									
1.	Title	The Materials Science of Semiconductors								
	Author	Angus	s Rocke	tt, University of Il	linois, Urban	a, IL, USA				
	Publishe	er Sprin								
	Edition	1 st Ed., 2008. [ISBN 978-0-387-25653-5]								
2.	Title	Quantum Physics of Semiconductor Materials and Devices								
	Author	Debdeep Jena								
	Publishe									
	Edition	1st Ed								
Reference			,							
1.	Title	Engin	eering	Materials						
	Author			udinski						
Publis										
	Edition			larch 2009. [ISBN		8]				
Course	UNIT I:		,	L		-				
Contents	-	of Solids:	Electro	nic band structur	es of solids.	Intrinsi	c and extrinsic			
semiconductors, Properties and the band structure, Quantum wells and confi										
		earriers in nano structures, Basic quantum mechanics and solid-state physics								
	UNIT II: Overviev		ectronic	Devices: ener	·gy hand i	n solide	s. conductors.			
	semicon	ductors	and i	nsulators, type type semiconduc	s of sem	iconduct	ors, Intrinsic			

	hall effect, thermal conductivity of semiconductors, electrical conductivity of doped materials, pn junction diodes, Schottky barriers and ohmic contacts, Semiconductor heterojunctions, Bipolar junction Transistors, Metal-Oxide- Semiconductor Filed Effect Transistors, Light Emitting Diodes, LASER diodes, Solar Cells, Photodiodes.	
	UNIT III: Aspects of Materials Science: Structures of materials, Crystal lattices, Basic thermodynamics of materials, Linking atomic orbitals to bands, Common semiconductor energy bands, Pressure and temperature dependence, Gunn diodes.	9
	UNIT IV: Semiconductor Alloys: Alloy selection, Semiconductor alloy thermodynamics, Band gap bowing, Silicon-germanium alloys, Metastable semiconductor alloys, Applications in Heterojunction bipolar transistors, Group IV semiconductors, Group III-V semiconductors. Defects in semiconductors, Growth Processes: Thin Film growth processes, physical vapour deposition, chemical vapour deposition etc.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course Code			1			
Course Code	:	HSPB 15				
		HOLISTI	C HEALTH &	& SPORTS		
Course Title	:					
Type of Course	:	Practical				
		Lecture	Tutorial	Practical	Credits	Total Lab Hours
Contact Hours		0	0	2	1	28 (P)
Pre-requisite	:	Nil				
Physical activities, Spo	orts Y	loga medita	tion Indore	and outdoo	r games et	-C
i nysicui uccivicios, ope	,1 (3), 1	ogu, meuru		and outdoo	i guines, et	

SEMESTER-III

Course 302	Code: E	CVB	Open Course		e HM Course: (Y/N)	PC Course:	(Y/N)	PE Course	: (Y/N)
001			N	. (-/)	N	Y		N	
Type of (Course		Theory	Course/	/ Lab Course				
Course T			ELECT	RONIC É	DEVICES AND CIRC	CUITS			
Course C	Coordina	tor							
Course O)bjective	S		•	ts into Electronics d introductions to				
Course O)utcomes	S						Cognitiv	e Levels
C01	of the	To acquaint the students with the construction, theory and operation of the basic electronic devices such as PN junction diode, Bipolar and Field-effect Transistors.						-	ember vel-I)
CO2	Under charao			ncept o	of BJT and MOS	transistors	and their		ember vel-I)
CO3	Analys	sis and	d applica	tions of	BJT and MOS trans	sistors.			pply vel-III)
CO4	Under charac			ncept o	of BJT and MOS	transistors	and their		alyze vel-IV)
Semeste	r		3 rd			Autur	nn		
Contact I	Hours		Lecture	e '	Tutorial	Practical	Credits	Total Hours	Teaching
		-	3	(0	2	4	48	
names Equivale codes proposed and old d	as d cou course	ırse per ırse							
Text Boo 1.		Title		Floctro	onic Devices and Ci	rauita			
1.		Autho	vr	David		icuits			
		Publis		Oxford					
		Editio		5 th	•				
2.		Title		-	electronic Circuits				
		Autho	or	Adel S.	. Sedra & Kenneth (C. Smith			
]	Publis	sher	Oxford	l				
		Editio	n	7 th					
Reference				-		-			
1.		Title			s of Semiconductor	Devices			
		Autho			ze and K. N. Kwok				
		Publis			Viley & Sons				
2		Editio	n		tion, 2006	·			
2.		Title			tate Electronic Dev				
		Autho			etman, and S. K. Ba	nerjee			
		Publis Editio		Pearso 7th odi	n ition, 2014.				
3.		Ealtio Title	11		onductor Physics a	ad Devices			
J.		Autho	r		men , D. Biswas	iu Devices			
		Publis			w-Hill Education				
				meura					

	Edition	2017						
4.	Title	Analysis and Design of Analog Integrated Circuits						
	Author	Paul Gray, Hurst, Lewis, Meyer						
	Publisher	John Willey & Sons						
	Edition	4th						
5.	Title Electronic Devices and Circuits							
	Author							
	Publisher	Pearson						
	Edition							
Course		ronic Devices	9					
Contents	characteristic Early effect – CC-Hybrid pin Transfer cha significance M model param channel length UNIT II: Amp DC Load line Stability-Bias Small signal limitations, C amplifier – C stages – Casc follower and C		9					
	UNIT III: Oscillators and Multivibrators Barkhausen criteria for oscillator – Analysis of RC oscillators – Phase shift, Wein bridge oscillators – LC oscillators – Colpitt, Hartely, Clapp, Crystal, Armstrong, Franklin and Ring oscillators, Switching characteristics of transistors, Astable Monostable and Pistable multivibrators. Schmitt trigger							
	Wein bridge Armstrong, H							
Course	Wein bridge Armstrong, H transistors – A UNIT IV: Ope The basic op representatio Amplifier, Ba Amplifier, Int filters - first o	Franklin and Ring oscillators, Switching characteristics of Astable, Monostable and Bistable multivibrators, Schmitt trigger. rational Amplifier perational amplifier and its characteristics, Block diagram n of Operational amplifier, Inverting Amplifier, Non-Inverting sic Application of Operation Amplifier: Subtractor, Summing regrator, Differentiator, Digital to Analogue Convertor, Active rder and second order filters.	9					
Course Assessment	Wein bridge Armstrong, H transistors – A UNIT IV: Ope The basic op representatio Amplifier, Ba Amplifier, Int filters - first o	Franklin and Ring oscillators, Switching characteristics of Astable, Monostable and Bistable multivibrators, Schmitt trigger. rational Amplifier perational amplifier and its characteristics, Block diagram n of Operational amplifier, Inverting Amplifier, Non-Inverting sic Application of Operation Amplifier: Subtractor, Summing regrator, Differentiator, Digital to Analogue Convertor, Active rder and second order filters. valuation 25%	9					

	de: ECVB	Open El Course: (HM Course: (Y/N)	PC C	Course:	(Y/N)	PE Course	e: (Y/N)
303		N	1/11)	N	Y			N	
Type of Cou	urse		ourse/I		1			11	
Course Titl			Theory Course/ Lab Course SIGNALS AND SYSTEMS						
Course Coo		DIGITIED		01210					
Course Obj		To provid	le the k	nowledge of diff	ferent	types	of signal	and system	ns and their
	••••	To provide the knowledge of different types of signal and systems and their transform and response analysis							
Course Out	comes			1 5				Cogni	tive Levels
		l the contin	uous ar	d discrete-time s	ignals	and sv	stems, the		derstand
		operties and representations and							evel-II)
CO2	Analyze me	thods those	e are ne	cessary for the ar	nalysis	s of con	tinuous a	nd A	nalyze
	discrete-tin	ne signals a	nd syst	ems.	-			(L	evel-IV)
CO3	Apply the	Knowledge	e of ti	me-domain repro	esenta	ation a	nd analys	sis	Apply
	concepts as	s they relat	e to dif	ference equation	s, imp	oulse re	sponse a	nd (L	evel-III)
	convolutior	,							
		•	-	ency-domain rep		tation a	and analys		Apply
	concepts us	sing Fourier	· Analys	is tools, Z-transfo	orm.	1		(L	evel-III)
Semester		3 rd				Autur	nn		
		Lecture	Τι	ıtorial	Prac	ctical	Credits	Total	Teaching
Contact Ho	urs							Hours	-
		3	0		2		4	48	
Prerequisi	te course								
codes wit	h course								
names									
Equivalent	course								
	as per								
proposed	course								
and old cou									
Text Books	5								
	m:.1	01	1 1	0					
1.	Title	-		Systems	7.11 1	:1.0		1	
	Autho			enheim, Alan S. W	Villsky	with S	. Hamid N	awab	
	Publi		Publica	tions					
2	Editio			flinger Contract	on d C	an al-			
2.	Title			f Linear Systems	anu 5	ignais			
	Autho		Lathi	ronaiter Dunge D. 1.1	inct:	20			
	Publis			versity Press Publ	icatio	115			
Doforonco	Editio	on 201	3						
Reference		C:	ماممتط	Sustama					
1.	Title		ais and on Hayl	<u>Systems</u>					
	Autho Publis		5		iona				
	Editio			and Sons Publicat	10115				
Course			フ						
			discro	te time signals:	Classi	ification	of Sign	als - Porio	dic
IONTONTO				energy and power			•		
Contents	aneri	001C even -					cer minist		
contents									
contents	signa	ls – comple	x expon	ential and sinuso	idal si	gnals –	periodici	ty – proper	ties
contents	signa of di	ls – comple screte time	x expon e comp		idal si unit	gnals – impuls	periodicit e – unit	ty–propert step impu	ties Ilse

	time and discrete time periodic signals – Explanation of properties of continuous time and discrete time Fourier series. Representation of continuous time signals by its sample - Sampling theorem – Reconstruction of a Signal from its samples, aliasing – discrete time processing of continuous time signals, sampling of band pass signals. UNIT II: Continuous time Fourier Transform and Laplace Transform analysis with examples – properties of the Continuous-time Fourier Transform and Laplace Transform basic properties, Parseval's relation, and convolution in time and frequency domains. Basic properties of continuous time systems: Linearity, Causality, time invariance, stability, magnitude and Phase representations of frequency response of LTI systems -Analysis and characterization of LTI systems using Differential Equations and Continuous time LTI systems. Laplace transform: Computation of impulse response and transfer function using Laplace transform.	9
	UNIT III: Discrete time system analysis using Difference equations, Discrete Time Fourier Transform, Discrete Fourier Transform, FFT and their property and usage in the analysis of Discrete time systems	9
	UNIT IV: Basic principles of z-transform - z-transform definition – region of convergence – properties of ROC – Properties of z-transform – Poles and Zeros – inverse z- transform using Contour integration - Residue Theorem, Power Series expansion and Partial fraction expansion, Relationship between z-transform and Fourier transform. Properties of convolution and the interconnection of LTI Systems – Causality and stability of LTI Systems. Computation of Impulse & response & Transfer function using Z Transform.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	
Tentative List of Experiments:	 MATLAB Basics, Independent and dependent variable and function generation Signal Generation: Such as unit impulse, unit step, Sinusoidal, exponential and To create user function for performing signal operations: folding, Shifting, addition for continuous and discrete time signal. Convolution and its properties for continuous and discrete time signal. Implementation of Continuous Time Fourier Series (CTFS) of continuous ptime signals. Properties of CTFS and implementation of Discrete Time Fourier Series (Discrete periodic time signals. Implementation of Discrete Time Fourier Transform (DTFT) of discrete aperiodic signals. Properties of DTFT. Implementation of Discrete Fourier Transform (DFT) of discrete time signals. 	l others. scaling, periodic DTFS) of te time

Course Co 304	ode: ECVB	-	Elective se: (Y/N)	HM Course: (Y/N)	PC C	Course:	(Y/N)	PE	Course	(Y/N)
		Ν		N	Y			Ν		
Type of Co	ourse	Theo	Theory Course/ Lab Course							
Course Tit		DIGI	TAL ELECT	RONICS						
Course Co	ordinator									
Course Ob	ojectives	-	ovide fund equential lo	amentals of digita	l logi	cs, digit	al opera	tions	and con	nbinational
Course Outcomes							Cog	gnitive L		
C01		rstand digital logic levels and application of knowledge to rstand digital electronics circuits.						Under (Leve		
CO2	Understand	d the co	oncept of dig	gital and binary sy	vstem	5			Under (Leve	
CO3	Design and	analyz	e combinat	ional logic circuit	5.				Crea (Leve	
CO4	Design and	analyz	e sequentia	ll logic circuits.					Crea (Leve	ate
Semester	I	3rd				Autur	nn			
Contact H	ours	Lectu	ire T	utorial	Pra	ctical	Credit	S	Total Hours	Teaching
Contact II	ours	3	0		2		4		48	
Equivalen codes proposed and old co	as per course									
Text Book	<u> </u>									
1.	Title		Digital Des	sign, Principles an	d Prad	tices				
	Auth	or	J. F. Waker	<u> </u>						
	Publi		Pearson Ed							
	Editi	on	4 th , 2005							
2.	Title		Digital Cor	nputer Fundamer	tals					
	Auth	or	T.C. Bratee)						
	Publi		McGraw H	ill.						
	Editi	on	2001							
Reference			DI - 1-							
1.	Title		<u> </u>	gic & Computer De	sign					
	Auth		M Morris N	Mano						
	Publi		Pearson							
Course	Edition Edition		5 th , 2011							
Course Contents			tale of Digit	tal Systems: Anal	00.00	d Digita	l signala	diai	tal circui	te
contents	Logic Stand simp XNOI	z gates, lard re lificatio R simpl	Examples o epresentation on of logic f	of IC gates, Boolea on for logic fun unctions using K- K-maps, minimiza	n Alge ctions map,	bra. s, K-ma Don't ca	ip repre	esent ition	ation, a s, XOR a	nd 9

	UNIT II:						
	Combinational Digital Circuits: Multiplexer, De-Multiplexer, Decoders, Encoder, Binary Adders and Subtractors, Binary multiplier, Binary parallel adder - Carry lookahead adder, BCD Adder, Magnitude Comparator, parity checker/generator, code converters, priority encoders, decoders/drivers for display devices, Mux/Demux, Case study: Digital trans-receiver, 8-bit arithmetic and logic unit.	9					
	UNIT III: Sequential circuits and systems: S-R, J- K, T and D flip flops, race around condition, Level and Edge triggering mechanism, Master-slave flip flop, Excitation and characteristics tables of flip-flops, realization of flip-flops using other flip-flops, shift registers, applications of shift registers, Ripple (Asynchronous) counters, Synchronous counters, design of counters, special counter IC's: Ring counter and Johnson counter. Mealy and Moore machine, state diagram, state table, Design of sequence detector.						
	state diagram, state table, Design of sequence detector. UNIT IV: Logic families: Characteristics of Digital ICs, Digital logic families: TTL, ECL and CMOS logic. Semiconductor memories and Programmable logic devices: Memory organization and operation, expanding memory size, classification and characteristics of memories, sequential memory, read only memory (ROM), read and write memory (RAM), content addressable memory (CAM). ROM as a PLD, Programmable logic array (PLA), Programmable array logic (PAL), Field Programmable Gate Array (FPGA).						
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%						
Tentative List of Experiments	 Verification and interpretation of truth table for AND, OR, NOT, NAND, NOR, Ex-NOR gates Construction of half and full adder using XOR and NAND gates and verification of its operation. To Study and Verify Half and Full Subtractor Realization of logic functions with the help of Universal Gates (NAND, NC Construction of a NOR gate latch and verification of its operation Verify the truth table of RS, JK, T and D flip-flops using NAND and NOR get Design and verification of decoder and encoder using logic gat Implementation and verification of decoder and encoder using logic gat Design and verify the 4- Bit Synchronous or Asynchronous Counter using Flop Verify Binary to Gray and Gray to Binary conversion using NAND gates of Verify the truth table of one bit and two-bit comparator using logic Gate 	ification OR) gates es ates g JK Flip only					

305	Code:	EEVL	Allied Engine		HM Course: (Y/N)	PC C	ourse: (Y/	N) P	E Course	: (Y/N)	
			Course: Y	: (Y/N)	N	N		N			
Type of Co	ourse		-	Theory Course							
Course Ti					LYSIS AND CONT	ROL T	HEORY				
Course Co		ator									
Course Ob			analysis	and con	its with foundat trol theory for m ing systems.						
Course Or	Course Outcomes							Cogniti	ve Levels		
C01		y the l vorks.	knowledg	ge of bas	ic circuital law a	ind si	mplify the	circuit		Apply evel-III)	
CO2	Anal	yze the	fundame k synthes		etwork analysis u	ising n	natrices, tw	o-port,	A	nalyze evel-IV)	
CO3		underst			of open loop an	nd clo	sed loop	control	A	nalyze evel-IV)	
CO4			domain a	nalysis ar	nd different metho	ods of	stability an	alysis.	Ev	valuate evel-V)	
Semester			3 rd				Autumn				
Contact H	lours		Lecture	e Tı	ıtorial	Prac	tical Cr	edits	Total Hours	Teaching	
			3	1		0	4		48		
Equivalen codes											
proposed and old co		ourse per ourse									
proposed and old co	l co ourse	per									
proposed and old co Text Book	l co ourse	per ourse		Network	Analysis						
proposed and old co	l co ourse	per ourse)r		Analysis Valkenburg						
proposed and old co Text Book	l co ourse	per ourse Title Autho			Valkenburg						
proposed and old co Text Book	l co ourse	per ourse	sher	M.E. Van	Valkenburg						
proposed and old co Text Book	l co ourse	per ourse Title Autho Publis	sher	M.E. Van Prentice 3 rd Ed.	Valkenburg	thesis					
proposed and old co <u>Text Book</u> 1.	l co ourse	per ourse Title Autho Publis Editio Title Autho	sher on or	M.E. Van Prentice 3 rd Ed. Network Franklin	Valkenburg Hall Analysis and Syn	thesis					
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proposed and old co Text Book 1. 2.	l co ourse	per ourse Title Autho Publis Editio Publis Editio	sher on or sher	M.E. Van Prentice 3 rd Ed. Network Franklin Wiley 2 nd Ed.	Valkenburg Hall Analysis and Syn F. Kuo						
proposed and old co <u>Text Book</u> 1.	l co ourse	per ourse Title Autho Publis Editio Title Autho Publis Editio Title	sher on or sher on	M.E. Van Prentice 3 rd Ed. Network Franklin Wiley 2 nd Ed. Control S	Valkenburg Hall Analysis and Syn F. Kuo Systems Engineer						
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proposed and old co Text Book 1. 2. 3	l co ourse	per ourse Title Autho Publis Editio Title Autho Fublis Editio Title Autho Publis	sher on or sher on or	M.E. Van Prentice 3 rd Ed. Network Franklin Wiley 2 nd Ed. Control S I. J. Nagr New Age Limited,	Valkenburg Hall Analysis and Syn F. Kuo Systems Engineer ath and M. Gopal, e International (P) Publishers	ing					
proposed and old co Text Book 1. 2.	l co ourse	per ourse Title Autho Publis Editio Title Autho Editio Title Autho Publis Editio Title	sher on or sher on or sher	M.E. Van Prentice 3 rd Ed. Network Franklin Wiley 2 nd Ed. Control S I. J. Nagr New Age Limited, Solution	Valkenburg Hall Analysis and Syn F. Kuo Systems Engineer ath and M. Gopal, International (P) Publishers s and Problems of	ing					
proposed and old co Text Book 1. 2. 3	l co ourse	per ourse Title Autho Publis Editio Title Autho Publis Editio Title Autho Publis Editio	sher on or sher on or sher sher	M.E. Van Prentice 3 rd Ed. Franklin Wiley 2 nd Ed. Control S I. J. Nagr. New Age Limited, Solution A.K. Jaira	Valkenburg Hall Analysis and Syn F. Kuo Systems Engineer ath and M. Gopal, International (P) Publishers s and Problems of ath	ing					
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	Edition	8 th Ed.					
2	Title	Control Systems: Theory and Applications,					
	Author	Smarajit Ghosh					
	Publisher	Pearson.					
	Edition	2/e	T				
Course	UNIT I:						
Contents	Law, Resistiv Colour Code Fourier seri differential e DC Circuits: S Analysis, Th Theorem, Su	rage, Ideal Voltage Source, Current Ideal Current Sources, Ohm's vely, Temperature Effect, Resistors, Resistor Power Absorption, s, Internal Resistance. Capacitance, Inductance, Transformers, es, Fourier transform, Laplace transform, and analysis of quations with constant coefficients Series and Parallel Circuits, Mesh Analysis, Loop Analysis, Nodal evenin's and Norton's Theorem, Maximum Power Transfer perposition Theorem, Millman's Theorem, Tellegen's Theorem, Y Transformation, Bridge Circuits.	9				
	Alternating C and Δ - Y Tran Two port Net parameters, ladder netwo Positive Real Functions. Pr	 AC Circuits: Circuits containing Capacitors and Inductors, Transient Response, Alternating Current and Voltages, Phasors, Impedances and Admittance, Y - Δ and Δ- Y Transformation, Bridge Circuits. Resonant Circuits. Two port Networks. Relationship between two port parameters, transmission parameters, hybrid parameters, interconnections of two port, analysis of ladder networks, Passive Filters. Positive Real Function: Driving-Point Functions, Properties of Positive Real 					
	UNIT III: Introduction: Classification of control systems - Open loop and closed loop control systems, feedback effects, Transfer Function Representation: Block diagram algebra, Signal flow graphs (SFG) - Reduction using Mason's gain formula. Time Response Analysis: Standard test signals, Time response of first order systems, Characteristic Equation of Feedback control systems, Transient response of second order systems - Time domain specifications, Steady state response, Steady state errors and error constants.						
	UNIT IV: The concept of stability: Routh-Hurwitz's stability criterion, Limitations of Routh-Hurwitz's stability. Root Locus Technique: Concept of root locus - Construction of root locus, Frequency Response Analysis: Introduction, Frequency domain specifications, Bode plot diagrams: Determination of Phase margin and Gain margin, Stability analysis from Bode plots, Polar plots.						
Course Assessment	Continuous E Mid Semeste End Semeste						

Course Co	de:	Allied	HM Course:	DC Course:	(Y/N)	DE Course: (Y/	/N)					
CSVB 306		Engineering	(Y/N)				,					
		Course: (Y/N)										
		Y	N	N	I	N						
Type of Co	ourse	Theory Course a										
Course Ti	tle	DATA STRUCT	URE AND PROGRA	MMING								
	ordinator											
Course Ob	ojectives		ims to provide									
		skills in stude	The goals of the control of the cont	ove their pro	ficiency in	n applying the	e basic					
Course Ou	itcomes				C	ognitive Level	S					
CO1	Recognize their chara		erent data structur	res and unde	rstand	Understan (Level-II)						
CO2			ons for maintain	ing commor	data	Understan						
		-	associated algorit	•		(Level-II)						
CO3			tures including st			Apply						
			ee structures, sear			(Level-III))					
	for given p											
CO4	-		e different algorit	hms for sorti	ng and	Evaluate						
	searching t	echniques.				(Level-V)						
Sem	lester		3rd		A	utumn						
		Lecture	Futorial	Practical	Credits		aching					
Contac	t Hours					Hours						
	-	3 ()	2	4	48						
	site course											
	ith course											
names Equivalen	t course											
codes	as per											
proposed	-											
and old co												
Text Book												
1.	Title	I	In Introduction to I	Data Structure	es with Ap	olications						
	Auth		Frembley & Sorenso		1							
	Publi		°MH									
	Editi	on 2	2/E, 1991									
2.	Title		Data Structures usin	ng C and C++								
	Auth		anenbaum & Auge	<u> </u>								
	Publi	isher F	earson									
	Editi	on 2	2/E, 2007									
3.	Title		The C PROGRAMMI	NG LANGUAG	E							
	Auth		3.W. Kernighan & D	.M. Richie								
	Publi		Prentice Hall									
	Editi	on 2	2/E, 1988									
Reference		•										
1.	Title	F	Fundamentals of Da	ita Structures								
	Auth Publi			ahni		E. Horowitz and S. Sahni						

	Edition	2 nd Edition, 2008						
2.	Title	Let Us C						
	Author	Y. Kanetkar						
	Publisher	Infinity Science Press						
Course	Edition	13 th Edition, 2012 DUCTION TO COMPUTER PROGRAMMING AND DATA						
Contents	STRUCTURES Introduction to pr double, char, Boo associativity. Flor constructs, Loops Definition, Chara Operations on de algorithms, Asym complexity.	 STRUCTURES Introduction to programming language, Basics of C, Basic Data types – int, float, double, char, Bool, Void. Arithmetic and logical operators: precedence and associativity. Flow of Control- Conditional statements- If-else, Switch-case constructs, Loops- While, do-while, for. Definition, Characteristics, Creation and manipulation of data structures, Operations on data structures, Types of data structures. Introduction to algorithms, Asymptotic notations, Analysis of algorithms, Time and Space 						
	Arrays, Dynamic dimensional arra representation, c Search, Binary Sea LINEAR LISTS, S Comparison of In	Sequential and Linked Representations of Linear Lists, sertion, Deletion and Search Operations for Sequential and	08					
	UNIT III: STACKS STACKS: Sequenti such as Recursio indirect recursio Parenthesis Match QUEUES: Implem	bly Linked Lists, Circular Lists, Applications of Lists. AND QUEUES al and Linked Implementations, Representative Applications on: Tail Recursion, non-tail recursion, nested recursion, n, Expression Evaluation Viz., Infix, Prefix and Postfix, ning, Towers of Hanoi. mentation of Queues-array and linked list, Operations of Queue, Priority Queue, Dequeue, Applications of Queues.	08					
	UNIT IV: GRAPHS AND TREES GRAPHS: Definition, Terminology, Directed and Undirected Graphs, Properties, Connectivity in Graphs, Applications, Adjacency Matrix and Linked Adjacency Chains, Graph Traversal, Breadth First and Depth First Traversal, Spanning Trees, Shortest Path and Transitive Closure, Activity Networks, Topological Sort and Critical Paths. TREES: Binary Trees and Their Properties, Terminology, Sequential and							
	 Inkees and Their Properties, Terminology, sequential and Linked Implementations, Tree Traversal Methods and Algorithms, Complete Binary Trees, General Trees, Binary Search Trees, AVL Trees, Threaded Trees, Heaps, Heap Implementation, Insertion and Deletion Operations, Heapsort. MULTIWAY TREES: M-Way Search Trees, B Trees, Search, Insert and Delete Operations, Height of B-Tree, 2-3 Trees. UNIT V: SORTING 							

	SORTING: Sorting Methods, Bubble Sort, Selection Sort, Quick Sort, Radix Sort, Bucket Sort, Dictionaries, Hashing, Analysis of Collision Resolution Techniques, Character Strings and Different String Operations. Algorithm design techniques: Greedy programming, Dynamic programming
Course	Continuous Evaluation 25%
Assessment	Mid Semester 25%
	End Semester 50%
Tentative List of Experiments	 To be displayed at the beginning of the semester by the concerned course In-Charge. Introduction to Programming Logic Building Basic Concepts of a Computer Programming Language Implementation of sequential constructs Implementation of selection constructs Implementation of Iterative constructs Implementation of functions (normal functions, recursive functions and parameter passing methods) Implementation of Array and its applications Implementation of Queue and its applications Implementation of Link List and its applications Implementation of Trees and its applications Implementation of Graph and its applications

SEMESTER-IV

Course C 405	Code: ECVB	Open Ele Course: (Y		HM Course: (Y/N)	PC (Course:	(Y/N)	PE Cour	se: (Y/N)
		N		N	Y			N	
Type of C	ourse	Theory Co	urse/ l	Lab Course					
Course Ti	tle	MICRO FA	BRICA	TION TECHNOL	DGY				
Course Co	ordinator								
Course O	bjectives	-		fundamental kn t designs and scali		0		methods	of CMOS
Course O	utcomes							Cognitive	e Levels
CO1 Understand the CN			process	s flow					rstand el-II)
CO2 Identify various critica			proce	ssing steps in mic	rofab	rication		-	ply el-III)
CO3 Apply the advanced me			thods	involved in IC fab	ricati	on.		Ар	ply el-III)
CO4	Analyze th technolog		ents in	CMOS process fal	oricat	ion with	scaling in	Ana	lyze el-IV)
Semester		5 th				Autum	n		,
Contact H	ours	Lecture	Τι	utorial	Pra	ctical	Credits	Total Hours	Teaching
Contact I	louis	3	0		2		4	48	
	site course ith course nt course								
codes proposed	as per								
and old c	ourse								
Text Bool			0 11						
1.	Title			n VLSI Technolog					
	Auth			mer, Deal and Gri	tfin				
	Edit	lisher		son Education					
2.	Title			dition, 2009 amental of Semico	nduc	tor Fabr	rication		
<i>L</i> .	Autl			nd May	muut				
		lisher							
	Edit								
Reference				,					
1.	Title	<u>)</u>	Silico	n Process Techno	logy				
	Autl			andhi					
	Pub	lisher	Wiley	/ India					
	Edit	ion	2nd E	Edition, 2009					
Course Contents	and Si, S	oduction: His MEMS. Electr	onic M vth. Cle	TC's; Operation & laterials: Crystal S ean room and Waf Si.	truct	ures, Def	fects in Crys	stals, Si, Pol	y 9
	UNI	T II:		et Oxidation, Kin	etics	of Oxid	lation, Oxio	lation Rate	9

	Constants, Dopant Redistribution, Oxide Charges, Device Isolation, LOCOS, Oxidation System Lithography: Overview of Lithography, Radiation Sources, Masks, Photoresist, Components of Photoresist Optical Aligners, Resolution, Depth of Focus, Advanced Lithography: E-beam Lithography, X-ray Lithography, Ion Beam Lithography.	
	UNIT III: Diffusion: Pre-Deposition and Drive-in Diffusion Modelling, Dose, 2-Step Diffusions, Successive Diffusion, Lateral Diffusion, Series Resistance, Junction Depth, Irvin's Curves, Diffusion System. Ion Implantation: Problems in Thermal Diffusion, Advantages of Ion Implantation, Applications in ICs, Ion Implantation System, Mask, Energy Loss Mechanisms, Depth Profile, Range & Straggle, Lateral Straggle, Dose, Junction Depth, Ion Implantation Damage, Post Implantation Annealing, Ion Channelling, Multi Energy Implantation	9
	UNIT IV: Thin Film Deposition: Physical Vapor Deposition: Thermal evaporation, Resistive Evaporation, Electron beam evaporation, Laser ablation, Sputtering Chemical Vapor Deposition: Advantages and disadvantages of Chemical Vapor deposition (CVD) techniques over PVD techniques, reaction types, Boundaries and Flow, Different kinds of CVD techniques: APCVD, LPCVD, Metalorganic CVD(MOCVD), Plasma Enhanced CVD etc. Etching: Anisotropy, Selectivity, Wet Etching, Plasma Etching, Reactive Ion Etching. Overview of Interconnects, Contacts, Metal gate/Poly Gate, Metallization.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	
Tentative List of Experiments	 Learn the techniques of Micro fabrication (Process simulator) Etching process Printing process Metallization 	

Course Co 406	ode: ECV		Open Elect Course: (Y/N		ourse:	PC C	ourse:	(Y/N)	PE Cou	rse: ((Y/N)
100			N	N N		Y			N		
Type of Co	ourse	, r	Theory Course/ Lab Course								
Course Tit				TEM DESIGN							
Course Co	ordinato	r									
Course Ob	ojectives	r	To give the	fundamental	knowle	dge o	f digita	l combin	ational	and s	sequential
		(circuits with	the help of HD	L and E	DA to	ol				
Course Ou	itcomes								Cog		e Levels
CO1 Design, and			rsis and optin	nization of syn	chrono	us ciro	cuits.				alyze el-IV)
CO2	Design,	analy	sis and optin	nization of asy	nchron	ous ci	rcuits				alyze el-IV)
CO3	To get e	xposı	ure to FPGA a	rchitecture ar	nd Verilo	og HD	L			Ana	alyze el-IV)
CO4	Use HD simulati		ıd appropria	te EDA tools	s for d	igital	logic	design a	nd	Ap	oply el-III)
Semester	Simulat		4 th				Spring	g		(101	01 111
Contact Ho	ours]	Lecture	Tutorial		Prac	tical	Credits	Tot Hou		Teaching
contact m	ours		3	0		2		4	48		
Equivalen codes proposed and old co	as p cour	er									
Text Book											
	KS										
1.		tle	Digit	al Design with	n an intr	oduct	ion to H	IDL, VHD	L and Ve	rilog	
	Ti	tle 1thor		al Design with Iorris Mano an				IDL, VHD	L and Ve	rilog	
	Ti Au Pu	ithor Iblish	M. M M. M	lorris Mano an son education	d Miche			IDL, VHD	L and Ve	rilog	
1.	Ti Au Pu Ec	ithor iblish lition	M. M ner Pear Sixth	lorris Mano an son education edition	d Miche	el. D. (IDL, VHD	L and Ve	rilog	
	Ti Au Pu Ec Ti	ithor iblish lition tle	M. M ner Pear Sixth Func	lorris Mano an son education edition damentals of L	d Miche	el. D. (IDL, VHD	L and Ve	rilog	
1.	Ti Au Pu Ec Ti Au	ithor iblish lition tle ithor	M. M. Mer Pear Sixth Func Char	lorris Mano an son education edition lamentals of L les H. Roth Jr	nd Miche ogic De	el. D. (IDL, VHD	L and Ve	rilog	
1.	Ті Ац Рс Ес Ті Ац Рг	ithor iblish lition tle ithor iblish	M. M. ner Pear Sixth Func Char ner Thor	lorris Mano an son education edition damentals of L des H. Roth Jr mson Learning	nd Miche ogic De	el. D. (IDL, VHD	L and Ve	rilog	
1. 2.	Ті Ац Ри Ес Ті Ац Ри Ес	ithor iblish lition tle ithor iblish lition	M. M. ner Pear Sixth Func Char ner Thor 2004	lorris Mano an son education edition lamentals of L les H. Roth Jr nson Learning 1	d Miche ogic Des	el. D. (sign	Ciletti				
1.	Ті Ац Ри Ес Ті Ац Ри Ес	ithor iblish lition tle ithor iblish	M. M. M. M. Pear Sixth Func Char her Thor Adva	lorris Mano an son education edition damentals of L des H. Roth Jr mson Learning	d Miche ogic De	el. D. (sign			L and Ve		
1.	Ti Au Pu Ec Ti Au Pu Ec Ti Ec	ithor iblish lition tle ithor iblish lition tle	M. M. ner Pear Sixth Func Char ner Thor Adva Optimer Steven	lorris Mano an son education edition damentals of L damentals of L	d Miche ogic Des	el. D. (sign	Ciletti				
1. 2.	Ti Au Pu Ec Ti Au Pu Ec Ti Ec	ithor iblish lition tle ithor iblish lition tle	M. M. ner Pear Sixth Func Char ner Thor Adva Optimer Steven	lorris Mano an son education edition damentals of L damentals of L	d Miche ogic Des	el. D. (sign	Ciletti				
1. 2. 3.	Ті Ац Ри Ес Ті Ац Ри Ес Ац Ри Ес	ithor iblish lition tle ithor iblish lition tle	M. M. M. M. Ner Pear Sixth Func Char her Thor Adva Optim Steven her Wile	lorris Mano an son education edition lamentals of L les H. Roth Jr nson Learning anced FPGA mization e Kilts y	d Miche ogic Des	el. D. (sign	Ciletti				
1. 2.	Ті Ац Ри Ес Ті Ац Ри Ес Ац Ри Ес	ithor iblish lition tle ithor iblish lition tle ithor iblish	M. M. M. M. Ner Pear Sixth Func Char her Thor Adva Optim Steven her Wile	lorris Mano an son education edition lamentals of L les H. Roth Jr nson Learning anced FPGA mization e Kilts y	d Miche ogic Des	el. D. (sign	Ciletti				
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	Publisher	Nelson Engineering	
	Edition	2005	
2.	Title	Verilog HDL	
	Author	Samir Palnitkar	
	Publisher	Pearson	
	Edition	2 nd Edition 2003	
Course	UNIT I: Seque	ential Circuit Design	
Contents	diagram, stat synchronous realization usi		9
	Analysis of asy assignment – asynchronous synchronizers electronic voti	chronous Sequential Circuit Design mchronous sequential circuit – flow table reduction – race -state transition table and problem in transition table – design of sequential circuit – Static, dynamic and essential hazards – data – mixed operating mode asynchronous circuits – designing ing machine, vending machine controller.	9
	Logic design w behavioural a synthesis of c synthesis of d algorithms a	oduction to Verilog HDL with Verilog: Introduction to Verilog, logic design with structural, and data flow models of combinational and sequential logic, combinational, sequential logic and state machine, Design and ata path controllers, programmable logic and storage devices, and architectures for digital processors, architectures for processors, Case study: FIFO, Traffic signal controller, newspaper ine.	9
	UNIT IV: Desi Overview, pro architectures, (Utilize comm synthesis, imp	gning with FPGAs gramming technologies, configurable logic block, FPGA routing Design flow for FPGAs, prototyping with FPGAs, and debugging. nercial FPGA development tools for compilation, simulation, elementation, and debugging), Case studies of FPGA applications programmable chip (SoPC) Design.	9
Course Assessment	Continuous Ev Mid Semester End Semester	25%	

Course Co 407	ode: ECVB	Open Ele Course: (Y		HM Course: (Y/N)	PC (Course:	(Y/N)	PE	E Course:	: (Y/N)
		N		N	Y			Ν		
Type of Co	ourse	Theory Cou	urse/ I	ab Course						
Course Tit	tle	ANALOG C	ОММ	JNICATION						
Course Co	ordinator									
Course Ob	ojectives	-	To provide fundamental knowledge of analog modulation and demodulation techniques, Transmitter and receiver circuits and pulse modulation techniques							
Course Ou	itcomes	•					•		gnitive L	
CO1				s of Amplitude Mo n techniques.	dulat	ion, Fre	quency		Under (Leve	
CO2		•		nunication modul	ation	technic	lues		Anal (Leve	yze
CO3	Understand	d the concept	t of rac	lio receivers					Under	stand
CO4	Analyza the	e pulse modu	lation	techniques					Leve) Anal	
604	Analyze the	e puise modu	natioll	teeninques					(Leve	•
C		A th				C			(Leve	1-1VJ
Semester		4 th			r	Spring	-			
Contact H	ours	Lecture	Τι	ıtorial	Pra	ctical	Credit	ts	Total Hours	Teaching
		3	0		2		4		48	
names Equivalen codes proposed and old co	as per course									
Text Book	76									
1.	Title		Flect	onic Communica	tion S	vstems				
1.	Auth	or		edy, Davis		ystems				
	Publi			aw Hill						
	Editi		4/e, 1							
2.	Title			nunication System	ns					
	Auth	or	S. Hay	/kins						
	Publi	sher	Wiley							
	Editi	on	4/e, 2							
Reference	Books		<u> </u>							
1.	Title		Intro	duction to Comm	unicat	tion Syst	tems			
	Auth	or	B. Car	lson						
	Publi	sher	McGr	aw-Hill						
	Editi	on	4/e, 2	.009						
CourseUNIT I:ContentsIntroduction: Introduct transmission media, co usage, Review of Sig				ncept of bandwid	th, ele n usi	ectroma ng Fou	gnetic sj rier Se	pectr ries	um and & Fouri	its .er o
				experimental dete	-					

	in temperature limited diode and space charge limited diodes, Pulse response	
	and Digital noise.	
	UNIT II:	
	Analog Modulation Techniques: Introduction and need of modulation, Theory of Amplitude Modulation; Amplitude modulation, DSB, SSB, (with and without carrier), VSB, Power Calculations, Generation of AM. Theory of Frequency Modulation (FM); FM and PM, Transmission FM spectra, Carson 's rule, Bandwidth of FM, reactance FET modulator Armstrong method, Foster-Seely discriminator, PLL detector, Stereophonic FM, Narrow band and wide band FM. Comparison of FM and PM.	9
	UNIT III:	
	Radio receivers: Tuned radio frequency receiver, Super heterodyne receiver, Sensitivity and selectivity, selection of IF. Block diagram and features of Communication Receiver and its spectral features.	9
	UNIT IV:	
	Pulse Modulation Transmission and Reception: Sampling Theorem–low pass and band pass, Pulse Amplitude Modulation (PAM), Pulse Time Modulation (PTM); Pulse Width Modulation (PWM).	9
Course	Continuous Evaluation 25%	
Assessment	Mid Semester 25%	
	End Semester 50%	
Tentative List	1. Study of AM Modulation/Demodulation.	
of	2. Study of FM Modulation/Demodulation.	
Experiments :	3. Study of Diode detector and AGC.	
	4. To study Sampling theorem.	
	5. Sensitivity of a super het Receiver.	
	6. Selectivity of a super het Receiver.	
	7. Fidelity of a super het Receiver.	
	8. Study of Pulse Amplitude Modulation/Demodulation.	
	9. Study of Pulse Width Modulation/Demodulation.	
	10. Study of Pulse Position Modulation/Demodulation.	

	ode: ECVL	-	Elective		PC C	ourse:	(Y/N)	PE Cou	rse: (Y/N)
408		N	se: (Y/N)	(Y/N) N	Y			N		
Type of Co	NILLEO		w Course /	Lab Course	I			IN		
Course Tit				ORS AND MICROC	ONTE		с			
	ordinator	MICK	OI NOLES			OLLEN				
Course Ob		Το σα	in the fund	amental concept of	of mic	rocontr	ollers and	1 micror	rocas	sor their
course of	Jectives									
Course Ou	itcomes	mstru	instruction set, addressing mode and program for 8085, 8086 and 8051. Cognitive Leve							
		te the a	rchitecture	e of 8085, 8086, 80)51ano	ARM a	and their	0	nders	
co1 addressing					/o run				Level	
CO2				se of Peripherals	and	Interfa	cing and		nders	
001				m design techniqu					Level	
CO3				ISC architecture a		explore	the ARM		nders	
	architectu								Level	
CO4			cessor and	l microcontroller-	based	svsten	n design		Analy	,
		-		bedded S/W deve			0	(Level	
Semester	· •	5 th		•		Autun	nn			
		Lectu	ro T	utorial	Drag	tical	Credits	Tot	al r	Feaching
Contact H	ours	Lettu		utoriai	TTac	licai	cieuits	Ho		leathing
Contact II	ours	3	0		2		4	48	115	
Prerequis	ite course	5	0		4		1	10		
-	th course									
names	eourse									
Equivalen	t course									
codes	as per									
proposed	-									
and old co										
Text Book	(S									
1.	Title		Micropro	cessor Architectu	e, Pro	gramm	ing and A	pplicatio	ons wi	ith 8085
	Auth	or	Ramesh S	5. Gaonkar						
	Publ	isher	Penram I	nternational Publi	shing	reprint				
	Editi	on	6th Editio	on, 2017						
2.	Title			cessor and Interfa	cing, F	Progran	nming and	l Hardw	are	
	Auth		Douglas V							
		isher	Tata McG							
	Editi	on	Revised 2	2ndEdition 2006, 12	lth rep	orint 20	15			
Reference			-							
1.	Title			Microcontroller a						
	Auth			ad Ali Mazidi, Jani	ce Gill	ispie M	azidi and	Rolin D.	МсКі	nley
		isher	Pearson I		<u> </u>					
-	Editi		2 nd Editio	n,12th impression	2018					
Course	UNI			0006 1 1 1						
Contents				8086 Architecture						
			-	les, 8086 Instru						
		-	and Ass	embler directive	s, 808	bo inte	errupts a	ina inte	errupt	
	appi UNI	ications								
			lo Dorinh	oral Interface (0	2551	Kowhar	and diam		rollar	
			-	eral Interface (8 DAC0808 Interfa	-	-	-	-		u
	-	-		e interrupt contro		•				
	-	4), P108	-		mei (0237J,		minum	auoii	
	me	1000 [02	.51).							

	UNIT III: 8051 – Architecture, Special Function Registers (SFRs), Instruction set,	9
	Addressing modes, Assembly language programming, I/O Ports, Timers /	
	counters, Interrupts and serial communication.	
	UNIT IV:	
	RISC Vs CISC Architecture, ARM Processor Architecture, ARM Core data flow	
	model, Barrel Shifter, ARM processor modes and families, pipelining, ARM instruction Set and its Programming.	9
	Interfacing to: matrix display, (16x2) LCD, high power devices, optical motor	
	shaft encoder, Stepper Motor, DC Motor speed Control using PWM, RTC and	
	EEPROM interface using I2C protocol.	
Course	Continuous Evaluation 25%	
Assessment	Mid Semester 25%	
Assessment	End Semester 50%	
Tentative List		
of	1. Programs for 8 / 16 bit Arithmetic, Sorting, Searching and String operations.	
Experiments:	2. Programs for Digital clock, Interfacing ADC and DAC.	
Experiments.	3. Interfacing and programming 8279, 8259, and 8253.	
	4. Serial Communication between two microprocessors kits using 8251.	
	5. Interfacing Stepper Motor, Speed control of DC Motor	
	6. Parallel communication between two microprocessors kits using Mode 1 and	Mode 2
	of 8255.	
	7. Macro assembler Programming for 8086.	
	8051 based experiments using assembly language and C programming:	
	8. Programming using Arithmetic, Logical and Bit Manipulation instructions of t microcontrollers.	he 8051
	9. Programming and verifying Timer, Interrupts and UART operations i	n 8051
	microcontrollers.	11 0051
	10. Interfacing – DAC and ADC and 8051 based temperature measurem	
	Interfacing - LED and LCD 12. Interfacing - Stepper motor and traffic light	control
	system.	
	13. Communication between 8051 Microcontroller kit and PC.	
	14. Programming ARM processor using Embedded C.	

	ode: ECVB		Elective	HM Course:	PC Course	e: (Y/N)	PE Course: (Y	//N)
409		N	e: (Y/N)	(Y/N) N	Y		N	
Type of C	nurse		Course / I	Lab Course	I		IN	
Course Ti				PROCESSING				
	ordinator							
Course Ol		To gain	the know	ledge of digital fil	tering techn	iaues of dis	crete time sign	als. their
	-,			eir mathematical				,
Course Ou	utcomes	•					Cognitive	Levels
C01	Define dis	crete-tim	e signals a	nalytically and v	isualize the	m in the tin	ne Remei	mber
domain.							(Leve	,
CO2			aning and	implications of t	he properti	es of syster		
	and signal						(Leve	<i>.</i>
CO3				omain and its si	gnificance a	and probler		
CO4	related to				aing MATI	۸D	(Leve Evalı	1
604	Assess to S	pecity an	u uesign a	ny digital filters u	ISTIIG MATL	ND	Leve	
Semester	L	4 th			C	na		,1 V J
Semester					Spri	I	m	
Combo at II		Lectur	e Ti	ıtorial	Practical	Credits		eaching
Contact H	ours	3	0		2	4	Hours 48	
Droroquie	site course	-	0		2	4	40	
-	ith course							
names	itii tourse							
Equivaler	nt course							
codes	as per							
proposed								
and old co								
Text Bool								
1.	Title			ignal Processing:	A Computer	r-Based App	broach	
	Auth		S. K. Miti					
		isher	McGraw					
2.	Edit Title			ition, 2006 -Time Signal Proc	accina			
2.	Auth			heim and R. Scha	U			
		isher	Prentice					
	Edit		-	edition, 1999				
Reference				•				
1.	Title		Schaum'	s Outline of Digita	al Signal Pro	ocessing		
	Auth	or	M. Hays					
		isher	McGraw	-Hill				
	Edit	on	1999					
Course								
Contents	UNI		to Digital	signal processing	. Ouomria	of Turnian	Digital signal	
			•	signal processing ld applications, 1		• •	• •	9
	-			Discrete time sy		•	-	9
	-	riant syst	-	Discrete time sy	sterns, then	i properties	, mear unic	
	UNI							
			by summa	tion of left, right,	and two-sid	led sequenc	es, Regions of	9
				sform properties				
			ition of Dif					

	UNIT III: Definition of Discrete Fourier Transform (DFT) and relation to Z-transform, Properties of the DFT, Matrix Formulation of the DFT and IDFT, Linear and periodic convolution using the DFT, zero padding, spectral leakage, resolution	9
	and windowing in the DFT. UNIT IV: Structures and properties of FIR and IIR filters, IIR– Direct, parallel and cascaded realizations, FIR – Direct and cascaded realizations, Coefficient quantization effects in digital filters. Digital filter design, Finite impulse response (FIR) filters-Window design techniques, Kaiser Window design technique, Equi-ripple approximations, Infinite impulse response (IIR) filters- Bilinear transform method, Examples of bilinear transform method.	9
Course	Continuous Evaluation 25% Mid Semester 25%	
Assessment	End Semester 50%	
Tentative List of Experiments:	 Study of Floating-Point Digital Signal Processor & Fixed-Point Digital Signal Preserve Realisation of Circular & Linear Convolution and Correlation of two sequences. Computation of DFT & IDFT of a given Sequence using DSP Processors. Classification, denoising of real time signals. Radix-2 & Radix-4 algorithm FFT Calculation using DSP Processors. FIR & IIR Filter Implementation using the DSP Processors. Basics of MATLAB-Realisation of Unit Impulse, Unit Step & Unit Ramp signals. Linear & Circular Convolution of two Sequences, Correlation of two sequences. DFT & IDFT Computation. Radix-2 algorithms FFT Calculation. Generation of Gaussian Distributed Numbers. 	s.

Course Code	:	ECVP 410				
		Mini Proje	ect			
Course Title	:					
Type of Course	:	Program (Core		-	-
		Lecture	Tutorial	Practical	Credits	Total Lab Hours
Contact Hours		0	0	2	1	
Pre-requisite	:	Nil				
Mini project related	d with t	he Microele	ctronics/VL	JSI/ECE.		

SEMESTER-V

Course (511	Code: ECV	B Open Course:		HM Course: (Y/N)	PC (Course:	(Y/N)	PE	Course	: (Y/N)	
		Ν		N	Y			Ν			
Type of C	lourse	Theory	Course/l	Lab Course							
Course T			L COMM	UNICATION							
	oordinato										
Course O	bjectives	-		fundamental knov tal systems	wledg	e of dig	ital moo	lulat	ion tech	niques and	
Course O	utcomes							Cog	gnitive L		
C01	To unde	rstand the bı	uilding bl	ocks of digital com	ımun	ication s	system.		Under (Leve		
CO2		d up concep lication syste	concept and analyze the signal flow in a digitalApplyon system(Level-III)								
CO3		<u> </u>		e of a digital comm	nunica	ation sys	stem.		Anal	yze	
CO4	To unde	rstand conce	pt of spr	ead spectrum com	imun	ication s	system.		Leve) Under		
			1 1	L.		-	5		(Leve	el-II)	
Semester	•	5 th				Autun	nn				
Contact F	Contact Hours		T	utorial	Pra	ctical	Credit	Credits Total Hours		Teaching	
Gontaet	louib	3	0		2		4		48		
codes w names Equivale codes proposed	as p l cour	se er									
and old c Text Boo											
1.	KS Ti	le	Princir	oles of communica	tion	systems					
		ithor	r Taub & Schilling								
	Pu	blisher									
	Ed	ition									
2.	Ti		Communication systems								
		thor		Haykin							
		blisher		Viley & sons, Inc.							
Referenc		ition	4rth E	dition							
1.	e BOOKS	le	Digital	and Analog Comn	nunic	ation Su	steme				
1.		ithor	Couch	and Analog Collin	iume	ation sy	3101113				
		blisher									
		ition	6 th Edi								
Course Contents	UN Re Pr In co	NIT I: view of prol ocess, Noise formation T mpression,	oability t e, Narro Theory: Discrete	heory and Stochas owband Noise, S Entropy, Source Memoryless cha oding Theorem,	inewa Cod nnel,	ave plu ing Th Mutual	s Narro eorem, Inform	owba Los: atioi	nd Nois sless da n, Chanr	se. 9 nta nel	

	Information for Continuous Random Ensembles, Information Capacity Law. Sampling Theory, PAM, Quantization characteristics, PCM, DPCM, Delta Modulation, Line Codes UNIT II: AWGN Channel Signalling: Geometric Representation of Signals, Conversion of Continuous AWGN Channel to a vector channel, ASK, QASK, FSK, M-array FSK, BPSK, DPSK, DEPSK, QPSK, M-array PSK, QAM, MSK, GMSK, Coherent and non-coherent detection and other keying techniques.	9
	UNIT III: Band Limited Channels: Error rate due to channel noise in a matched filer receiver, Intersymbol Interference, Signal Design for Zero ISI, Ideal Nyquist Pulse for Distortionless Baseband data transmission, raised cosie and square root raised cosine spectrum, Eye pattern, Adaptive equalization, signalling over multiple baseband channel, Digital Subscriber Lines Fading Channels: Propagation effects, Jakes Model, Statistical Characteristics of wideband wireless channel, FIR modelling of doubly spread channel, Effects of flat fading, Diversity techniques, MIMO, MIMI Capacity for channel known at receiver, OFDM, Spread-spectrum signals, CDMA, Rake receiver and Multipath Diversity	9
	UNIT IV: Error Control Coding: Introduction, Error Control using forward correction, Discrete Memory less channel, Linear Block Code, Cyclic Codes, Convolutional Codes, Optimum Decoding of Convolutional Codes.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

	ode: ECVB	-		HM Course:	PC	Course:	(Y/N)	PE	Course:	(Y/N)			
512		Course: (Y/	N)	(Y/N) N	Y			N					
Type of Co	011760		rco / L /		ľ			IN					
Course Ti			Theory Course/ Lab Course DIGITAL VLSI DESIGN										
	ordinator		JI DE	Siun									
Course Ob		To provide	in-de	pth understandi	ing	of the V	'LSL des	ign 1	nrocess a	nd digital			
	sjeenves	-		and basic idea o	-					ina angitar			
Course Ou	utcomes	1							gnitive Le	vels			
	1	ne design of dig	gital in	ntegrated circuits	s, M(OS fundar	nentals		Unders				
CO1	-		0	digital circuits.					(Level	-II)			
CO2	Design and	study the MO	S inve	rters and combin	natio	onal circu	iits,		App	ly			
									(Level	-III)			
CO3	•		equent	tial circuit, dynar	nic l	ogic circu	iits and		Crea				
	MOS memo								(Level				
CO4	To underst	and the VLSI c	lesign	flow and design	styl	es.			Unders				
		1							(Level	-II)			
Semester		5 th				Autur	nn						
		Lecture	Tu	torial	Pr	actical	Credit	s	Total	Teaching			
Contact H	ours								Hours				
		3	0		2		4		48				
-	site course												
codes wi names	ith course												
Equivalen	nt course												
codes	as per												
proposed													
and old co													
Text Book						_							
1.	Title		CMOS Digital Integrated Circuits										
	Auth												
	Publi			McGraw Hill									
2	Editi	on	2014				. D		_				
2.	Title	o.n		al Integrated Circ		-		ective	е				
	Auth Publi		J.M R Pears	abaey, A. Chandr	ака	san, B.Ni	KOIIC						
	Editi		2012										
Reference		011	2012										
1.	Title		Intro	duction to VLSI (lirc	uits and S	lystems						
1 .	Auth	or		Jyemura	J I U	and and d	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,						
	Publi		Wile	2									
	Editi		2006										
Course	2	-											
Contents	UNIT	I:											
			c prin	ciple of MOS tra	nsis	tor, Intro	oduction	to la	arge signa	al			
				el) for digital des	<u> </u>				-				
		•		Simulation and			•	<u> </u>		u u			
				MOS layout: desi	-			-		r			
	-		CMOS	S basic manufact	turi	ng steps.	CMOS 1	atch-	up and it	S			
		ention.								-			
	UNIT		Ŧ		.1		100 .			9			
	The	MUS Inverter	: Inve	erter principle,	tne	Dasic Cl	MUS INV	erter	, transfe	r			

	characteristics, logic threshold, Noise margins, switching characteristics, Propagation Delay, Power Consumption. Combinational MOS Logic Design: Static MOS design, Ratioed logic, Pass Transistor logic, complex logic circuits. CMOS Transmission Gates, Complementary Pass Transistor Logic, Transistor sizing in static CMOS, logical effort, Pass-transistor logic, sizing issues.	
	UNIT III: Sequential Logic Circuits: Introduction, Static Latches and Registers, Dynamic Latches and registers, Pipelining. Timing issues in Digital Circuits: Timing classification of digital systems, Synchronous Design Timing basics, clock skew, clock jitter and their combine impact. Dynamic Logic Circuits: Voltage Bootstrapping, Synchronous Dynamic Logic, Dynamic CMOS Logic, High Performance Dynamic CMOS Circuits, Domino CMOS logic, NP-Domino Logic, Zipper CMOS Circuits, TSPC Dynamic CMOS.	9
	UNIT IV: VLSI Design Methodologies, VLSI Design Flow, Design Hierarchy, Concepts of Regularity, Modularity and Locality, VLSI Design Styles. CMOS Sub system design: Adders, Multipliers, MOS memories: Introduction, DRAM and SRAM.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	
Tentative list of Experiments		

Course 513	e Code: ECVB	Open E Course: (Y	ective (/N)	HM (Y/N)	Course:	PC (Y/N)	Course:	PE Cour	se: (Y/N)			
515		N	/\\	N		Y		N				
Type o	f Course	Theory Co	urse/La		<u>,</u>	-		11				
Course		, , , , , , , , , , , , , , , , , , ,	SEMICONDUCTOR PACKAGING AND TESTING									
	Coordinator											
Course	Objectives	To enhan semicondu			dge of p	ackagin	g and tes	ting tech	nology of			
Course	Outcomes	÷						Cognitiv	e Levels			
CO1	Understand var speed, signal, an		•••		ong with a	ssociate	ed thermal,		erstand vel-II)			
CO2	Plan the design vibrations, and s	of package			nstand hig	her ten	iperatures,	-	pply vel-III)			
CO3	Design of PCBs t		e the EM	I and op	erate at a h	igher fro	equency	Cr	eate vel-VI)			
CO4	Analyze the con	cepts of Test	ing and t	esting m	ethods.			An	alyze vel-IV)			
Semes	ter	7 th				Autun	n	(20)				
Contac	t Hours	Lecture	Tuto	rial		Prac tical	Credits	Total Hours	Teaching			
		3	0			0	3	36				
Text B												
1.	Title	Fu	damon	tals of Mi	crosystem	e Dackad	ting					
1.	Author		R. Tum		<u>ci osystem</u>	S I acraz	Sillg					
	Publisher		Graw Hi									
	Edition	20		,								
2.	Title	Ad	vanced I	Electroni	c Packagin	g						
	Author		William D. Brown									
	Publisher		IEEE Press									
	Edition	19	1999									
	nce Books				1.5.	1	, ,					
1.	Title			cuit Boai	ds Design	and Tec	hnology					
	Author		sshart McCro	LI:11								
	Publisher Edition		TataMcGraw Hill 1988									
Course		190	0									
Conten		of electroni	c systen	is nacka	ging: Intro	duction	and Ohiect	tives of th	ne			
	course de of packagi Overview Silicon", V evolution,	finition of a s ng, Packagin Basics of So Vafer fabrica Chip conneo Need for	system a g aspect emicond tion, ins ction cho	nd histo ts of hand luctor ar spection bices, Wi	ry of semic dheld prod ad Process and testin re bonding	conducto ucts. Sei flowcha g, Wafei g, TAB a	ors, Products miconductor art; Video o r packaging and flipchip-	s and leve r Packagir n "Sand-t ; Packagir 1, TAB ar	ls ^{pg} o- ng nd			

	Commonly used packages and advanced packages, Materials in packages, Thermal	
	mismatch in packages, Current trends in packaging, Multichip modules (MCM)-	
	type, System-in- package (SIP), Packaging roadmaps, Hybrid circuits.	
	UNIT II: Electrical Design considerations in systems packaging: Electrical Issues -	
	I Resistive Parasitic, Electrical Issues - II; Capacitive and Inductive Parasitic,	
	Electrical Issues - III; Layout guidelines and the Reflection problem, Electrical	
	Issues – IV; Interconnection, CAD for Printed Wiring Boards: Benefits from CAD;	9
	Introduction to DFM, DFR & DFT, Components of a CAD package and its highlights,	
	Design Flow considerations; Beginning a circuit design with schematic work and	
	component layout, Demo and examples of layout and routing; Technology file	
	generation from CAD; DFM checklist and design rules; Design for Reliability.	
	UNIT III: Printed Wiring Board Technologies: Board-level packaging aspects,	
	Review of CAD output files for PCB fabrication, Photo plotting, and mask	
	generation, Process flow-chart; Vias; PWB substrates, Surface preparation,	
	Photoresist and application methods, UV exposure and developing, Printing	9
	technologies for PWBs, PWB etching, Resist stripping, Screen-printing technology,	9
	Through-hole manufacture process steps, Panel and pattern plating methods,	
	Solder mask for PWBs, Multilayer PWBs; Introduction to microvias, Microvia	
	technology, and Sequential build-up technology process flow for high-density	
	interconnects, Conventional Vs HDI technologies; Flexible circuits.	
	UNIT IV: Surface Mount Technology: SMD benefits; Design issues; Introduction to	
	soldering, Reflow, and Wave Soldering methods to attach SMDs, Solders: Wetting	
	of solders; Flux and its properties, Defects in wave soldering, Vapor phase	9
	soldering, BGA soldering, and de-soldering/ Repair, SMT failures, SMT failure	9
	library, Tin Whiskers, Tin-lead, and lead-free solders; Phase diagrams, Thermal	
	profiles for reflow soldering, Lead-free alloys, Lead-free solder considerations;	
	Green electronics; RoHS compliance, e-waste recycling issues.	
Course	Continuous Evaluation 25%	
Assessmen	Mid Semester 25%	
t	End Semester 50%	

Course C	ode: ECV	-		HM Course:	PC	Course:	(Y/N)	PE	Course:	(Y/N)			
514		Course: (Y	(Y/N) (Y/N) N Y										
Type of C	ourse		irse / I		1			N					
Course Ti		-	Theory Course/ Lab Course ALGORITHM FOR VLSI DESIGN										
Course Co													
Course Ol			e the u	inderstanding of t	he th	eoretica	l as wel	l as p	ractical c	oncepts of			
	,	-		orithms for CAD t				1		1			
Course O	utcomes	·						Cog	nitive Le	evels			
CO1	Understa	nd the VLSI sy	nthesi	s techniques.					Unders	tand			
									(Leve)	,			
CO2	Analyze	the VLSI algorit	thms f	or automation.					Analy				
			-						(Level				
CO3	Apply th	e algorithm for	floor	planning and conf	igura	ition.			App				
<u> </u>		. 1			1	·1 · 1 · ·			Level) Unders				
CO4	VLSI.	understanding	conce	ept of global and	aeta	ilea rou	ting in		(Leve				
<u> </u>		611							(Leve	1-11)			
Semester		6 th			r	Spring							
		Lecture	T	utorial	Pra	ctical	Credit	ts	Total	Teaching			
Contact H	ours	-			0		2	Hour					
Prerequis		3	0		0		3		36				
names Equivaler													
codes proposed and old co													
Text Bool	ζS												
1.	Tit	le	Algo	rithms for VLSI p	hvsic	al desigr	1 Autom	ation					
	Au	thor		eed Shervani	<u> </u>	0							
	Pu	blisher	Kluv	ver Academic Pub	lishe	r							
	Ed	ition	3 rd e	dition, 1999									
2.	Tit			rithm and Data S				sign					
		thor		stophn Meinel & '			obold						
		blisher		ver Academic Pub	lishe	r							
D (ition	2002	2									
Reference		10	E1	utionow Al		VICICA							
1.	Tit	thor		utionary Algorith Drechsheler	m for	VLSI CF	AD.						
		blisher		ver Academic Pub	licho	r							
		ition	-	dition 2010	iisiie	1							
Course		IT I:	2 e										
Contents			verifi	cation: Introduct	ion to) comhir	national	logic	synthesi	s, 9			
Someries				n, Hardware mode				<u> </u>	•	, ,			
	UN VL of	IT II: SI automation A partitioning alg	Algori [.] gorithi	thms Partitioning ms, Group migrat tioning algorithm	: Prol ion a	olem for	mulation	n, cla	ssificatio				

	UNIT III: Placement, floor planning & pin assignment: Problem formulation, simulation base placement algorithms, other placement algorithms, constraint-based floor planning, floor planning algorithms for mixed block & cell design. General & channel pin assignment.	9
	UNIT IV: Global Routing: Problem formulation, classification of global routing algorithms, Maze routing algorithm, line probe algorithm, Steiner Tree based algorithms, ILP based approaches Detailed routing: Problem formulation, classification of routing algorithms, single layer routing algorithms, two-layer channel routing algorithms, three-layer channel routing algorithms, and switchbox routing algorithms.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course Code		ECVP 515									
	<u> </u>	Programn									
Course Title	:	r i Ugi ainn									
Type of Course	:	Program	Program Core								
		Lecture	Tutorial	Practical	Credits	Total Lab Hours					
Contact Hours		0	0	4	2	32 (P)					
						· · · · ·					
Pre-requisite	:	Nil									
Programming lab rela	ated	to the Micro	oelectronics	/VLSI domai	in.						
				1							

Course Code	:	ECVP 516	ECVP 516								
		Seminar	/ Summer	Internship ·	·I						
Course Title	:										
Type of Course	:	Program	rogram Core								
		Lecture	Tutorial	Practical	Credits	Total Lab Hours					
Contact Hours		0	0	2	1	-					
Pre-requisite	:	Nil									
Seminar / Summer	Intern	ship related	d to Microel	ectronics/VI	.SI domain						

SEMESTER-VI

Course 617	Code: EC		Dpen Elec Course: (Y/		HM Course: (Y/N)	PC C	Course:	(Y/N)	PE	Course	: (Y/N)		
		Ν		,	N	Y			Ν				
Type of (Course	1	Theory Cour	se/L	ab Course								
Course T	litle	E	EMBEDDED AND REAL TIME OPERATING SYSTEMS										
Course C	Coordinat	or											
Course O)bjectives		To provide to systems and		indamental knov and ROM	vledg	e of em	bedded	and	real-time	e operating		
Course O)utcomes								Cog	nitive L	evels		
C01	Explain	n the ba	asics of an e	mbec	lded system and	its ap	proache	S.		Under (Leve			
CO2	Identify	y the v	e various methods of Hardware Implementation. Apply (Level-III)								oly		
CO3	Analyz	e the c	locking issu	es in	embedded syster	ns.				Anal (Leve	yze		
CO4	Compil	e the o	perating sy	stem	s concepts, types	and R	TOS.			Crea (Leve	ate		
Semeste	r	e	5 th				Spring	<u> </u>		(1070			
Contact Hours			<i>lecture</i>	Tu	itorial	Pra	ctical	Credits		Total Hours	Teaching		
Contact	liouis	3	}	0		2		4		48			
codes v names	isite cou vith cou	rse											
Equivale codes propose and old o	as j d cou	per											
Text Boo													
1.	Т	itle		Int	roduction to Emb	oedde	d Syster	ns					
	A	uthor			Shibu K. V								
	Р	ublish	er	Мс	Graw Hill								
	E	Edition		2013									
2.	Т	itle		En	bedded Systems								
		uthor		Ly									
		<u>ublish</u>	er		arson								
D - 6		Edition		20	13								
Referenc		ינ ג ן -		۸	Emplo d d = d C = C	P							
1.		<u>itle</u>			Embedded Softw	vare P	rimer						
		uthor Publish	or		vid E. Simon arson								
		dition	C1	20									
Course				20	13								
CourseUNIT I:ContentsIntroduction to Embedded Systems: Definition of Embedded Embedded Systems Vs General Computing Systems, History of En Systems, Classification, Major Application Areas, Purpose of En								d Syste	m,				
	S	Embedo System:	ded System s, Classifica	s Vs ation,	General Comput Major Applicat	tion I	Areas, I	Purpose	of	Embedd	ed 9		
	S S	Embedo System:	ded System s, Classifica s, Character	s Vs ation,	General Comput	tion I	Areas, I	Purpose	of	Embedd	ed 9		

	and Domain Specific Processors, ASICs, PLDs, Commercial Off- The-Shelf Components (COTS), Memory: ROM, RAM, Memory according to the type of Interface, Memory Shadowing, Memory selection for Embedded Systems, Sensors and Actuators, Communication Interface: Onboard and External Communication Interfaces	
	UNIT III: Embedded Firmware: Reset Circuit, Brown-out Protection Circuit, Oscillator Unit, Real Time Clock, Watchdog Timer, Embedded Firmware Design Approaches and Development Languages. ATMega and Resberi Pi.	9
	UNIT IV: RTOS Based Embedded System Design: Operating System Basics, Types of Operating Systems, Tasks, Process and Threads, Multiprocessing and Multitasking, Task Scheduling. Task Communication: Shared Memory, Message Passing, Remote Procedure Call and Sockets, Task Synchronization: Task Communication/ Synchronization Issues, Task Synchronization Techniques, Device Drivers, How to Choose an RTOS.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

(10	Code:	ECVB	Open E		HM	Course:	PC	Course	(Y/N)	ΡΕ Cou	ırse:	(Y/N)
618	518		Course:	(Y/N)	(Y/N)		V			N		
Type of Course			N N Y N									
Course Title			Theory Course/ Lab Course ANALOG VLSI DESIGN									
Course Coordinator			ANALUG VLƏI DEƏIGIN									
Course Objectives			To deve	lon ins	ight of	Analog M	05	device a	nd ampl	ifiers t	heir	frequency
dourse objectives			To develop insight of Analog MOS device and amplifiers, their free response and stability analysis									nequency
Course O	utcon	nes				-)				Cogr	nitive	e Levels
			ng the MC	ng the MOS Operation and small signal models. Understa								
CO1			-	_		-					(Lev	vel-II)
CO2	Ana	lyze single-stage amplifiers with different loads.									Ana	alyze
												rel-IV)
CO3	Тос	lesign sir	ngle and d	lifferent	ial CMOS	amplifier	'S					eate
60.4		. 11	.1 1	6.6	11 1 .	1.0					· ·	rel-VI)
CO4	Und	erstandi	ng the rol	e of feed	iback in a	amplifiers	5.					rstand
-								a -			Lev	vel-II)
Ser	meste	r	6 th					Spring				
			Lecture	e Tı	utorial		Pr	actical	Credits	To		Teaching
Conta	act Ho	urs	-				-				urs	
<u> </u>			3	0			2		4	48	48	
Prerequis		course										
codes v names	vith	course										
Equivaler	nt	course										
codes		course										
proposed course and		per										
proposed	as 1 cour	per se and										
proposed old cours	l cour	-										
	l cour e	-										
old cours	l cour e	-				g CMOS In	tegr	ated Circ	cuits			
old cours Text Boo	l cour e	Title	•	Behzad	Razavi		tegr	ated Circ	cuits			
old cours Text Boo	l cour e	Title Author Publisl	ner	Behzad McGrav			tegr	ated Circ	cuits			
old cours Text Bool 1.	l cour e	Title Author Publisl Editior	ner	Behzad McGrav 2000	Razavi v Hill Edu	ication		ated Circ	cuits			
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old cours Text Bool 1.	l cour e	Title Author Publisl Editior Title Author	ner	Behzad McGrav 2000 CMOS A Phillip	Razavi v Hill Edu analog Cin Allen and	ication	gn		cuits			
old cours Text Bool 1.	l cour e	Title Author Publisl Editior Title Author Publisl	- ner n - ner	Behzad McGraw 2000 CMOS A Phillip A OUP US	Razavi v Hill Edu analog Cin Allen and A	ication rcuit Desi l Douglas I	gn		cuits			
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old cours Text Bool 1. 2. Reference	l cour se ks	Title Author Publisl Edition Title Author Publisl Edition ks Title Author		Behzad McGrav 2000 CMOS A Phillip A OUP US 3 rd Edit Operati Yannis	Razavi v Hill Edu analog Cin Allen and A ion, 2011 on and M Tsividis	ication rcuit Desi l Douglas L Iodelling o	gn R. H	olberg				
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old cours Text Bool 1. 2. Reference	l cour se ks	Title Author Publisl Editior Title Author Publisl Editior ks Title Author Publisl		Behzad McGrav 2000 CMOS A Phillip A OUP US 3 rd Edit Operati Yannis Oxford	Razavi v Hill Edu Analog Cin Allen and A ion, 2011 on and M Tsividis Universit	ication rcuit Desi l Douglas l l lodelling o ty Press	gn R. H	olberg				
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old cours Text Bool 1. 2. 2. Reference 1. Course	l cour se ks e Boo	Title Author Publisl Editior Author Publisl Editior Ks Title Author Publisl Editior Ks Title Author Publisl Editior UNIT I Introde Capace Consid	ner ner ner ner ner ner ner ner	Behzad McGrav 2000 CMOS A Phillip A OUP US 3 rd Edit Operati Yannis Oxford 2 nd editi MOSFE del, MOS	Razavi v Hill Edu Analog Cin Allen and A ion, 2011 on and M Tsividis Universit on, 2003 FS, Simpl SFET bas I/V Cha	ication rcuit Desi Douglas Douglas Douglas I I I I I I I I I I I I I I I I I I I	gn R. Ho of th Γ cir ce St cs,	olberg e MOS T rcuits, Th ructure a Finite	ransistor reshold v and Opera Output H	ation, G Resistar	lener nce	al in 9
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	Amplifiers: Basic concepts, Single Stage Amplifiers: Basic Concepts, Common Source Stage: resistive load, diode connected load, current source load, triode load, source degeneration. Source Follower, Common Gate Stage, Cascode Stage. Folded cascode. Differential Amplifiers: Single Ended and Differential Operation, Basic Differential Pair, Common Mode Response, Differential Pair with MOS loads, Gilbert Cell.	
	UNIT III: Basic current mirrors, Cascode current mirrors, Active current mirrors with large and small signal analysis, Feedback topologies (voltage-voltage, current-voltage, voltage-current, current-voltage), loading effect analysis, Negative feedback, Stability of negative feedback systems, Stability and frequency compensation. Frequency Response of Amplifiers: Amplifier transfer function, General Considerations, Miller Effect, Common Source Stage, Source Followers, Common Gate Stage.	9
	UNIT IV: Design of the CMOS operational amplifiers: One-stage opamps and two-stage opamps, Gain boosting techniques, folded cascode, telescopic amplifier, common mode feedback (CMFB) amplifier, Input Range limitations, Slew Rate, Power Supply Rejection, VCO Circuit design, OTA design.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

		ECVP 619				
Course Code	:					
		Minor Pr	oject			
Course Title	:					
Type of Course	:	Program	Core			
		Lecture	Tutorial	Practical	Credits	Total Lab Hours
		2000000			0100100	
Contact Hours		0	0	4	2	
Contact Hours Pre-requisite	:	0 Nil	0	4	2	
	:	-	0	4	2	

Course Code	:	ECVP 620								
Course Title	:	Project B	Project Based Learning							
Type of Course	:	Program	Program Core							
		Lecture	Tutorial	Practical	Credits	Total Hours				
Contact Hours		0	0	2	1					
Pre-requisite	:	Nil								
Project-based Learning	g relat	ed to Micro	pelectronics	/VLSI/ECE.						

SEMESTER-VII

	Code: ECVL	-		HM Course:	PC C	Course:	(Y/N)	PE C	Course	: (Y/N)	
721		Course: (Y/	N)	(Y/N)	17			NT			
T		N TTI									
Type of Course Course Title		Theory Course									
Course Coordinator		LOW-POWER VLSI DESIGN									
Course Ol		To provide t									
course of	bjectives	To provide the fundamental knowledge of VLSI systems using CMOS technology for low power and high-performance applications									
Course O	utcomes	t				•		Co	ognitiv	e Levels	
C01	To underst	and the impor		Understand							
COI									(Level-II)		
CO2	To study th	ie various sour	rce of	power consump	tion ir	n CMOS	circuits.		Unde	erstand	
										vel-II)	
CO3		he techniques	s to r	reduce the powe	r diss	sipation	in CMOS	S		pply	
	circuits.									/el-III)	
CO4	To analyse	the circuit wi	th pro	obabilistic power	techr	1ique.				alyze	
		1				1			(Lev	vel-IV)	
Sem	nester	6 th				Spring	-	·			
		Lecture	Tu	itorial	Pra	ctical	Credits		Total	Teaching	
Conta	ct Hours								Hours		
	•-	3	0		0		3		36		
	site course										
	ith course										
names Equivaler	nt course										
codes	as per										
proposed	-										
and old co											
Text Bool		.1									
1.	Title		CMO	S Digital Integrat	ed Cir	cuits					
	Auth	or									
	Publ	isher									
	Editi	on									
2.	Title		Principles of CMOS VLSI Design								
	Auth										
	Publ										
	Editi	on	n 2nd Edition								
Reference					<u> </u>						
1.	Title			Power VLSI CMO			ign				
	Auth										
	Publ										
Course	Editi		1995								
Course Contents	UNI		ivatio	n for low nor	or 171	SI doo	ian Cour	<u> </u>	of norm	or	
contents				on for low powe tegrated circuits			•		-		
				CMOS, Effect of su		0 0	-			ο Te	
	-	-		Scaling, Techno		-			-	- u	
	-			•							
		-	-	-	-						
		•			•			1			
	Low-	Power Design	n Thro	ver design: techr ough Voltage Scal oction of Switched	ling, I	Estimati	ion and O				

	UNIT II: SPICE circuit simulation, gate level logic simulation, capacitive power estimation, static state power, gate level capacitance estimation, architecture level analysis. Probabilistic power analysis: Random logic signals, probability & frequency, probabilistic power analysis techniques, signal entropy.	9
	UNIT III: Low Power Circuit's: Transistor and gate sizing, network restructuring and Reorganization. Logic level: Gate reorganization, signal gating, logic encoding, state machine encoding, pre-computation logic. Energy Recovery CMOS: energy dissipation in transistor channel using RC model, adiabatic dynamic logic circuit.	9
	UNIT IV: Leakage Power minimization Approaches: Variable-threshold-voltage CMOS (VTCMOS) approach multi-threshold-voltage CMOS (MTCMOS) approach Power gating Transistor stacking Dual-Vt assignment approach (DTCMOS)	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course 722	Code:	ECVL	Open Elect Course: (Y/		HM Course: (Y/N)	PC Cours	se: (Y/N)	PE	Course:	(Y/N)
			N		N	Y		N		
Type of	f Course		Theory Cour	se/I						
Course					ION AND TESTIN	IG				
Course	Coordina	ator								
Course	Objectiv	es	To provide the for VLSI circu		ndamental knowl	edge of fai	alt detection	n and	l correcti	ive analysis
Course	Outcome	es	I						Cogniti	ve Levels
C01	Underst	and th	e requiremen	t of f	ault modelling in	VLSI circu	its.		Und	erstand evel-II)
CO2	CO2 Analyze test vectors to t				uit efficiently cov	ering max	imum faults	s.	Ar	nalyze vel-IV)
CO3 Apply the concept of M				y tes	ting techniques				A	vel-III)
CO4	Evaluate	- Built	-in-Self Test a	nd ite	application in m	odern digi	tal design			aluate
	Lvuluut	Dune	in ben rest a	ind it.	, application in in	ouern aigi	tui uesigii			evel-V)
Semest	er		7 th			Aut	tumn			
Contact			Lecture	Τι	ıtorial	Practica		S	Total Hours	Teaching
			3	0		2	4		48	
names Equival codes propos and old	as ed co	ourse per ourse								
Text Bo	oks									
1.	-	Title Autho Publis Editio	or M. sher Kl	L. Bi uwer	als of Electronic ushnell and V. D. A Academic Publis ion2002	Agrawal				
2.		Title			Fault Testing for V	LSI Circui	ts			
<i>–</i> .	-	Autho			ic and K-T Cheng	Lor Gircul				
	-	Publi			· Academic Publis	hers				
		Editio			ion 2003					
Referen	ice Book	S	• • • •							
1.		Title			g of Digital System	IS				
		Autho			a and S. Gupta					
	Ļ	Publi			dge University Pr	ess				
		Editio		d edit	tion 2003					
Course Conten	ts	collap	cal faults and osing, Fault si	mula	r modelling. Fau tion: parallel, de	-				u
L		CITUC	al path tracing	.						

	UNIT II: Test generation for combinational circuits: Boolean difference, D-algorithm, Podem, random etc. Exhaustive, random and weighted test pattern generation; aliasing and its effect on fault coverage. PLA testing: cross-point fault model, test generation, easily testable designs. Memory testing: permanent, intermittent and pattern-sensitive faults; test generation.	9
	UNIT III: Delay faults and hazards; test pattern generation techniques, ATPG and its different types Test pattern generation for sequential circuits: ad-hoc and structures techniques scan path and LSSD, boundary scan	9
	UNIT IV: Built-in self-test techniques: LBIST and MBIST. Verification: logic level (combinational and sequential circuits), RTL-level (data path and control path). Verification of embedded systems. Use of formal techniques: decision diagrams, logic-based approaches. ASIC/IP Verification, direct and random testing, Error detection and correction codes.	9
Course	Continuous Evaluation 25%	
Assessment	Mid Semester 25% End Semester 50%	
Tentative list of Experiments		urse.

Course Code: HMVL 703		1VL	Open Course	Elective : (Y/N)	HM Course: (Y/N)	DC (Course:	(Y/N)	DE Cour	rse: (Y/N)
		Ī	Ν		Y	Ν			N	
Type of Co	ourse		Theory	Course/ l	Lab Course			·		
Course Ti	itle		ENGINE	EERING E	CONOMICS AND	ACCO	UNTIN	G		
Course Co										
Course Ol	bjectives	5	To gain the fundamental knowledge of management principles, organizat their structure						ganization and	
Course Ou	utcomes								Cogn	itive Levels
C01	Unders	stand	the obje	ective and	principles of man	agem	ent			nderstand (Level-II)
CO2	Apply process		manage	ment pla	anning technique	e and	l decisi	on-makin	•	Apply (Level-II)
CO3	Analyze the architecture of organization and departments			Analyze Level-IV)						
CO4	Predict the nature of directions and coordination			Create Level-VI)						
Semester	•		7 th				Autun	nn		
Contact H	lours		Lecture	e T	utorial	Pra	ctical	Credits	Tota Hou	
		F	3	0		0		3	36	
Equivaler	nt cou	rse								
codes proposed and old co	as j l cou ourse	per								
codes proposed and old co Text Bool	as j l cou ourse ks	per rse								
codes proposed and old co	as j l cou ourse ks	per rse			ment-Tasks, Resp	onsibi	ilities &	Practices		
codes proposed and old co Text Bool	as j course ks T A	per rse Title		Drucker	, F. Peter	onsib	ilities &	Practices		
codes proposed and old co Text Bool	as j course ks A P	per rse Title Autho Publis	sher	Drucker TRUMA	, F. Peter N TALLEY BOOKS	onsibi	ilities &	Practices		
codes proposed and old co <u>Text Book</u> 1.	as j course ks T A P E	per rse litle Autho Publis Editio	sher	Drucker TRUMA 1 st Editio	, F. Peter N TALLEY BOOKS on		ilities &	Practices		
codes proposed and old co Text Bool	as j course ks T A P E T	per rse litle Autho Publis Editio Litle	sher n	Drucker TRUMA 1 st Editio Organiza	, F. Peter N TALLEY BOOKS on ational Behaviour		ilities &	Practices		
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codes proposed and old co <u>Text Book</u> 1.	as j course ks 7 A P E T A P	per rse Title Autho Publis Editio Title Autho	sher n or sher	Drucker TRUMAI 1 st Editio Organiza C.H Dub	, F. Peter N TALLEY BOOKS on ational Behaviour ey		ilities &	Practices		
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codes proposed and old co <u>Text Bool</u> 1. 2.	as j course ks A P E T A P E E E E Books	per rse litle Autho Publis Editio Litle Autho Publis	sher n or sher	Drucker TRUMAI 1 st Editio Organiza C.H Dub Prentice	, F. Peter N TALLEY BOOKS on ational Behaviour ey e Hall in India (PH		ilities &	Practices		
codes proposed and old co <u>Text Book</u> 1. 2. <u>Reference</u>	as j course ks KS P E E E Books T A	per rse Title Autho Publis Editio Title Autho Title Autho	sher n or sher n n	Drucker TRUMA 1 st Editio Organiza C.H Dub Prentice 2015 C. B. Gup Human	, F. Peter N TALLEY BOOKS on ational Behaviour ey Hall in India (PH bta Resource Manager	[]	ilities &	Practices		
codes proposed and old co <u>Text Book</u> 1. 2. <u>Reference</u>	as j course ks Ks T A P E E T A P E E Books T A P	per rse rse <u>Citle</u> Autho Citle Autho Citle Citle Citle Citle Autho Publis	sher n or sher n or sher	Drucker TRUMA 1 st Editio Organiza C.H Dub Prentice 2015 C. B. Gup Human Sultan C	, F. Peter N TALLEY BOOKS on ational Behaviour ey Hall in India (PH)	[]	ilities &	Practices		
codes proposed and old co <u>Text Bool</u> 1. 2. <u>Reference</u> 1.	as j course ks Ks P E P E F E Books T A P E E E E E E E E E E E E E	per rse Title Autho Publis Editio Citle Autho Publis Editio	sher n or sher n or sher n	Drucker TRUMA 1 st Editio Organiza C.H Dub Prentice 2015 C. B. Gup Human	, F. Peter N TALLEY BOOKS on ational Behaviour ey Hall in India (PH bta Resource Manager	[]	ilities &	Practices		
codes proposed and old co <u>Text Bool</u> 1. 2. <u>Reference</u> 1. Course	as j course ks Ks A P E E E E Books T A P E E E E U	per rse Title Autho Publis Editio Citle Autho Publis Editio Publis Editio JNIT	sher n or sher n or sher n I:	Drucker TRUMA 1 st Editio Organiza C.H Dub Prentice 2015 C. B. Gup Human Sultan C 2006	, F. Peter N TALLEY BOOKS on ational Behaviour ey Hall in India (PH Hall in India (PH Dta Resource Manager hand & Sons	I) ment			Ohiostiin	
codes proposed and old co <u>Text Bool</u> 1. 2. <u>Reference</u> 1.	as j ourse ks Ks T A P E E E Books T A P E E U V W S P P E U V V V P P E P E P E P E P P E P E P P E P	per rse rse Citle Autho Publis Editio Citle Autho Publis Editio Citle Autho Publis Editio JNIT Manag Manag Skills, Proces Princi	sher n or sher n or sher n l: gement gement, Manage ss and ples- Ge	Drucker TRUMAI 1st Editio Organiza C.H Dub Prentice 2015 C. B. Gup Human Sultan C 2006 Concept a Significar ment and Function eneral an	, F. Peter N TALLEY BOOKS on ational Behaviour ey Hall in India (PH bta Resource Manager	ature nt, Ma Levels reas of ageme	of Man inageria s of Man of Man ent, Evo	agement, l Roles ar nagement, agement,	nd Manag Manage Manage	gerial ment 9 ment

	Need for Planning, Principles of Planning, Types of Planning, Advantages and Disadvantages of Planning; Decision making concept, Characteristics of Decision Making, Types of Decisions, Decision Making Process, Characteristics of Effective Decisions, Rationality in Decision Making. UNIT III: Organizing definition. Organisation as a Process, Organisation Structure, Principles of Organisation, Importance of Organisation, Types of Organisations. Departmentation- Meaning, Need and Significance of Departments, Process involved in Departmentation, Methods or Basis of Departmentation; Span of Management; Centralization and Decentralisation; Delegation.	9
	UNIT IV: Directing concept, Nature and Characteristics of Directing, Principles of Directing; Motivation- Concept and Theories of motivation; Concept of Leadership- Theories and Styles; Communication Process, Channels and Barriers, Effective Communication. Coordination- Concept and Nature of Coordination, Need for coordinating; Importance, Principles and Techniques of Coordination; Process of Coordination. Controlling- Definitions, Characteristics of Controlling, Steps in Control Process, Types of Controlling, Control Techniques.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course Code	:	ECVP 723				
		Seminar	/ Summer	Internship -	II	
Course Title	:		-	-		
Type of Course	:	Program	Core			
		Lecture	Tutorial	Practical	Credits	Total Lab Hours
Contact Hours		0	0	2	1	-
Pre-requisite	:	Nil				
Seminar / Summer I	nternshir	o related wit	th the Micro	electronics/	VLSI /ECE.	

SEMESTER-VIII

Course Code	:	ECVP 824	4			
Course Title	:	MAJOR P	ROJECT / I	NTERNSHIP		
Type of Course	:	Project	1		1	
		Lecture	Tutorial	Practical	Credits	Total Lab Hours
Contact Hours		-	-	-	16	-
Pre-requisite	:	Nil				
Major Project / Int	ernshij	p related to	Microelectr	onics/VLSI/	ECE.	

Course Title Independent study and Seminar • •	
Course Title :	
Type of Course:Seminar / Internship / Independent s	tudy
Lecture Tutorial Practical Cred	ts Total Hours
Contact Hours 4	_
Pre-requisite : Nil	
Seminar / Internship / Independent study related with the Microele	ctronics/VLSI /ECE.

Program Electives and Open Electives for B.Tech VLSI Design and Technology List of Electives Bouquet 1: Elective-I

S. No.	Course Code	Course Title	L	Т	Р	Credits
1.	PEVL 501	Semiconductor Device Modelling	3	0	0	3
2.	PEVL 502	Introduction to Machine Learning	3	0	0	3
3.	PEVL 503	Internet of Things	3	0	0	3
4.	PEVL 504	Wireless Communication	3	0	0	3
5.	PEVL 505	Digital Signal Processor and Architecture	3	0	0	3
6.	PEVL 506	Antenna Theory and Design	3	0	0	3

Bouquet 2: Elective-II and Elective III

S. No.	Course Code	Course Title	L	Т	Р	Credits
1.	PEVL 607	Introduction to MEMS	3	0	0	3
2.	PEVL 608	Nano Electronics	3	0	0	3
3.	PEVL 609	Cyber Security	3	0	0	3
4.	PEVL 610	ASIC and FPGA Design	3	0	0	3
5.	PEVL 611	Radar Engineering	3	0	0	3
6.	PEVL 612	Advance Neural Network	3	0	0	3
7.	PEVL 613	VLSI Interconnects	3	0	0	3
8.	PEVL 614	AI and Machine Learning for IC	3	0	0	3
9.	PEVL 615	VLSI for Communications	3	0	0	3
10.	PEVL616	Memory Devices and circuits	3	0	0	3

Bouquet 3: Elective-IV and Elective V

S. No.	Course Code	Course Title	L	Т	Р	Credits
1.	PEVL 717	CAD for VLSI	3	0	0	3
2.	PEVL 718	Thin Films Characterization	3	0	0	3
3.	PEVL 719	Mixed Signal IC design	3	0	0	3
4.	PEVL 720	Bio-Medical Electronics	3	0	0	3
5.	PEVL 721	RF Microelectronics	3	0	0	3
6.	PEVL 722	High-Speed Interfacing Circuits	3	0	0	3
7.	PEVL 723	Digital Image Processing	3	0	0	3
8.	PEVL 724	Flexible Electronics	3	0	0	3
9.	PEVL 725	Quantum Computing	3	0	0	3
10.	PEVL 726	Solar Cell Technology	3	0	0	3
11.	PEVL 727	Ad-hoc Sensor Networks	3	0	0	3
12.	PEVL 728	Full Custom Design	3	0	0	3
13.	PEVL 729	Advance Semiconductor Manufacturing	3	0	0	3
14.	PEVL 730	Data Converters	3	0	0	3
15.	PEVL 731	Reconfigurable Computing System and Applications	3	0	0	3

Open Elective-I

S. No.	Course Code	Course Title	L	Т	Р	Credits
1.	0EVL 601	Growth, Fabrication and Manufacturing	3	0	0	3
		of Electronic Devices				
2.	0EVL 602	Electronic Materials	3	0	0	3
3.	0EVL 603	Basics of IC Design	3	0	0	3

Open Elective-II

S. No.	Course Code	Course Title	L	Т	Р	Credits
1.	0EVL 704	Data Communication and Networking	3	0	0	3
2.	0EVL 705	Micro-Electronics and VLSI Technology	3	0	0	3
3.	OEVL 706	Embedded and real time operating systems	3	0	0	3

Course 501	Code: PEVL	Open Elect Course: (Y/		ourse: PC Courses	: (Y/N)	PE Course:	(Y/N)
		N	N	Ν	1	Y	
Type of			se/ Lab Course				
Course 1		SEMICONDU	ICTOR DEVICE	MODELLING			
Course (Coordinator						
Course (Objectives	To enhance characteristi		ge of semiconduc	tor device:	s, various	and their
Course (Outcomes					Cognitiv	ve Levels
CO1	deriving a r	model with		s, and techniques a erties, for a gen ry.			erstand vel-II)
CO2	Apply suitab	le approxima		nniques to derive	the mode		pply vel-III)
CO3	Examine clue	es to a qualita	ative understar	nding of the physic ng into equations.	cs of a new	7 Eva	aluate vel-V)
CO4				ising MATLAB, and	SPICE tools		eate vel-VI)
Semeste	er	5 th		Autu	mn		
Contact	Hours	Lecture	Tutorial	Practical	Credits	Total Hours	Teaching
		3	0	0	3	36	
-	isite course with course						
Equivale codes propose and old Text Boo	as per d course course						
1.	Title		l State Electron				
	Author	B. G.	Streetman and	S. Banerjee			
	Publish		Private Limited				
	Edition						
2.	Title			ice Modelling and C	Circuit Simu	lation	
	Author			dal, and M. Shur			
	Publish	,	Wiley and Son	S			
Deferre	Edition	1998	5				
	ce Books	I a k	duction to Com	viconductor Mataria	la and dar-	<u> </u>	
1.	Title			niconductor Materia	us and devi	Les	
	Author Publish		Гуаgi Wiley & Sons				
	Edition						
Course	UNIT I:		,				
Content			uuilibrium and (Carrier Transport, S	emiconduct	tor Materia	s
Soutont	Carrier Recomb Ballistic Physics Depleti	Concentration pination Proce c Transport, H s of Junction D	on, Carrier D ess, Continuity D igh Field Effect Devices: Therma sion Capacitanc	prift, Carrier Diffi Equation, Thermior s. al Equilibrium Con- es, Current-Voltage	usion, Gen nic Emissior dition, Depl e characteri	eration ar n, Tunnellin etion regio stics, Charg	nd 9 n, 9 ge 1

	Contacts, forward and reverse-biased junctions, reverse bias breakdown, transient, and a-c conditions.	
	UNIT II:	
	Physics of Bipolar devices: Transistor action, Static Characteristics, minority carrier distribution and terminal currents, generalized biasing, secondary	9
	effects, Frequency Response and Switching, Semiconductor Heterojunctions.	
	UNIT III: Field-Effect Transistors: JFET- current-voltage characteristics, effects in real devices, high-frequency and high-speed issues, Metal Insulator Semiconductor FET.	
	MOSFET- basic operation and fabrication, ideal MOS capacitor, Energy band diagram in equilibrium and under bias, Flat band voltage, Potential Balance and charge balance, Effect of gate body voltage on surface condition, Accumulation and depletion, Inversion, CV Characteristics, Frequency response, threshold voltages, output and transfer characteristics of MOSFET, short channel and Narrow width effects, MOSFET scaling.	9
	UNIT IV: Optoelectronics Devices: Light emitting diodes, Lasers, Photoconductors, Junction Photodiodes, Avalanche Photodiodes, Solar Cells, SPICE Models for Semiconductor Devices: MOSFET Level 1, Level 2 and level 3 model, Model parameters; SPICE models of p-n diode and BJT.	9
Course	Continuous Evaluation 25%	
Assessment	Mid Semester 25%	
	End Semester 50%	

Course 502	Code: P	EVL	-	Electiv e: (Y/N)	re HM Co (Y/N)	ourse:	PC (Course:	(Y/N)	PE Co	ourse:	(Y/N)
			N		N		N			Y		
Type of	Course		Theory	v Course	/ Lab Course	<u>,</u>						
Course 7					GE PROCESS							
Course	Coordina	tor										
Course	Objective	S	•		owledge of di for digital ar			forms, s	egmenta	tion an	d com	pression of
Course	Outcome	S	0	0	0 1	•				Co	gnitiv	ve Levels
CO1	Analyze	imag	es in the	e freque	ncy domain ι	ising va	rious	transfo	rms.			alyze vel-IV)
CO2	Evaluate	e the t	echniqu	ies for ir	nage enhanc	ement a	and in	nage res	toration.		Eva	aluate vel-V)
CO3	Categori	ize va	rious co	mpressi	on techniqu	es.					<u>`</u>	alyze
	0			1	1							vel-IV)
CO4	Interpre	et I	mage	compre	ession sta	ndards,	se	gmenta	tion a	nd	Eva	aluate
	represei	ntatio	n techni	iques.							(Le	vel-V)
Semeste	er		5 th					Autun	nn			
Contact	Hours		Lectur	e	Tutorial		Pra	ctical	Credit		otal ours	Teaching
			3		0		0		3	30	5	
codes names	with cou	ırse										
Equival codes	as as	ırse per										
propose		ırse										
and old												
Text Bo												
1.		Title			Image Proce		1					
		Autho			onzalez and		ods					
		Publis Editio			n Education edition, 2009							
2.		Title	/11		mental of Dig		ισρ Ρι	ncessin	g			
		Autho	or	Anil K	,		-9-11	5000511	0			
		Publis		Prenti								
		Editio		1989								
Referen	ce Books											
1.		Title			sential guide	to imag	ge pro	ocessing				
		Autho		A. C. B								
		Publis			nic Press	0						
Correct		Editio		Second	l edition 200	19						
Course Content		UNIT		to digita	l imaga pro		What	t is ima	TA Proces	cing D	lifforo	nt
Content				•	ll image proo Visual perc				-			
					ng, colour ir	-				-		
		-		-	rocessing, I			•				
	;	and F proce	Frequen ssing, S	cy dom Spatial	ain: Image i filter: smoo	negative othing	es, Lo and	og trans Sharpei	formatio	ons, His screte	stogra Fouri	m er
		transf doma	-	operties	of 2-D DFT,	Image s	moot	hing an	d Sharpe	ning in	Fouri	er

	UNIT II: Image transforms: Two-dimensional orthogonal and Unitary transforms, Optimum transform, Properties of Unitary transforms, 2D DFT, Cosine transforms, Hadamard transforms, KL transforms, Comparison of image transforms, Edge detection: Gradient and Laplacian based edge detection, Diffusion based edge detection: Isotropic and anisotropic diffusion.	9
	UNIT III: Wavelet transform for Image Processing: Multi resolution expansion, Wavelet functions, Wavelet Series expansion, Continuous and Discrete Wavelet transforms, Wavelet transforms for two dimensional signals (images), Applications of wavelet transforms for edge extraction, noise suppression.	9
	UNIT IV: Image segmentation: Thresholding, region-based Morphological Watersheds, Bayesian-base image segmentation. Image restoration and reconstruction: Models of image degradation, noise models, Spatial and Frequency domain- based approaches for image restoration, Inverse filtering, Wiener Filtering, Bayesian denoising. Image Compression: Spatial and Temporal redundancy, Basic image compression models, compression standards, basic compression methods: Huffman coding, Run-length coding, Block transform coding, Predictive coding. Colour Image Processing: Colour Fundamentals, Colour Models, Colour transformation, smoothing, sharpening and edge detection in colour images.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course 503	Code: I	PEVL	-	Elective e: (Y/N)	HM Course: (Y/N)	PC (Course:	(Y/N) P	E Course	: (Y/N)
			N		N	N		Y		
Type of (Course		Theory	v Course/	Lab Course					
Course T				NET OF T						
Course C		ator								
Course C	bjectiv	es	-	rove the k s applicati	nowledge of use o ons	of Inte	rnet of T	hings relate	ed with th	e electronic
Course C)utcome	es							Cognit	ive Levels
C01	will b		to choos		rping boards and opriate board/cor		-	-		lerstand evel-II)
CO2 Analyze the			1 0	0	off-the-shelf boar riate libraries for		0 1			nalyze evel-IV)
CO3		-			tion standards an echnology for des					Apply evel-III)
CO4	Evalu	ate th			s Protocols, routi				Ev	valuate evel-V)
Semeste	r		5 th Autumn							
Contact	Hours		Lectur	e T	utorial	Pra	ractical Credits		Total Hours	Teaching
			3	0		0		3	36	
Prerequ	isite co	urse								
codes v	vith co	urse								
names										
Equivale		urse								
codes	as	per								
propose and old o		urse								
Text Boo										
1.		Title		Internet	of Things					
1.	F	Autho	nr	Dr. Jeeva						
	F	Publis								
	F	Editic								
2.		Title			tion to Security of	Cybe	r-Physic	al Systems		
	F	Autho	or		Jose & Vijo Mathe		J = ··	<u> </u>		
	F	Publi			Book Publishing C		ny			
	F	Editio	n	2022						
Reference	ce Book									
1.		Title		The Inte	rnet of Things: En	abling	g Techno	logies, Plat	forms, an	d Use Cases
	F	Autho	or		Raj and Anupama					
	Γ	Publis	sher	CRC Pres	SS					
		Editic	n	2017						
Course		UNIT	I:							
Contents	5	An in	troducti	on to IoT		ation	and mot	ivation of I	oT systen	15
					systems: Introduo					
		Hardy	ware co	mponent	systems: Introduc s of IoT system ntrollers, SoCs, co	s: A	quick	overview o	of differe	ent 9

CourseContinuous Evaluation 25%AssessmentMid Semester 25%End Semester 50%	
Smart Cities and Smart Homes, Connected Vehicles, Smart Grid, Industrial IoT, Industrial IoT (contd), Case Study: Agriculture, Healthcare and Activity Monitoring.	9
wireless sensor networks to meet QoS requirements. Introduction to Python programming, Introduction to Raspberry Pi, Implementation of IoT with Raspberry Pi. Implementation of IoT with Raspberry Pi (contd), Introduction to SDN, SDN for IoT.SDN for IoT (contd), Data Handling and Analytics.	9
and sensing modulesof off-the-shelf prototyping boards, e.g., Arduino UNO, <u>MSP430 Launch Pad; Node MCU, STM32.</u> UNIT II: The software component of IoT systems: Introduction to IDEs for off-the-shelf boards, e.g., Arduino IDE, Waspmote IDE, Code composed studio; Contiki-OS and RIOT OS; 6LowPAN network stack; Sensor interfacing; GPIO programming. Communication paradigm of IoT systems: Different wireless standards, e.g., IEEE802.15.4, ZigBee, BLE, IEEE802.11; link layer technologies, Medium Access Control; Routing; Application layer protocols; Network topologies.	9

Course C 504	ode: PEVL	Open Electi Course: (Y/N		PC Course:	(Y/N) P	E Course:	(Y/N)			
501		N	N	N	Y	7				
Type of Co	ourse	Theory Course/ Lab Course								
Course Tit			OMMUNICATION							
Course Co	ordinator									
Course Ob	ojectives		he students about t	he technolog	y and advar	ncements	in modern			
		wireless com	munication.							
Course Ou	1			<u> </u>			ve Levels			
CO1	Discuss the	cellular systen	n design and technica	al challenges.			erstand evel-II)			
CO2	Analyze the channel mo	•	propagation, fading, c	liversity conc	epts and the		nalyze vel-IV)			
CO3		e design para d MIMO system	imeters, link design is.	n, smart ante	enna, beam		nalyze vel-IV)			
CO4	Analyze M OFDM Cond	ultiuser Syster cepts. summari	ns, CDMA, WCDMA ze the principles and	1	0		nalyze vel-IV)			
a	systems and	d standards								
Semester		5 th	1	Autur	1					
Contact H	ours	Lecture	Tutorial	Practical	Credits	Total Hours	Teaching			
		3	0	0	3	36				
-	tt course									
codes proposed	as per									
and old co	ourse									
Text Book		· · · · · · · · · · · · · · · · · · ·								
1.	Title		Wireless Communic	ations						
	Autho		A.F.Molisch							
	Publi		Wiley							
	Editio	on	2005							
2.	Title		Wireless Communications							
	Autho		A.Goldsmith							
	Publi		Cambridge Universi	ty Press						
Doferre	Editio	on	2005							
Reference			Winalaga Community	ation"c						
1.	Title Autho	0.r	Wireless Communic P.Muthu Chidambar							
	Publi		PHI							
	Editic		2008							
Course	UNIT				_	-				
Contents			eless Communication			-	u u			
	-	• •	ent in cellular system			e reductio	n.			
			ept and applications.	Technical Cha	allenges.					
	UNIT Mobil		agation, Deflection	Diffus	Endi	M	h O			
	Propa		agation: Reflectior Innel modeling, D		-	Multipat Combinin				

	UNIT III: Design parameters at the base station, Practical link budget design using path loss models. Smart antenna systems, Beamforming. MIMO Systems. RAKE receiver.	9
	UNIT IV: Multiuser Systems: CDMA- Principle, Network design, Link capacity, Power control, WCDMA-Network planning, MC-CDMA, OFDM, Cellular mobile communication beyond 3G. GSM, IS-95, GPRS, UMTS, WLAN, WPAN, WMAN, Ultra-Wideband communications, 4G and beyond 4G.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course C 505	ode: PEVL	Open El Course: (HM Course: (Y/N)	PC C	Course:	(Y/N)	PE Course:	(Y/N)
		N		N	N			Y	
Tumo of C		Theory		ah Cauraa					
Type of Co Course Ti				Lab Course PROCESSOR AN		СПІТЕС	TIDE		
	ordinator	DIGITAL	SIGNAL	I FRUCESSUR AN	DAK		IUKE		
Course Ob		To educat	e the st	udents about the	archi	tecture	and prog	rammable di	oital signal
	Jeenves	processin		adents about the	arcin			Cognitive Le	5 5
Course Ou	•							0	
CO1	Understan	d Architectu	ires for	programmable D	SP dev	vices		Unders (Leve	
CO2	Analyze th	e Execution,	, contro	l and pipelining o	f DSP	devices		Analy (Level	
CO3	Examine P	rogrammab	le digita	al signal processo	rs			App	
								(Level	-III)
CO4	Apply the	basic DSP al	gorithm	IS				Арр	-
		1				[(Level	-III)
Semester		5 th				Autun	nn		
Contact H	ours	Lecture	Τι	ıtorial	Prac	ctical	Credit	s Total Hours	Teaching
		3	0		0		3	36	
	ite course ith course								
Equivalen	t course								
codes	as per								
proposed									
and old co									
Text Book 1.	ts Title		Digita	l Signal Proce	acore	Are	hitecture	, Programn	ning and
1.	TILLE		-	cations	essors	, AIC	meeture	, Flograiiii	ning and
	Auth	lor		ikataamani and M	. Bhas	skar			
		isher	TMH						
	Edit	ion	2004						
2.	Title			l Signal Processin	g-Ap	ractical	approac	h	
	Auth			or & Jervis					
		isher		on Education					
Reference	Edit	ion	2005						
			m) (25			m) (000	000	1.1.1	
1.	Title		TMS3	20C50, TMS320C	54XX,	TMS32	UC6713 (tatabooks	
	Auth								
		isher							
Course	Edit								
Contents			S FOR	PROGRAMMABLE		DEVIC	ES: Basi	r Architectur	al
Someries				tional Building Bl					
				ilities, Address Ge					
			-	ed Issues, Feature				•	
	UNI	Г II:							9
	EXE	CUTION CO	NTROL	AND PIPELININ	IG: H	ardwar	e loopin	ig, Interrupts	5,

	Stacks, Relative Branch support, Pipelining and Performance, Pipeline Depth, Interlocking, Branching effects, Interrupt effects, and Pipeline Programming models.	
	UNIT III: PROGRAMMABLE DIGITAL SIGNAL PROCESSORS: Commercial Digital signal- processing Devices, Data Addressing modes of TMS320C54XX DSPs, Data Addressing modes of TMS320C54XX Processors, Memory space of TMS320C54XX Processors, Program Control, TMS320C54XX instructions and Programming, On-Chip Peripherals, Interrupts of TMS320C54XX processors, Pipeline Operation of TMS320C54XX Processors.	9
	UNIT IV: IMPLEMENTATIONS OF BASIC DSP ALGORITHMS: The Q-notation, FIR Filters, IIR Filters, Interpolation Filters, Decimation Filters, PID Controller, Adaptive Filters, 2-D Signal Processing, FFT Algorithm for DFT Computation, A Butterfly Computation, Overflow and scaling, Bit-Reversed index generation, An 8-Point FFT implementation on the TMS320C54XX, Computation of the signal spectrum.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course C 506	ode: PEVL	Open E Course: (lective	HM Course: (Y/N)	PC (Course:	(Y/N)	PE Cours	se: (Y/N)
500		N	1/11	N	N			Y	
Type of Co	ourse	Theory Co	ourse/L					-	
Course TitleANTENNA THEORY AND DE									
	ordinator								
Course Ob									
Course Ou								Cognitiv	e Levels
CO1 Understand the Antenna theory, Radiation Pattern and wave								Unde	erstand vel-II)
CO2	Analyze the Antenna dipoles, loop pattern and Antenna array. Analyze (Level-IV) (Level-IV)								alyze
CO3	Examine tl	ne types of A	Antenna	and their configu	iratio	n.		Eva	lluate vel-V)
CO4	Design the	Antenna at	microlev	vel and study the	ir cha	racteri	stics.	· · · · ·	eate
				· · · · · · · · · · · · · · · · · · ·					vel-VI)
Semester		5 th				Autur	nn		
Contact H	ours	Lecture	Tu	torial	Pra	ctical	Credits	Total Hours	Teaching
0011000011	ourb	3	0		0		3	36	
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Equivalen	nt course								
codes	as per								
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Text Book	ts Title		Archar						
1.	Auth			nna Theory Analy Balanis	ysis al	iu Desig	gn		
		isher		Publication					
	Editi			dition					
2.	Title			nas: For All App	licati	ons			
	Auth			s, John D &, Rona			1		
		isher		McGraw Hill	. ,				
	Editi	on	3rd E	dition					
Reference	e Books								
1.	Title		Anter	nna Theory and I	Desigr	1			
	Auth			Stutzman and G.	A. Th	iele			
		isher		Publication					
	Editi		2005						
Course		Гŀ						D 11	
	UNI								n
Contents	Revi	ew of electro		ic theory, Antenn					
	Revi Mecl	ew of electro nanism and	Curren	t Distribution, F	Funda	mental	Parameter	s related	to
	Revi Mecl ante	ew of electro nanism and nna (Radiat	Curren	t Distribution, F ern, Radiation Po	Funda ower 1	mental Density	Parameter Directivity	s related , Gain, Bea	to ^m g
	Revi Mecl ante widt	ew of electro nanism and nna (Radiat h, Antenna	Curren ion Patte Efficier	t Distribution, F ern, Radiation Po icy, Bandwidth,	Funda ower 1 Pola	mental Density rization	Parameter , Directivity n, Radiation	s related , Gain, Bea n Efficienc	to m cy, 9
	Revi Mecl ante widt Ante	ew of electro nanism and nna (Radiat h, Antenna nna Factor	Curren ion Patte Efficier) Radia	t Distribution, F ern, Radiation Po acy, Bandwidth, tion Integrals,	Funda ower Pola Auxil	mental Density rization iary Po	Parameter Directivity, Radiation Ditential Fu	s related , Gain, Bea n Efficienc nctions ar	to m 9 29, nd
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	Analysis using assumed current Distribution Small Circular loop, Circular	
	Loop with constant current, Two Element Array N-Element Linear Array with	
	uniform amplitude and spacing, Broadside and End-Fire Array, N-Element	
	Linear Array: Three-Dimensional Characteristic	
	UNIT III:	
	Long Wire – Designing, V and Rhombic Antenna – Designing, Helical Antenna – Designing of normal and axial mode, rectangular apertures with different configurationsWith analysis Circular Apertures, E-Plane Sectoral Horn – Analysis and Design, H-Plane Sectoral Horn – Analysis and Design Pyramidal Horn	9
	UNIT IV:	
	Basic of Microstrip Antenna, Designing of Rectangular Microstrip Antenna, Antenna Ranges, Gain Measurement, Radiation Pattern Measurement, Anechoic Chamber	9
Course	Continuous Evaluation 25%	
Assessment	Mid Semester 25%	
	End Semester 50%	

Course Co	ode: PEV	-	Elective	HM Course:	PC Course	:: (Y/N)	PE Course: (Y/N)	
607		Course N	:(Y/N)	(Y/N) N	N		Y		
Type of Co	nurco		Course	IN	IN		1		
Course Tit			Theory Course INTRODUCTION TO MEMS						
Course Co									
Course Ob			rate the le	arners about mic	ro machines	materia	ls and systems f	or MEMS	
course ob				arners about mit		, materia	is and systems i	01 101110	
Course Ou	itcomes	Devices	, 				Cognitive Lev	rels	
	1	nd fundam	ental pri	nciples of sensing	g and actua	tion and	Understa		
co1 correspond			-				(Level-	II)	
CO2	Construc	t a compr	ehensive	perspective of	various fal	rication	Apply	7	
	processe	s and mater	rials used	in microfabricati	on.		(Level-I	II)	
CO3				, and fabrication t	echniques o	fleading	Analyz		
		•		AS industry.			(Level-I		
CO4	Design			EMS devices	0	relevant	Create		
	mechani		al/fluidic	engineering princ	ciples.		(Level-V	VI)	
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		Lecture	e Ti	utorial	Practical	Credit	s Total 1	Гeaching	
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	un cours	e							
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Equivalen codes proposed and old co	it cours as pe cours ourse s ts Tit	e r e e		nentals of Microfa	brication ar	nd Nanote	chnology		
Equivalen codes proposed and old co Text Book	at cours as pe course ourse cs Tit Au	e r e e chor	Marc M	adou	brication ar	ıd Nanote	chnology		
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	End Semester 50%	
Assessment	Mid Semester 25%	
Course	Continuous Evaluation 25%	
	UNIT IV: Materials, Mechanics and design of micro-systems: Silicon as a substrate, compounds, piezo-resistors, polymers, and packaging materials, micro-fabrication and micro-etching: static bending of thin plates, thermos-mechanics and thin film mechanics.	9
	Micro-actuators and Micro-sensors: Micro-sensors, acoustic wave sensors, biomedical and Nano-sensors, chemical sensors, optical sensors, pressure sensors, thermal sensors, micro-actuation through thermal forces, SMA-Piezo electric crystals, and electrostatic forces, magnetic actuation, micro-grippers, micro-motors, micro-valves, micro-pumps, micro-accelerometers.	

	ode: PEVL	-		HM Course:	PC C	Course:	(Y/N)	PE	Course:	(Y/N)
608		Course:	(Y/N)	(Y/N) N	N			Y		
Turne of Co			Course / I		IN			Ĭ		
Type of Co Course Tit		Theory Course/ Lab Course NANOELECTRONICS								
	ordinator	NANUEI		NICS						
Course Co		Toimpr	ovo tho fi	undamentals of el	octro	nicforn	ano cino	dou	icoc	
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course ou		d the fund	amontala	of classical CMOS	toch	nology	nd the	LUE	Unders	
CO1				ie sub-100nm reg		nonogy a	inu the		(Level	
CO2				nsistors with new		vico stri	ictures		Analy	
02	and nanon			insistors with he	w uc		ictui cs		(Level	
CO3			realizing	Germanium and	comn	ound			App	
000	semicondu		-	der mannann and	comp	ouna			(Level	-
CO4				characterization t	echni	aues th	at help		Evalu	
001				e transistors.		quee m	at norp		(Level	
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Jemester		-			P		_		m. • •	T 1'
6		Lecture		ıtorial	Pra	ctical	Credit	S	Total	Teaching
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names	th course									
Equivalen	t course									
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Text Book										
1.	Title		Fundan	nentals of Modern	VLSI	Devices	5			
	Auth	or		and T. Ning						
	Publ	isher		dge University Pr	ess					
	Edit	on	2 nd edit	ion 2009						
2.	Title		Silicon VLSI Technology							
	Auth	or								
	Publ	isher								
	Edit	on	2000							
Reference	Books									
1.	Title		Encyclo	paedia of Materia	ls Ch	aracteri	zation			
	Auth			e, C.Richard; Evan	s, Cha	rles A. J	r.;Wilso	n, Sh	aun	
		isher	Elsevier	ſ						
	Edit		1992							
Course	UNI		_			_			_	
Contents				s, Nano materials,						
		echnology node, Basic CMOS Process flow, MOS Scaling theory, Issues in								
		scaling MOS transistors: short channel effects, Description of a typical 65 nm							n	
		S technolo		classical MOS	rone	ctor M	05	acita	r Dolo	9
				-classical MOS 1 lated process tech						
		-	•	ate dielectrics. Ir	-					•
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		idates, CV	-	-	, 10110	ionity –	Zpa mgi	1 1101	a, possibi	
	UNI									9
	UNI									

	Metal gate transistor: Motivation, requirements, Integration Issues, Transport in Nano MOSFET, velocity saturation, ballistic transport, injection velocity, velocity overshoot. SOI - PDSOI and FDSOI, Ultrathin body SOI – double gate transistors, integration issues, Vertical transistors - FinFET and Surround gate FET, Metal source/drain junctions – Properties of Schottky junctions on Silicon, Germanium, and compound semiconductors-Work function pinning. Germanium Nano MOSFETs: strain, quantization, Advantages of Germanium over Silicon, PMOS versus NMOS.	
	UNIT III: Compound semiconductors – material properties, MESFETs Compound semiconductors MOSFETs in the context of channel quantization and strain, Heterostructure MOSFETs exploiting novel materials, strain and quantization.	9
	UNIT IV: Synthesis of Nanomaterials: CVD, Nucleation and Growth, ALD, Epitaxy, MBE. Compound semiconductor hetero-structure growth and characterization: Quantum wells and Thickness measurement techniques: Contact - step height, Optical - reflectance and ellipsometry. AFM. Characterization techniques for nanomaterials: FTIR, XRD, AFM, SEM, TEM, EDAX etc. Applications and interpretation of results. Emerging nano materials: Nanotubes, nano-rods and other nano structures, LB technique, soft lithography etc. Microwave-assisted synthesis, Self-assembly etc.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course C 609	ode: PEVL	Open Course:		HM Course: (Y/N)	PC C	Course:	(Y/N)	PE C	ourse	: (Y/N)
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Type of Co	ourse		Course/I					1		
Course Ti		Theory Course/ Lab Course CYBER SECURITY								
	ordinator		200111	-						
Course Ob		To gain	the funda	mentals of securi	tv me	asures	from cvb	er rela	ted th	reats
Course Ou		0			5			Cogni		
C01			ept of Cyl	per security and is	ssues	and cha	llenges		Under (Leve	
CO2	Analyze th	e cyber-cri		r nature, legal ren ilable platforms a					Anal (Leve	yze
CO3				security concern					Anal	
005				eporting procedu					(Leve	•
				ects and best pra					(LCVC	
		lia platforn	-	r i i i i i i i i i i i i i i i i i i i						
CO4				nd algorithms rela	ated t	o E-Con	nmerce		Crea	ate
	-	l payments	-						(Leve	el-VI)
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	ith course									
names	thi course									
Equivalen	nt course	•								
codes	as per									
proposed	-									
and old co										
Text Book	KS									
1.	Title)	Introdu	ction to Security	of Cył	er-Phys	sical Syst	tems		
	Autl	nor	Dr. Jeev	a Jose & Vijo Mat	hew					
	Pub	lisher		Book Publishing	Comp	oany.				
	Edit		2022							
2.	Title			rime and its Prev	entio	n in Eas	y Steps			
	Autl			u Chatterjee						
		lisher		Publishing House	е					
D (Edit	ion	2022							
Reference								1		
1.	Title			ttacks and Count	er-Me	asures	Made Sir	nple		
	Auth			u Chatterjee						
		lisher		Publishing Hous	е					
Course	Edit		2022	nace and Orear		Commut.	or and M	lob to-	hnolo	
Course Contents			•••	pace and Overvie bace, Communica		-			-	
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				et society, Regula						
		-		llenges of cyber se		-		meepe	51 0 9 0	~1
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				d mobiles, cyber		-		-		
		-		ngineering attack						
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	cyber-crimes, Remedial and mitigation measures, Legal perspective of cyber- crime, IT Act 2000 and its amendments, Cyber-crime and offences,	
	Organisations dealing with Cyber-crime and Cyber security in India, Case	
-	studies.	
	UNIT III: Introduction to Social networks. Types of social media, Social media platforms, Social media monitoring, Hashtag, Viral content, Social media marketing, Social media privacy, Challenges, opportunities and pitfalls in online social network, Security issues related to social media, Flagging and reporting of inappropriate content, Laws regarding posting of inappropriate content, Best practices for the use of Social media, Case studies.	9
	UNIT IV: Definition of E- Commerce, Main components of E-Commerce, Elements of E-Commerce security, E-Commerce threats, E-Commerce security best practices, Introduction to digital payments, Components of digital payment and stake holders, Modes of digital payments- Banking Cards, Unified Payment Interface (UPI), e-Wallets, Unstructured Supplementary Service Data (USSD), Aadhar enabled payments, Digital payments related common frauds and preventive measures. RBI guidelines on digital payments and customer protection in unauthorised banking transactions. Relevant provisions of Payment Settlement Act, 2007. End Point device and Mobile phone security, Password policy, Security patch management, Data backup, Downloading and management of third-party software, Device security policy, Cyber Security best practices, Significance of host firewall and Anti-virus, Wi-Fi security.	9
Course	Continuous Evaluation 25%	
Assessment	Mid Semester 25%	
	End Semester 50%	

Course Co 610	ode: PEVL	-		HM Course:	PC Course:	(Y/N)	PE Cour	se: (Y	Y/N)	
010		Course: (N	(/NJ	(Y/N)	N		Y			
Type of Co	nirse		urse/l		1		1			
Course Tit		Theory Course/ Lab Course ASIC AND FPGA DESIGN								
Course Co			11 011							
Course Ob		Understan	d non-	logic-design issue	es in ASIC an	d FPGA d	esign, inc	ludin	g timing,	
	,	power, an					0 /		0 0,	
Course Ou	tcomes	· •					Cogn	itive	Levels	
CO1	Understan	d the ASIC li	brary a	nd Design Flow.			U	nder	stand	
								(Leve	el-II)	
CO2	Analyze th	e RAM ROM	techno	logy and intercon	nects using Y	Kilinx.		Anal		
								Leve	,	
CO3	Apply the	logic synthes	is ASIC	Schematic design	n and constru	iction.		Anal		
<u> </u>	T al arad		1	• • • • • • • • • • • •	· · · · · · · · · · · · · · · · · · ·	. 1		Leve		
CO4	Evaluate t	ne FPGA floo	r plann	ing and design us	sing Xilinx far	niiy.		Evalı (Leve		
<u> </u>								Leve	ei-v j	
Semester		6 th			Sprin	-				
		Lecture	T	utorial	Practical	Credits			Teaching	
Contact H	ours					-	Hou	rs		
	ite course	3	0		0	3	36			
Equivalen codes proposed and old co	as per course									
Text Book	S									
1.	Title)	Appli	cation -Specific In	tegrated Circ	uits				
	Auth			. Smith						
		isher		on Education						
-	Edit		2003							
2.	Title			for programmabl	0					
	Auth			Skahill, Jay Legen	inausen					
		lisher		on–Wesley						
Reference	Edit	10[]	1997							
1.	Title	<u> </u>	Digita	l Decign: Principle	os and Practi	CO5				
1.	Auth		Digital Design: Principles and Practices John F. Wakerly							
		lisher	PHI	····						
	Edit			dition, 1994						
Course	UNI			, -						
Contents	Intro Desi	oduction: AS gn flow - CM	OS trar	10S Logic and AS asistors CMOS Des ta path logic cell.	-	•	-			
	UNI Revi		L/Veri	log, Anti fuse s	tatic RAM -	EPROM a	and EEP	ROM	9	

	technology, Xilinx I/O blocks. Programmable ASIC Interconnect	
	UNIT III: Logic Synthesis: Half gate ASIC -Schematic entry -Low level design language - PLA tools -EDIFCFI design representation. ASIC Construction, Floor Planning, Placement and Routing, System partition	9
	UNIT IV: FPGA partitioning: Floor planning -placement -physical design flow -global routing –detailed routing -special routing circuit extraction -DRC. Design using Xilinx family FPGA.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

	ode: PEVL	•		HM Course:	PC	Course:	(Y/N)	PE Course	e: (Y/N)	
611		Course: (Y	/N)	(Y/N)	N			Y		
Type of Co		N N Y Theory Course/ Lab Course Y								
Course Ti		RADAR ENGINEERING								
	ordinator	KADAK EN	GINE	EKING						
Course Ob		To introdu	CA st	udents to the ba	asic	concent	s of radar	communica	tion and	
	-	navigation.		ducints to the ba	asic	concept	5 01 14041	I		
Course Ou								Cognitive		
C01	Understan	d the principl	es of I	Radar jamming an	nd R	adar rang	ge.	Under: (Leve		
CO2	Analyze th	e target, their	detec	tion and interface	5			Anal (Leve		
CO3	Analyze th	e CW Radar, I	Doplai	Radar and Track	ing	Radar		Anal (Leve		
CO4	Apply the p	oulse compres	ssion	technique in Rada	ar sy	stem		Apr (Leve		
Semester	1	6 th				Sprin	g		,	
Contact H	ours	Lecture	Т	ıtorial	Pr	actical	Credits	Total 7 Hours	Feaching	
		3	0		0		3	36		
codes proposed and old co										
Text Book	s									
1.	Title		Mod	ern Radar System	n An	alvsis				
	Auth	or		d Barton. K						
	Publ	isher	Arte	ch House						
	Editi	on	1988	3						
2.	Title			ar Design Principl	es S	ignal Pro	cessing and	The Environ	iment	
	Auth			Nathanson E						
	Publ			raw Hill						
D (Editi	on	1969)						
Reference	BOOKS Title		Dad	ar Signals						
1.	Auth	or								
	Publ									
	Editi		1962							
Course	UNI		170							
Contents			tion:	Radar fundament	als,	Derivatio	n of range e	equation, the		
				amming and rada			•	-		
				clutter, Radar r					es 9	
	sour									
	UNIT								9	
	Theo	ry of Target D)etect	ion: Noise and fals	se al	arms, De	tection of or	ie sample of		

	signal with noise, Integration of pulse trains, Detection of fluctuating targets, CFAR, Optimum and matched filter Theory, Loss factors in detection. Targets and Interference: Definition of radar cross section, Radar cross section of simple and complex objects, Spatial distribution of cross section, Bistatic cross section.	
	UNIT III: CW and FM Radar: Doppler Effect, CW and FMCW Radar, Airborne Doppler Navigation, Multi frequency CW Radar. MTI Radar: Delay lines and line cancellers, Subclutter Visibility. MTI using range gates and filters, Pulse Doppler radar, Noncoherent MTI radar, Application of Digital signal processing to radar system. Tracking Radar: Different types of tracking techniques, tracking in range, Tracking in Doppler, Search Acquisition radar, Comparison of Trackers.	9
	UNIT IV: Introduction to Pulse Compression Radar: Height finding radars, Air traffic control Radars and data handling, Atmospheric effects of radar, Electromagnetic compatibility aspects, Airborne Radars, Synthetic Aperture Radar, Secondary surveillance Radars.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course C 612	ode: PEVL	Open Ele Course: (Y	ective (/N)	HM Course: (Y/N)	PC Co	ourse:	(Y/N)	PE Course: (Y/N)		
•1-		N	/	N	N			Y		
Type of Co	ourse	Theory Cou	irse/L	ab Course				-		
Course Ti		ADVANCE NEURAL NETWORK								
	ordinator			_						
Course Ob		To become	e famili	ar with several	advan	ced ma	achine-learn	ing method	ds, and to	
				ntly in Python usi						
Course Ou	itcomes							Cognitive		
C01	Understand	d the concept	ofneu	rons and human	brain ii	n neura	al network	Under (Leve		
CO2	Analyze th network	alyze the error corrections and filtering techniques for neura work							lyze el-IV)	
CO3	Apply the b	oack propaga	tion alg	gorithm in neura	l netwo	orks		Apj (Leve	ply	
CO4	Apply the f	eature mapp	ing tec	hniques for vario	ous mo	dels		Apj (Leve	ply	
Semester	I	6 th				Spring	g	L L	,	
Contact H	ours	Lecture	Tu	torial	Prac	tical	Credits	Total Hours	Teaching	
l		3	0		0		3	36		
Equivalen codes proposed and old co	as per course ourse									
Text Book	ts Title		Noural	Networks: A cor	nnroha	ncivo	foundation			
1.	Auth			Haykin	nprene	lisive	Iouiiuauoii			
	Publi			n Education						
	Editi			tion, 2004						
2.	Title			ial Neural Netwo	rks					
	Auth			nanarayana						
	Publi		0	ce Hall of India, P	vt. Ltd					
	Editi		2005							
Reference	e Books									
1.	Title			Networks in Cor	nputer	Intelli	gence			
	Auth		Li Min							
	Publi									
	Editi		2003							
Course	UNIT						· · ·			
Contents	techr no fr dyna view Repr	niques, Lagra ee lunch theo mical systen ed as Di esentation, A	nge mu orem, k ns. Hu rected	, norms and dist Iltiplier method, o basics of probabi man Brain, Moo Graphs, Net I Intelligence and	derivat lity the lels of work	ive fre eory, st a Ne Arch	e optimizati tate variable uron, Neura itectures,	on methods e analysis o	s, f 9 s e	
	UNIT	IT II:							9	

	Error Correction learning, Memory based learning, Hebbian learning, Competitive, Boltzmann learning, Credit Assignment Problem, Memory, Adaption, Statistical nature of the learning process, Adaptive filtering problem, Unconstrained Organization Techniques, Linear least square filters, least mean square algorithm, learning curves, Learning rate annealing techniques, perception –convergence theorem, Relation between perception and Bayes classifier for a Gaussian Environment	
	UNIT III: Back propagation algorithm XOR problem, Heuristics, Output representation and decision rule, Computer experiment, feature detection, BACK PROPAGATION - back propagation and differentiation, Hessian matrix, Generalization, Cross validation, Network pruning Techniques, Virtues and limitations of back propagation learning, accelerated convergence, supervised learning.	9
	UNIT IV: Two basic feature mapping models, Self-organization map, SOM algorithm, properties of feature map, computer simulations, learning vector quantization, Adaptive patter classification, Hierarchal Vector quantizer, contexmel Maps, Dynamical systems, stability of equilibrium states, attractors, neurodynamical models, manipulation of attractors' as a recurrent network paradigm, Hopfield models.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course (613	Code: P	PEVL	Open I Course:		HM Course: (Y/N)	PC (Course:	(Y/N)	PE	Course	(Y/N)
		Ν						Y			
Type of Course		Theory Course									
Course Title		VLSI INTERCONNECTS									
Course Co	oordina	tor									
Course Objectives		Introduce students to the basic interconnect parameters and its model. Students will learn Scaling and crosstalk issues of interconnects. They will also learn the repeater design methods and various advanced interconnects technique.									
Course O	utcome	S	Cognitive Levels								
CO1	To un	dersta	and the basic interconnect parameters and its model						Understand (Level-II)		
CO2	TO stu	ıdy di	ly different scaling issues in interconnects. App						oly		
CO3	To an	alyse t	yse theoretical and device level modelling of crosstalk					ζ.	(Level-III) Analyze (Level-IV)		
CO4		To learn the repeater various advanced			r interconnects technique. design methods and				Understand (Level-II)		
Semester			6 th				Spring	J			
Semester			Lecture	Т	itorial	Dra	ctical	g Credits		Total	Teaching
Contact H	lours		Lecture	11	1101101	r I a	lllai	creun		Hours	Teaching
contact I	iours		3	0		0		3		36	
codes w names Equivaler codes proposed and old c Text Boo	nt co as l co ourse	urse urse per urse									
1.		Title		High-Sp	eed VLSI Interco	nnect	s 2007				
1.		Autho	nr	Ashok k		mett	5,2007				
		Publis									
		Editio		2007	Ind Co						
		Title		Advance Applica		ULSI	Inter	connects	s: Fi	undame	ntals and
	F	Autho									
		Publis			dge University Pr	ess					
	F	Editio									
Referenc	e Books	5									
1.		Title		Carbon nanotube and Graphene Device Physics							
		Autho									
		Publis		0,							
_		Editio		2011							
Course					VLSI Interconnec						
Contents		scalin	•	3D interconnect view; Interconnect Parameters: Resistance, nce, and Capacitance, skin effect and its influence on resistance and							
		induc Mode mode	tance. Int ls: The lui	erconneo nped RC Vire Mod	tance, skin effect ct RC Delays: Eln Model, the distrik lels: Distributed	nore l outed	Delay Ca RC Mod	lculatio el, the tr	n. Int ansm	erconne ission li	ect 9 ne

	UNIT II: Scaling issues in interconnects: Gate and Interconnect Delay; CMOS Repeater: The Static Behavior- Switching Threshold, Noise Margins, The Dynamic Behavior Computing the capacitances, Propagation Delay: First order Analysis, Propagation Delay from a Design perspective, Power, energy and Energy-Delay- Dynamic Power Consumption, Static Consumption, Analyzing Power Consumption using SPICE.	9
	UNIT III: Repeater Design: Driving Interconnects for Optimum speed and power; Short channel model of CMOS Repeater - Transient Analysis of an RC loaded CMOS repeater, Delay Analysis, Analytical power expressions: Dynamic power, Short circuit Power, Resistive Power Dissipation, CMOS Repeater insertion: Analytical expressions for delay and power of a repeater chain driving an RC load.	9
	UNIT IV: Advanced Interconnect Techniques: Reduced-swing Circuits, Current-mode Transmission Techniques Crosstalk: Theoretical basis and circuit level modeling of crosstalk, Energy dissipation due to crosstalk: Model for energy calculation of two coupled lines. Contribution of driver and interconnect to dissipated energy, Crosstalk effects in logic VLSI circuits: Static circuits, Dynamic circuits and various remedies.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course Code: PEVL 614 Type of Course		Open Elective Course: (Y/N		PC C	ourse:	(Y/N)	PE	Course: (Y	/N)
		N	N	Ν			Y		
		Theory Course	e/ Lab Course				1		
Course Ti			, IINE LEARNING FO	R IC					
Course Co	ordinator								
Course Ob	ojectives		ndamentals of Progr ning techniques	ammin	ig for A	rtificial I	ntell	igence and	
Course Ou	utcomes	1	0 1				Cog	nitive Leve	els
CO1	Introduce t search stra	ne fundamentals of AI, problem-solving, and basic Remember							-
CO2		l various AI sea	rch algorithms.					Analyze (Level-IV	
CO3		he fundamental learning techni	s of machine learnin ques	ng, expl	ore			Apply (Level-II	I)
CO4	Explore uns	supervised lear	ning techniques and	l introd	uce the			Apply	
		als of reinforcer					(Level-III)		
Semester		6 th			Spring	5			
Contact H	ours	Lecture	Tutorial	Prac	tical	Credit	Credits Tota Hou		ching
		3	0	0		3		36	
Prerequis codes wit names	site course h course								
Equivalen codes as p	ber								
proposed and old co									
Text Book									
1.	Title	Artif	icial Intelligence: A	Moder	n Annro	hach			
1.	Autho	Artificial Intelligence: A Modern Approach or Russell, Norvig							
	Publi		Prentice Hall						
	Editio		Third edition, 2010.						
2.	Title		MACHINE LEARNING An Algorithmic Perspective						
	Autho		Stephen Marsland						
	Publi		Taylor & Francis Group, LLC						
	Editio		2nd Edition, 2015						
Reference			,						
1.	Title	Intro	duction to Machine	e Learni	ing				
	Autho								
	Publi		The MIT Press, Cambridge, Massachusetts, London, Engla						
	Editio		2nd Edition.						
Course	UNIT	UNIT I: Introduction-AI problems, Agents and Environments, Structure of							
Contents		Agents, Problem Solving Agents Basic Search Strategies: Proble							
		nformed Search (Breadth-First, Depth-First Search, Depth-f							9
	Iterat	tive Deepening), Heuristic Search (Hill Climbing, Generic I						First, A*),	
		straint Satisfaction (Backtracking, Local Search)							
	Searc	II: Advanced Search- Constructing Search Trees, Stochastic Search, AO*9th Implementation, Minimax Search, Alpha-Beta Pruning Basic9							9
	Know	vledge Represer	tation and Reasoni	ng: Pro	positio	nal Logic	c, Firs	st-Order	

	Logic Forward Chaining and Packward Chaining Introduction to	
	Logic, Forward Chaining and Backward Chaining, Introduction to	
	Probabilistic Reasoning, Bayes Theorem	
	UNIT III: Machine-Learning- Introduction, Machine Learning Systems, Forms	
	of Learning: Supervised and Unsupervised Learning, reinforcement – theory	
	of learning – feasibility of learning – Data Preparation– training versus testing	
	and split.	9
	Supervised Learning: Regression- Linear Regression, multi linear regression,	
	Polynomial Regression, logistic regression, Non-linear Regression, Model	
	evaluation methods. Classification: – support vector machines (SVM), Naïve	
	Bayes classification	
	UNIT IV: Unsupervised learning- Nearest neighbor models – K-means –	
	clustering around medoids – silhouettes – hierarchical clustering – k-d trees,	
	Clustering trees – learning ordered rule lists – learning unordered rule.	9
	Reinforcement learning- Example: Getting Lost -State and Action Spaces	-
Course	Continuous Evaluation 25%	•
Assessment	Mid Semester 25%	
	End Semester 50%	

Course C	Code: PE	-	Elective	HM Course:	PC (Course:	(Y/N)	PE Course	: (Y/N)	
615		N	e: (Y/N)	(Y/N)	N			Y		
Type of Course			N N Y Theory Course							
Course Title				IUNICATION						
Course Co	oordinato	r								
Course O	bjectives									
Course O	,	•						Cognitive I	evels	
CO1		lerstand the concept of communication in VLSI. Understand the Understand the H Frequency model of MOS and importance of Impedance (Level-II ching.								
CO2		<u> </u>	transceiv	er and radio arch	itectu	res.		-	ply	
			110						el-III)	
CO3	Design I	low Noise a	mplifiers a	and Mixers with s	pecifi	cations			uate	
C04	Dealine								el-V)	
C04		ions to tran		and Frequency synthesizers and their				Analyze (Level-IV)		
Semester		6th	Sectiver de			Sprin	σ	(10)		
		Lectur	e T	utorial	Pra	ctical	Credit		Teaching	
Contact H	lours	-			0		-	Hours		
D		3	0		0		3	36		
Prerequis codes w										
codes w names	ith cour	se								
Equivaler	nt cour	50								
codes		er								
proposed	I -									
and old c										
Text Bool	ks									
1.	Ti	tle	RF Mic	roelectronics						
	Au	ıthor	B.Razav	B.Razavi						
	Ρι	ıblisher	sher Pearson Education Limited							
		lition		Edition.2013						
2.		tle	Radio-Frequency Integrated Circuits and Systems							
		ithor								
		lblisher								
Doforma		lition	2015							
Reference 1.		tle	VICIFO	r Wiroloss Comm	unicat	ior				
1.		ithor	r Bosco Leung							
		ıblisher								
		Edition		2011						
Course				to Communicat	ion ir	VLSI:	Complex	ity design a	nd	
Contents				Technology - Bas			-	•		
	-	-	ne Variance - Intersymbol Interference - random pro- nitions of sensitivity - dynamic range -conversion Gain FET behaviour at RF frequencies - Noise performance ar						50	
									u u	
	М	OSFET beh								
			ces - Impedance matching networks - transformers and baluns.							
			II: Analog& Digital Communication system: Coherent and Non 9							
			ent detection - Mobile RF Communication systems and basics of Multiple s techniques - Receiver and Transmitter Architectures and Testing:							
	•			a a a jura a ser d' l'	a a wa - 1 / 1			a and "reat"		

	Heterodyne - Homodyne, Image-reject, Direct-IF and subsampled receivers - Direct Conversion and two steps transmitters.	
	UNIT III: Low Noise Amplifiers and Mixers: Low Noise Amplifiers: Common Source LNA - Common Gate LNA -Cascode LNA. Mixers: Design of Active and Passive Mixers.	9
	UNIT IV: Oscillators : Basic topologies VCO and definition of phase noise. Noise-Power trade-off. Resonatorless VCO design - Quadrature and single- sideband generators - Radio Frequency Synthesizers: PLLs.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course C	ode: PEVL	Elective	HM Cours	e: DC Cou	ırse: (Y	Y/N)	DE	Course:	(Y/N)
616		Course: (Y/	N) (Y/N)						
		Y	Ν	Ν			Ν		
Type of Co			se/ Lab Course						
Course Ti		MEMORY D	EVICES AND CIRCU	ITS					
Course Co	ordinator								
Course Ol	ojectives	Preferable in	one or two lines in	continuati	on witl	hout bւ	ullets	s and nun	nbering
Course Ou	utcomes						Cog	nitive Le	
CO1	acquaint t	he students wit	h memory cell devi	ces				Unders (Leve	
CO2	Analyze t SRAM cell	ne read write	operation in memo	ory periph	erals, 1	novel		App (Level	-
CO3	Analyze th	e read write op	peration of DRAM co	ell				App (Level	•
CO4	Analyze t	he read/write	/hold operations	of differen	nt me	mory		Anal	yze
	structures	using CAD too	ls			-		(Leve	
Semester		7 th		Α	utumr	1			
		Lecture	Tutorial	Practic		Credit	c	Total	Teaching
Contact H	ours	Lecture	Tutoriai	riacui		cieuit	3	Hours	Teaching
Contact II	ours	3	0	0		3		36	
Proroquio	site course	-	-	0		5		30	
-	ith course	•	Sign						
names	itin course								
Equivaler	nt course								
codes	as per								
proposed	-								
and old co									
Text Bool		•							
1.	Title)	Semiconductor Me	emory Devi	ces and	l Circu	its		
	Auth	ior	Shimeng Yu						
	Pub	lisher	CRC Press						
	Edit	ion	1 st edition						
2.	Title)	Memory Devices						
	Auth	ior	David R. Coelho						
	Pub	lisher	Kluwer Academic	Publishers,	Spring	ger			
	Edit	ion	1989						
Reference	e Books								
1.	Title								
	Auth								
		isher							
	Edit								
Course	UNI								
Contents			le memory, Non-v	olatile mer	nory,	On-chi	p m	emory, C)n 9
		memory types	•						
	UNI					-			. 9
			ircuit design, sensi	· ·	-		•		st
			peripheral circuitri	es, Next ger	neratio	n SRAI	M cel	11.	
		T III:		AN. 1		0.	. 1.6	.1.1. 1	
			AM, High speed DRA			-			9
	arra circi		ns, Bandwidth, lat	ency, and	cycle	ume, I	rowe	er, rimin	g
		T IV:							9
	UNI	1 1 1 1							7

	STT-MRAM, Data migration policy for hybrid cache. Operation of FLASH memories (FLASH array sensing and programming), Charge Pump circuits. Basic of memory compiler for SRAM architecture using scripting language
Course	Continuous Evaluation 25%
Assessment	Mid Semester 25%
	End Semester 50%

	ode: PEVL	-	Elective	HM Course:	PC (Course:	(Y/N)	PE (Course	: (Y/N)
717		Course	:(Y/N)	(Y/N) N	N			Y		
Type of Co	NIITEO	Theory	Course	IN	IN			I		
Course Ti		CAD FO								
	ordinator									
Course Ob		To educ	ate the le	earners about use	ofcor	nputer	Aided Des	ign fo	or VLSI	digital logic
	,	families				- P		-0		
Course Ou	itcomes								Cogniti	ive Levels
CO1	Understan	d the fund	amentals	of Computer-Aid	ed De	sign (CA	AD) tools f		<u> </u>	lerstand
COI	the design,	analysis.							(Le	evel-II)
CO2	-	-	ter-Aide	d Design (CAD) to	o perf	form sy	nthesis, te	est		nalyze
	and verific									evel-IV)
CO3	0			puter-Aided Desi	0 0					reate
	0	d placeme	ent of di	gital Very Large-	Scale	Integra	ation (VLS	SI)	(Le	evel-VI)
<u> </u>	systems.				1.17				C	
CO4	Create the	mini proje	ect work	with Computer-Ai	aea L	besign (LADJ tool			reate evel-VI)
<u> </u>		-							(Le	evel-vij
Semester		7 th			1	Autur	1			
a		Lecture	e T	utorial	Pra	ctical	Credits		Total	Teaching
Contact H	ours	2			0		2		Hours	
Duouomula		3	0		0		3		36	
codes with	ite course ith course									
names	itii course									
Equivalen	t course									
codes	as per									
proposed	course and									
old course	e									
Text Book	KS:									
1.	Title			sis and Optimizati	on of	Digital	Circuits			
	Auth		G. De M							
	Publ		McGrav	w Hill						
	Editi		1994							
2.	Title			ynthesis	Cl	h 1 17	V. t			
	Auth			vadas, A. Abhijith Academic	GUOS	n and K	. Keutzer			
	Publ Editi		1998	Academic						
Reference		011	1990							
1.	Title		Digital	VLSI Chip Design	with (Cadence	and Sync	nsve	CADT	ools
	Auth		E. Brun			Judenet	, and by no	-1-2-2-2		0010
		isher		n Wesley						
	Editi		2010							
Course	UNI		•							
Contents	Over	view of di	gital logi	c design, Simplific	ation	of swit	ching fun	ction	s, K-ma	ıp-
	base	d reductio	n of swi	tching functions. (Comb	inationa	al logic de	esign,	Compl	ex 9
			0	dules such as mul	-	•	-	kers,	decode	rs,
			use in s	tandardized comb	inatio	onal logi	ic design.			
	UNI						_			_
		-		time delay con	-	-	-			
	-			pts and state diag			-			
	anal	sis and	uesign;	Synthesis of st	ale (nagram	s; runda	imen	tai-moo	le

	sequential circuits.	
	UNIT III:	
	Analysis and design, hazards, races, and cycles. Logic element realization: Ideal switch-based implementation; Logic families; FET switches; MOS switch-based logic realization; NMOS and CMOS logic-Pass transistor logic; Algorithmic optimization of combinational logic; VLSI realization of combinational logic.	9
	UNIT IV:	
	Language-based description of complex digital systems; RTL descriptions and design language representation; Levels of description; Behavioural and structural descriptions; VHDL and Verilog.	9
Course	Continuous Evaluation 25%	
Assessment	Mid Semester 25%	
	End Semester 50%	

718	e Code: I	PEVL	Open Course	Elective	HM Course: (Y/N)	PC Course:	(Y/N)	PE Cour	rse: (Y/N)
/10			N	. (1/N)	N	N		Y	
Type o	of Course		Theory	course	14	11		-	
Course					ACTERIZATION				
	e Coordina	ator							
Course	e Objectiv	es	To educ	cate the lea	rners about the p	roperties, gr	owth technic	ques and a	pplications
·			of thin f	films.	-				
Course	e Outcome	es							ve Levels
CO1	To under	rstand	the kine	tics and gr	owth of thin film.			Unde	erstand
									vel-II)
CO2	Analyse t	the gro	owth tech	nniques, m	easurements and	l property of	thin films		alyze
600		1 110	<i>c</i> .	1					vel-IV)
CO3	Analyse t	the dif	fusion pr	ocess in th	in films.				aluate
<u> </u>	Tashawa	-		<u> </u>					vel-VI)
CO4	10 chara	cterise	e the thin	nim and a	analyse the coatin	ig mechanish	n		aluate vel-VI)
0								(Lev	vei-vij
Semes	ster		7 th			Autumn	T		
			Lecture	e Tu	torial	Practical	Credits	Total	Teaching
Contac	ct Hours		-					Hours	
	quisite co		3	0		0	3	36	
Equiva		ourse							
names Equiva codes propos and ol	alent co as	ourse per ourse							
Equiva codes propos	alent co as sed co d course	per							
Equiva codes propos and ol	alent co as sed co d course	per		Material	ls Science of Thin	Films: Depo	sition and St	ructure	
Equiva codes propos and ol Text B	alent co as sed co d course	per ourse Title Autho		M. Ohrin	ng	Films: Depo	sition and St	ructure	
Equiva codes propos and ol Text B	alent co as sed co d course	per purse Title Autho Publis	sher	M. Ohrin Academ	ng ic Press	Films: Depo	sition and St	cructure	
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	Beam Epitaxy, Atomic Layer Deposition, spin & dip coating and Chemical vapour deposition. Film thickness measurement, properties of thin films: Structural, optical, electrical and mechanical properties.	
	UNIT III: Thin film analysis (with applications of techniques in solving research problems): ion beam sputtering, depth profiling, Study of inter diffusion in thin films using XPS, AES, SIMS and RBS. Diffraction studies on thin films using XRD and LEED. Thin film morphological studies by SEM, STM and AFM.	9
	UNIT IV: Characterization of thin films: Different methods of thickness measurements, electrical, optical, chemical and structural property determination. Some important applications of thin films: Hard and decorative coatings, semiconductor thin films, organic thin films.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

	e Code: P	EVL	-	Elective	HM Course:	PC Course:	(Y/N)	PE Course	e: (Y/N)
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Course			MIXED-	SIGNAL IO	C DESIGN				
	e Coordina								
	e Objective		To educa	ate the lea	rners about ICs f	for mixed sign	nal applicatio		
Course Outcomes								Cognitive	
CO1					miconductor fiel with models use			Unders (Leve	
CO2	Analyse t	he CM	IOS digital	l circuits o	operation.			Analy (Leve)	5
CO3			-	•	behaviour of the	devices and c	circuits with	Evalu	late
CO4	which dig				ation, and layout			(Leve Evalu	
LU4	Explain u	le ch c	uit desigi	i, opuniiz	ation, and layout	5.		(Leve	
-						L _		(Leve	1-V J
Semes	ster		7 th			Autumn			
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codes propos and ol	as sed cou d course	per urse							
Text B	ooks								
1.		Title		Analog N	MOS integrated ci	ircuits for sig	nal processin	Ig	
		Autho	or	U	rian and Temes		1	0	
		Publis	sher	Wiely					
		Editio	n	2008					
2.		Title		Introduc	ction to CMOS op	amps and cor	nparators		
		Autho	or	R.Grego	rian				
	Γ	Publis	sher	Wiely in	terscience				
		Editio	n	1999					
Refere	ence Books								
1.		Title		Analog i	ntegrated circuit	design			
		Autho	or	D.Johns	and K.Martin				
		Publis		Wiely					
		Editio		2008					
Course		UNIT		_					
Conter)S amplifiers: de				9
		-		-	tional trans-cond	-		n of single	
				ic cascode	e, folded cascade	and two-stag	e amplifiers.		<u> </u>
		UNIT		_			41 ·	_	9
					n schemes: Miller	compensatio	on, Ahuja com	pensation	-
		and N	ested Mil	ier compe	ensation.				

	UNIT III: Design of fully differential amplifiers, discussion of common mode feedback circuits. Switched capacitor circuits, design of switched capacitor amplifiers and integrators, effect of opamp finite gain, bandwidth and offset, circuit techniques for reducing effects of opamp imperfections, switches and charge injection and clock feed-through effects.	9
	UNIT IV: Design of sample and hold and comparators. Fundamentals of data converters; Nyquist rate A/D converters (Flash, interpolating, folding flash, SAR, and pipelined architectures); Nyquist rate D/A converters - voltage, current and charge mode converters, hybrid, and segmented converters); Oversampled A/D and D/A converters. Design of PLL's and DLL's and frequency synthesizers.	9
Course	Continuous Evaluation 25%	
Assessment	Mid Semester 25%	
	End Semester 50%	

	ode: PEVL	-	Elective	HM Course:	PC C	ourse:	(Y/N)	PE Co	ourse: (Y	Y/N)
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Course Co		DIO M								
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	,	applica					101 010 1			
Course Ou	tcomes							Co	ognitive	Levels
CO1	Demonstra	te stand	ard tests,	measurements, a	nd ex	perime	ents and		Unders	
01	analyse and	d interpr	et the resu	llt to improve pro	cesses	- 5.			(Leve	l-II)
CO2	Develop kr	nowledge	e about di	fferent types of H	Electro	des, Ti	ansduce	ſS,	Арр	oly
	and Amplif	iers.							(Leve	l-III)
CO3	Examine th	e import	ant and m	odern methods o	f imag	ing tecł	nniques.		Anal	-
									(Leve	,
CO4	Apply the e	lectroni	cs fundame	entals for bio-med	lical aj	pplicati	on.		Anal	
		1							(Leve	l-IV)
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and old co										
Text Book										
1.	Title			k of Biomedical In	istrun	ientatio	on			
	Auth		R.S. Khan							
	Publi		Tata McG							
2	Editi	on		on, 2003.	I E audi]	_	
2.	Title Auth	or		tion to Biomedica			anu rechi	notogy	,	
	Publi			seph and John M. Hall, New Jersey	DIOWL	1				
	Editi		4th editio							
Reference		511								
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	Auth	or	Sabrie So		•					
	Publi			Publishing House						
	Editi		2020							
	Laith									
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				signals, Bio-elect		-				
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		-	-	d Sensing, Strain (-	-				
			nsors to	Circuits, Tempe	erature	e, Capa	acitive, a	and Ii	nductive	
		sducers.								
	UNIT		1	a. 1 -	_ .				-	9
	Bioel	ectric A	mplifiers:	Signal Processin	g Circ	uits, P	ractical ()p-Am	ps, and	

	Isolation Amplifiers Chopper Stabilized Amplifiers, Electrocardiographs: The Heart as a Potential Source, The ECG Waveform, The Standard Lead System, Other ECG Signals, The ECG Preamplifier ECG Readout Devices, ECG Machines, ECG Maintenance and Troubleshooting.	
	UNIT III: Physiological Pressure and Other Cardiovascular Measurements and Devices: Physiological Pressures, Pressure Measurements, Blood Pressure Measurements Oscillo metric, and Ultrasonic Non-invasive Pressure Measurements. Pressure Amplifier Designs, AC Carrier Amplifiers, Systolic, Diastolic, and Mean Detector Circuits, Pressure Differentiation (dP/dT) Circuits, Practical Problems in Pressure Monitoring, Step-Function Frequency Response Test, Defibrillator Circuits, Pacemakers.	9
	UNIT IV: Medical Ultrasonography: Ultrasound Transducers, Absorption, and Attenuation of Ultrasound Energy, Biological Effects of Ultrasound, Doppler Effect, Transcutaneous Doppler Flow Detector, Flowmeters, Ultrasonic Blood Pressure Measurement.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

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721			e: (Y/N)	(Y/N)	N		
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Course Ob	ojectives	-	n the known ency range.		the applicati	on of elec	ctronic devices in rado
Course Ou	itcomes	neque	incy range.				Cognitive Levels
			ncv resnor	se of MOSFET.			Understand
CO1	merpretra	neque	ney respon				(Level-II)
CO2	Construct th	ne RF teo	chnology a	nd basic concept	s in RF design	1.	Apply
							(Level-III)
CO3	Analyse con	nmunica	ation conce	pts in transceive	r architecture	es.	Analyze
	5			•			(Level-IV)
CO4	Evaluate ba	sic blocl	ks in RF sys	stems such as LN	A, Mixer and	VCO.	Evaluate
							(Level-V)
Semester		7 th			Autumn		
		Lectur	re Tu	itorial	Practical	Credits	Total Teaching
Contact H	ours						Hours
		3	0		0	3	36
Equivalen codes proposed old course	as per course and						
Text Book	75						
1.	Title		Radio Fre	equency Integrate	ed Circuit Des	sign	
	Autho	r		1. Rogers, Calvin		0	
	Publis		Artech Ho	U			
	Editio		2010				
2.	Title		Operation	n and Modelling o	of MOS Transi	istor	
	Autho	r	Yannis Ts	ividis, Colin McA	ndrew		
	Publis			niversity Press			
	Editio	n	3rd editio	on, 2011			
Reference			1				
1.	Title			electronics			
	Autho		Behzad R				
	Publis		Prentice				
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Course	UNIT		d anti-	m of MOC ''			toff linear and
ContentsDerivation and estimation saturation region, derivation including threshold voi conductance (gds), small				ation and estimat ltage, body eff l-signal output r	tion of MOSFE ect, transcon resistance (r _o	ET's long-o iductance), A Medi	channel model (g _m), output um-Frequency
	Small	-Signal N	Model for t	ne Intrinsic Part,	Intrinsic Trar	nsition Fre	equency, Noise

	in MOSFET: white noise, flicker noise, High frequency Small Signal Model, Transition Frequency (f_T) and Maximum oscillation (f_{max}) of MOSFET.	
	UNIT II:	
	Introduction to RF and Wireless Technology: Challenges in RF Design, Complexity Comparison, Design Bottleneck, Applications, Choice of Technology; Basic concepts in RF Design: Units in RF Design, Time Variance, Nonlinearity, Effects of nonlinearity; Noise as Random Process, effect of transfer function on noise, device Noise, Representation of Noise in Circuits. Sensitivity and Dynamic Range.	9
	UNIT III: Analog modulation, Digital modulation, Spectral Regrowth, Mobile RF Communications, Multiple Access techniques Wireless standards; Receiver Architectures: Basic Heterodyne Receivers, Modern Heterodyne Receivers, Direct-Conversion Receivers, Image Reject Receivers, Low-IF Receivers; Transmitter Architectures: Direct-Conversion Transmitters, Modern Direct- Conversion Transmitters, Heterodyne Transmitters.	9
	UNIT IV: Low Noise Amplifier Design in various technologies, Design of Mixers at GHz frequency range; Various Mixers, their working and implementations; Oscillators: Basic topologies of VCO and definition of phase noise. Noise Power tradeoff. Resonator less VCO design; Quadrature and single-sideband generators.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

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144		_	Course:	(Y/N)	(Y/N)						
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Type of			Theory Course HIGH SPEED INTERFACING CIRCUITS								
Course '			HIGH SI	PEED IN I	ERFACING CIRC	UITS					
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	Objectives		10 gain	the know	ledge of dynamic	CMOS circuit	ts for high-				
Course	Outcomes		- hasiaf		nd nooda fan alaal	ring studies		Cognitive			
CO1					nd needs for cloc			(Lev	rstand el-II)		
CO2	Develop applicati	•	od under:	standing	in the advanced	clock logic st	yles and it	-	ply el-III)		
CO3			d profici	ency in th	e different non-c	locking logic	styles		ply		
	-	U		5		0 0	5	(Leve			
CO4	Evaluate	the v	vorking c	of differer	it latching strateg	ies		Eval	uate		
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Semeste	er		7 th			Autumn					
			Lecture	Τι	ıtorial	Practical	Credits	Total	Teaching		
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	switched output differential structure, clocked pass-gate logic, dynamic complementary pass gate logic.	
	UNIT III: Static combinational CMOS logic, pulsed static logic, Differential cascode voltage switch logic, Differential split-level logic, cascode non-threshold logic, CMOS pass gate & transmission gate logic, DCVS logic with pass gate, complementary pass gate logic	9
	UNIT IV: Basic Latch design, storage elements, static and dynamic latches, latch clocking, pseudo-inverter latch, True single-phase clocking, Double edge triggered flip-flops, DCVS latches, static RAM latches, Race free latches for pre-charged logic, cross-coupled differential output	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course 723	Code: Pl	EVL	-	Elective e: (Y/N)	HM Course: (Y/N)	PC	Course:	(Y/N)	PE Course	: (Y/N)
			N		N	N			Y	
Type of	Course		Theory	v Course						
Course'					E PROCESSING					
	Coordinat	or								
Course	Objectives	5	0		vledge of differen or digital applicat		sforms, s	egmentat	ion and con	pression of
Course	Outcomes		0		0 11				Cogniti	ve Levels
CO1	Analyze	imag	es in the	frequent	cy domain using v	arious	s transfo	rms.		nalyze evel-IV)
CO2	Evaluate	the t	echniqu	les for im	age enhancement	and in	mage res	storation.	Ev	aluate evel-V)
CO3	Categoriz	ze va	rious co	mpressio	n techniques.				A	nalyze
										evel-IV)
CO4	Interpret		mage	compres	sion standards	5, S6	egmenta	tion ar		raluate
	represen	itatio	n techni	ques.			1		(Le	evel-V)
Semeste	er		7 th				Autur	nn		
Contact	Hours		Lectur	e T	'utorial	Pra	ctical	Credits	Total Hours	Teaching
			3	0		0		3	36	
-	uisite cou with cou ent cou	rse								
codes propose	as j ed cou	per rse								
and old Text Bo										
1.		Title		Digital I	mage Processing					
1.		Autho	nr	Digital Image Processing or R. C. Gonzalez and R. E. Woods						
		Publis								
		Editio			lition, 2009					
2.	Г	ſitle			ental of Digital In	1age P	rocessin	lg		
		Autho		Anil K Ja						
		Publis		Prentice	Hall					
		Editio	on	1989						
	ice Books			m 1						
1.		<u>Fitle</u>			ential guide to ima	age pr	ocessing	5		
		uthc ublis		A. C. Boy Academ						
		Editio			edition 2009					
Course		JNIT		Jeconu	LUIUUII 2007					
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				•	g, colour image p		•		-	
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concepts for image processing, Intensity transformation, Filtering in spatial and Frequency domain: Image negatives, Log transformations, Histogram processing, Spatial filter: smoothing and Sharpening, Discrete Fourier transform, properties of 2-D DFT, Image smoothing and Sharpening in Fourier						am ier				
		loma	-	•	, -8-		0	F	0	

	UNIT II: Image transforms: Two-dimensional orthogonal and Unitary transforms, Optimum transform, Properties of Unitary transforms, 2D DFT, Cosine transforms, Hadamard transforms, KL transforms, Comparison of image transforms, Edge detection: Gradient and Laplacian based edge detection, Diffusion based edge detection: Isotropic and anisotropic diffusion.	9
	UNIT III: Wavelet transform for Image Processing: Multi resolution expansion, Wavelet functions, Wavelet Series expansion, Continuous and Discrete Wavelet transforms, Wavelet transforms for two dimensional signals (images), Applications of wavelet transforms for edge extraction, noise suppression.	9
	UNIT IV: Image segmentation: Thresholding, region-based Morphological Watersheds, Bayesian-base image segmentation. Image restoration and reconstruction: Models of image degradation, noise models, Spatial and Frequency domain- based approaches for image restoration, Inverse filtering, Wiener Filtering, Bayesian denoising. Image Compression: Spatial and Temporal redundancy, Basic image compression models, compression standards, basic compression methods: Huffman coding, Run-length coding, Block transform coding, Predictive coding. Colour Image Processing: Colour Fundamentals, Colour Models, Colour transformation, smoothing, sharpening and edge detection in colour images.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course Code: PEVL 724		-		HM Course:	PC (Course:	(Y/N)	PE Course	e: (Y/N)	
/24		Course: (Y/NJ	(Y/N)	N			Y		
Type of Co	ourso		nirco	IN	IN			1		
Course Ti		Theory Course FLEXIBLE ELECTRONICS								
	ordinator									
Course Ob		To enhan	ce the	knowledge of el	ectro	nic devi	ces with	flevihle st	ructure and	
course or	bjeenves	applicatio		Knowledge of ef			CC3 WITH	IICAIDIC 30	fucture and	
Course Ou	itcomes	applicatio	/115					Cognit	ive Levels	
dourse or	Summariz	e the	advan	tages, drawb	acks	ner	formance	<u> </u>	lerstand	
CO1				eness of large a		-		-,	evel-II)	
	silicon tec	-	1	0			0		,	
CO2			princip	les, architectures	, and	process	ing of mai	n A	Apply	
				d for flexible elect			0		evel-III)	
CO3	Analyse th	e concept of	f thin fil	m electronics				A	nalyze	
	-	-						(Le	evel-IV)	
CO4	Elaborate	systems in	ntegrati	on issues and	prop	ose me	ethods fo	r (Create	
	integration	n and encaps	sulation	of printed device	es and	l system	s.	(Le	evel-VI)	
Semester		7 th				Autun	nn			
		Lecture	Τι	utorial	Pra	ctical	Credits	Total	Teaching	
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		3	0		0		3	36		
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	materials, Thin-film Deposition and Processing Methods for Flexible Devices, Solution-based Patterning Processes; Ink-jet printing, gravure, and other processes, surface energy effects, multilayer patterning. UNIT III: Flexible Thin-Film Transistors and Circuits: Thin-Film Transistor; Device structure and performance, Electrical characteristics, parameter extraction, characterization methods for rigid and flexible devices, electrical stability, printed transistors; organic/polymer, metal-oxide, electrolyte gated, Case studies; sub micrometer OTFTs and gravure printed OTFTs, From transistors to circuits.	9
	UNIT IV: Circuits on flexible and non-silicon substrates, Contacts, and Interfaces to Organic and Inorganic Electronic Devices: Schottky contacts, defects, carrier recombination, the effect of applied mechanical strain. Other Flexible Devices and System Integration: Organic Light Emitting Diodes, Organic Solar Cells, thin flexible OLED displays, OLED lighting, smart wallpaper, sensors, logic, and memory, RFID tags, Latest applications of printed electronics, Encapsulation, Roll to roll printing processes, Integration Issues, and Designs for the Future.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course C	ode: PE		-	Elective	HM Course:	PC (Course:	(Y/N)	PE	Course:	(Y/N)	
725			Course	: (Y/N)	(Y/N)							
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Type of Co			Theory Course									
Course Tit			QUANTUM COMPUTING									
Course Co			Toonh	ango tho f	un domontolo of a	nontr	m com	auting to	ahni	auga in au	mont and	
Course Ob	ojectives		To enhance the fundamentals of quantum computing techniques in current and future technologies									
Course Ou	itcomes	1	iuture t	ecimolog	163				Coo	gnitive Le	vols	
		strate	the fra	mework	of quantum comp	utatio	n		CUE	Unders		
CO1	Demons	Strate	, the hu		n quantani comp	atatio				(Level		
CO2	Utilize 1	the fr	amewo	ork to loo	k how that may	be us	eful for	future		Appl		
	quantur				, i i i i i i					(Level-	-	
CO3			U		n computing.					Analy		
	5			1	1 0					(Level		
CO4	Apply th	he qua	antum (circuits fo	r error control.					Appl	у	
							-			(Level-	·III)	
Semester		2	7 th				Autur	nn				
		I	Lecture	e T	utorial	Pra	ctical	Credit	ts	Total	Teaching	
Contact H	ours									Hours	_	
			3	0		0		3		36		
Prerequis												
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codes	-	ber										
proposed and old co	cour	rse										
Text Book												
1.		itle		Quantu	m Computation a	nd Ou	antum	Informat	tion			
1.		uthor	-		ielsen and I. L. Ch	-		morma	uon			
		ublish			dge University Pr	0						
		dition		10 th , 20	· · ·							
2.		itle		,	m Information an	d Cor	nputatio	on				
		uthor	•	J. Presk			1					
		ublish		,	ture Notes							
		dition		1998								
Reference	Books		·									
1.	Ti	itle		Quantu	m Theory: Conce	ots an	d Metho	ods				
	A	uthor	•	Asher F	Peres							
		ublish	ıer	Kluwer	Academic Publis	ners						
		dition		1993								
Course		NIT I:										
Contents			-		echanics and Mo			-		-	u u	
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		computational basis unitary evolution.										
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		-	-		cloning theorem	-		•				
					qualities. Protoc							
	T	егерог	rtation	- gates:	CNOT - Toffoli	gate	- NAN	u - FAI	NUUT	i - Walsh	1	

	Hadamard. Measurement: Projective operators - General, Projective and POVM measure, Ensemble: Density operators - pure and mixed ensemble - time evolution – post measurement density operator. Composite systems: Partial trace - Reduced density operator - Schmidt decomposition, Purification bipartite entanglement.	
	UNIT III: Quantum computing: Classical computing using qubits - Quantum parallelism - Deutsch's algorithm -Deutsch Josza algorithm.	9
	UNIT IV: Quantum circuits: Basic gates - ABC decomposition - Gray codes - Universal gates - Principle of deferred and implicit measurements - Quantum Fourier transform - applications: phase estimation, order finding - factoring, discrete logarithm and hidden subgroup problems - Role of prime factoring in classical cryptography – search algorithms. Quantum error correcting codes, Physical realization of qubits.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

	ode: PEVL	-		HM Course:	PC C	Course:	(Y/N)	PE	Course:	(Y/N)
726		Course:	(Y/N)	(Y/N) N	N			Y		
Type of Co	urco		Jourse	IN	IN			1		
Course Tit			Theory Course SOLAR CELL TECHNOLOGY							
Course Co		JOLING								
Course Ob		To enha	ance the	fundamentals	of wo	orking	of photo	ovolt	aic mod	ules, their
	,		To enhance the fundamentals of working of photovoltaic modules, their characteristics and fabrications technologies							
Course Ou	itcomes	•				0		Cog	nitive Le	evels
C01	Understan	d the princ	iples and	l arrangements of	silico	n atoms	and p-		Unders	stand
	n junction								(Leve	l-II)
CO2	Apply know	wledge on	solar cell	l parameters for e	fficie	nt desig	n		Арр	-
									(Level	
CO3	-	e growth	process	of metallurgical a	nd el	ectronic	c grade		Anal	•
<u> </u>	silicon	o]]]	an of est		. for 1	orrolare	nont -f		(Level	
CO4	commercia		0	ar cell technology	ior d	evelopr	nent of		Crea (Leve)	
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Semester						Autun				
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Equivalen	t course									
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and old co										
Text Book										
1.	Title		Solar Photovoltaic Technology and Systems							
	Auth			Singh Solanki	·	• • •	1			
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		isher	Springe		11, 311	yann				
	Editi			tion, 2016.						
Reference			200000							
1.	Title		SOLAR	ENERGY						
	Auth	or	S. P. Sul							
	Publ	isher	McGrav	v hill education						
	Editi			ition, 2017						
Course				as solar cell mate					-	
Contents				attices in solar ce						
				n atom, quantum						
				tion of energy ba						
				P-N junction dio sities and carrier						
				/ relation quanti			-			
		-		generation of pho		-		-		
				solar cell characte				accu		-
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	End Semester 50%	
Assessment	Mid Semester 25%	
Course	Continuous Evaluation 25%	
	and rear contact.	
	solar cell, buried contact and rear point contact solar cell, passivated emitter	
	pattern defining and deposition; High efficiency solar cell: passivated emitter	
	process, thin film layer for ARC and surface passivation, metal contacts-	
	damage removal and surface texturing, P-N Junction formation - diffusion	
	commercial Si cell technology; processes used in solar cell technology: saw	9
	multi-crystalline Si and first terrestrial PV modules; process flow of	
	optimized junction, front metal and surface texturing, use of screen printing,	
	single crystal, diffused junction and anti-reflective coating; improvement from	
	UNIT IV: Development of commercial solar cell: improvement from use of CZ	
	feedstock for solar cell industry.	
	production of Si wafers: monocrystalline Si ingots- CZ and FZ process; multi- crystalline Si ingots; wafer-dicing: ID and wire sawing; Si sheet, silicon	
	grade Si (EGS): high purity Si containing gases, obtaining solid poly-Si;	9
	Si wafers, production of metallurgical grade Si (MGS), production of electronic	0
	UNIT III: Growth of solar PV industry and Si requirements; steps in producing	
	measurement, minority carrier lifetime and diffusion length measurement.	
	Analytical Techniques: solar simulators, I-V measurement, quantum efficiency	
	requirement of high Voc; Design of high FF: base resistance, emitter resistance;	
	minimization of optical losses, minimization of recombination; Design	
	Isc: requirement of high Isc, choice of junction depth and its orientation,	2
	efficiency, effect of temperature in efficiency; sola cell designs; Design of high	9
	of series and shunt resistance on efficiency, effect of solar radiation in	
	voltage, Fill Factor, Efficiency; Losses in solar cell: model of a solar cell, effect	
	UNIT II: Upper limits of cell parameters: short circuit current, open circuit	

Course C	ode: PEVL	Open Elect Course: (Y/I		PC Course:	(Y/N)	PE Course	: (Y/N)			
		N	N	N		Р				
Type of Co	ourse	Theory Cour	se							
Course Ti		ADHOC SENSOR NETWORKS								
Course Co	ordinator									
Course Ob	ojectives	Preferable in	one or two lines in	continuation w	vithout bull	lets and nu	mbering			
Course Ou	itcomes					Cognitiv	e Levels			
C01	To Unders	tand the Adhoc	wireless networks	and their Proto	ocols.		erstand vel-II)			
CO2	To Analyse	e the transport	An	alyze vel-IV)						
CO3	To Analysi	s of Wire and v	vireless sensors netv	works.		An	alyze			
CO4	To Evamin	o tho communi	cation and routing F	Protocol			vel-IV) aluate			
C04			ication and routing r	1010001.			vel-V)			
Semester		6 th		C	~		vervj			
Semester		-	T	Sprin	_					
<u> </u>		Lecture	Tutorial	Practical	Credits	Total	Teaching			
Contact H	ours	2	0	0	2	Hours				
D .	site course	3	0	0	3	36				
Equivalen codes proposed and old co	as per course ourse									
Text Book										
1.	Title		Ad HOC Wireless N		itectures &	& Protocols				
	Auth		C Siva Ram Murty							
		isher	Pearson Education	l.						
	Edit		2 nd Edition							
2.	Title		Fundamentals of M		vasive Com	puting				
	Auth		Adleshein & Gupta							
		isher	ТМН							
	Edit	ion	2005							
Reference			T							
1.	Title		Protocols and Arch	nitectures for V	Vireless Se	nsor Netwo	orks,			
	Auth		By Holger Karl							
		isher	John Wiley & Sons							
Edition			2006							
Course	UNI									
Contents			ntroduction, Mobile			0	ų			
		-	es in Ad hoc wireles	s Networks, IE	EE 802.11	Architectu	ire 🥤			
	and	protocols.								

1		
	Protocol for AD HOC Wireless Networks: Issues and classification of MAC protocol, other MAC protocols, Dynamic Source Routing (DBR), Adhoc Distance	
	Vector (AoDV) routing, Routing Protocols, Multicasting Routing issues	
	UNIT II:	
	Transport layer & Security protocols: Issues in designing transport layer protocols, TCP over Ad Hoc Wireless Networks, Network Security Attacks, and	9
	Key management.	
	UNIT III:	
	Wire Sensor Networks: Basic Sensor Network Architectural Elements, Applications of Sensor Networks, Comparison with Ad Hoc Wireless Networks, Challenges and Hurdles.	9
	Architecture of WSNs Hardware components, Operating systems and execution environments, some examples of sensor nodes, Network Architecture, Sensor networks scenarios, Optimization goals and figures of merit, Design principles for WSNs.	
	UNIT IV:	
	Communication Protocols: Physical Layer and Transceiver design considerations in WSNs, Fundamentals of (wireless) MAC protocol, Address and name management in wireless sensor networks, Localization and positioning	9
	Routing protocols: Data Dissemination and Gathering, Routing Challenges and Design Issues in Wireless, Routing Strategies in Wireless Sensor Networks, QoS in wireless sensor networks, Coverage and deployment	
Course	Continuous Evaluation 25%	
Assessment	Mid Semester 25%	
Assessment	End Semester 50%	

	ode: PEVL	Open El		HM Course:	DC	Course:	(Y/N)	DE Cou	urse: (Y/N)
728		Course: (Y/NJ	(Y/N)	N			N		
Type of Co	ourse	Theory Co	nirse	1	1			IN		
Course Ti		FULL CUS		ESIGN						
	ordinator	1012000	10112	201011						
Course Ob		Preferable	e in one	or two lines in co	ontinu	ation w	rithout b	ullets and	d numł	pering
Course Ou								Cogniti		
C01	Understan	d efficient L	ayout d	esign techniques.				U	ndersta	and
								(Level-	
CO2	Absorb the	process variations into the layout. Apply								
CO3	Construct	mand ringa	nadrin	a quiting mived	aianal	onvinor	mont		Level-l	
C03	Construct	guaru rings,	paurin	gs suiting mixed	signai	enviror	iment.		Analyz Level-l	
CO4	Design lave	outs minimi	zing str	ess effects					Analyz	
COT	Design laye		Ling Sti	css cheets.					Level-l	
Semester	<u>I</u>	7 th				Δ	nn	(•)
semester		-			P	Autun				
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Contact H	ours	3	0		0		3	H0	urs	
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-	ith course									
names	tin course									
Equivalen	nt course									
codes	as per									
proposed	course									
and old co	ourse									
Text Book										
1.	Title			IC Layout Concep	ots Me	thodolc	ogies and	l Tools		
	Auth		Dan C							
	Publi	1								
	E 1.4.	sher	Newn							
2	Editi		Newn 2000	es						
2.	Title	on	Newno 2000 The Ar	es rt of Analog Layou	ut					
2.	Title Auth	on or	Newno 2000 The An Ray Al	es rt of Analog Layou an Hastings	ut					
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2. Reference	Title Auth Publi Editi	on or isher	Newno 2000 The An Ray Al Prenti	es rt of Analog Layou an Hastings	ut					
	Title Auth Publi Editi	on or isher	Newno 2000 The An Ray Al Prenti	es rt of Analog Layou an Hastings ce Hall	ut					
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Reference	Title Auth Publi Editi Books Title	on or isher on or	Newno 2000 The An Ray Al Prenti	es rt of Analog Layou an Hastings ce Hall						
Reference	Title Auth Publi Editi Books Title Auth Publi Editi Editi	on or isher on or isher on	Newno 2000 The An Ray Al Prenti	es rt of Analog Layou an Hastings ce Hall	<u>ut</u>					
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Reference 1. Course	Title Auth Publi Editi e Books Title Auth Publi Editi Editi UNIT Intro VLSI Signi	on or isher on or isher on C I: oduction: So manufactur ficance of fu	Newno 2000 The An Ray Al Prenti 2nd Eo chemat	es rt of Analog Layou an Hastings ce Hall dition, 2006 ic fundamentals,	Layou nd cor	nectivi	ty, Proce			
Reference 1. Course	Title Auth Publi Editi e Books Title Auth Publi Editi Editi UNIT Intro VLSI Signi UNIT	on or isher on or isher on C I: oduction: So manufactur ficance of fu C II:	Newno 2000 The Ai Ray Al Prenti 2nd Eo 2nd Eo chemat	es rt of Analog Layou an Hastings ce Hall dition, 2006 ic fundamentals, ocesses, Layers ar om IC design, layo	Layou nd con ut des	nnectivit sign flov	ty, Proce vs.	ess design	n rules	
Reference 1. Course	Title Auth Publi Editi Books Title Auth Publi Editi UNIT Intro VLSI Signi UNIT Adva	on or isher on or isher on C I: oduction: So manufactur ficance of fu C II: inced tech	Newno 2000 The An Ray Al Prenti 2nd Ed and Ed chemat	es rt of Analog Layou an Hastings ce Hall dition, 2006 ic fundamentals, ocesses, Layers ar om IC design, layo for specialize	Layou nd con ut des d bu	ilding	ty, Proce vs. blocks :	ess design Standar	n rules d cell	9
Reference 1. Course	Title Auth Publi Editi e Books Title Auth Publi Editi UNIT Intro VLSI Signi UNIT Adva libra	on or isher on or isher on C I: oduction: So manufactur ficance of fu C II: unced tech ries, Pad ce	Newno 2000 The Ai Ray Al Prenti 2nd Eo 2nd Eo chemat ring pro ill custo miques ells and	es rt of Analog Layou an Hastings ce Hall dition, 2006 ic fundamentals, bcesses, Layers ar om IC design, layo for specialize Laser fuse cells	Layou nd con ut des d bu , adva	ilding	ty, Proce <u>vs.</u> blocks : echnique	ess design Standar es for bu	n rules d cell ulding	
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Reference 1. Course	Title Auth Publi Editi e Books Title Auth Publi Editi UNIT Intro VLSI Signi UNIT Adva libra block desig	on or isher on or isher on F I: oduction: Se manufactur ficance of fu F II: inced tech ries, Pad ce ss, Power gr	Newno 2000 The Ai Ray Al Prenti 2nd Eo 2nd Eo chemat ring pro ill custo miques ells and id Clock- lectrica	es rt of Analog Layou an Hastings ce Hall dition, 2006 ic fundamentals, becesses, Layers ar om IC design, layo for specialize Laser fuse cells c signals and Inter l requirements, I	Layou nd con ut des d bu , adva	ilding anced to ectrouti	ty, Proce vs. blocks : echnique .ng. Inter	Standar Standar s for bu	n rules d cell iilding layout	9

	Layout considerations due to process constraints: Large metal via implementations, Step coverage rules, Special design rules, Latch-up and Guard rings, Constructing the pad ring, Minimizing Stress effects.	
	UNIT IV: Proper layout: CAD tools for layout, planning tools, Layout generation tools, Support tools. Analog layout concepts.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course	Code: P	EVL	Elective		HM Course:	DC Co	urse:	(Y/N)	DE	Course:	(Y/N)	
729			Course: (Y/	N)	(Y/N)	2000		(-/-)			(-/-)	
			Y	.,	N	Ν			Ν			
Type of	Course		Theory Cour	·se					I			
Course 7			ADVANCED S	SEMIC	ONDUCTOR MAN	UFACTU	RING					
Course (Coordina	tor										
Course (Objective	es	Preferable in	n one	or two lines in co	ntinuat	ion w	ithout b	ullets	and nur	nbering	
Course (Outcome	S							Cogn	itive Lo	evels	
C01	Comp	rehen	sive Knowled	ge of	Advanced Manuf	acturin	g Proc	cesses		Unders (Leve		
CO2	In-Dej Equip		Understandin Process Integ	0	f Semiconducto n Strategies	or Ma	terial	s and		l-III)		
CO3					d Scaling Down T	echnol	ogies			oly		
CO4	Reliah	ility (onsideration	s in Se	emiconductor Ma	nufacti	iring			(Leve) Anal		
004	Renat	inty c	2011310121211011	5 111 50		luctor Manufacturing				(Leve	·	
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Semeste	1		•							m . 1		
Contact	Hours		Lecture		torial	Practi	cal	Credit]	Total Hours	Teachi	ng
			3	0		0		3		36		
Prerequ codes v			Digital IC De	sign								
names												
Equivale codes		urse										
propose	as d cou	per urse										
and old		urse										
Text Boo												
1.		Title		Sem	iconductor Micro	ochips a	and F	abricatio	on: A	Practica	al Guide	to
					ory and Manufact							
		Autho	or		lang Lian	0						
		Publis	sher	John	Wiley and Sons	Inc.						
		Editic	n	2023	3							
2.		Title			dbook of VLSI Mi							
		Autho		Will	iam Glendinning,	Willian	n And	rew				
		Publis										
		Editic	n	2012	2							
Referen				5		<u> </u>			6			
1.		Title			-to-Run Control i	n Semic	condu	ctor Mar	utacti	uring		
		Autho			es Moyne							
		Publis Edition			Press							
Course		Editic UNIT		2018	0						1	
Contents				condu	ictor manufactu	ring an	d ite	significa	nce ¹	Historia	al	
Goments			verview of semiconductor manufacturing and its significance, Historical 9									
	ļ	CONTE	ontext and evolution of semiconductor manufacturing technologies., ontext and evolution to advanced processes and equipment.									
								acturing	tech	nologie	3.,	
		Intro	duction to adv						tech	nologie		
		Introc UNIT	duction to adv II:	vanceo	l processes and e	equipme	ent.				d	
	-	Introc UNIT Princi	duction to adv II: iples of photo	vanceo olitho		equipme onducto	ent. or ma	nufactur	ing, A	dvance	d o	
		<u>Introc</u> UNIT Princi lithog	duction to adv II: iples of photo raphy technic	vanceo olitho ques a	d processes and e	equipme onducto In-dept	ent. or ma h stud	nufactur ly of etc	[.] ing, A hing p	dvance	d s 9	
		Introd UNIT Princi lithog and	duction to adv II: iples of photo raphy technic equipment, T facturing	vanceo olitho ques a	d processes and e graphy in semic and innovations,	equipme onducto In-dept	ent. or ma h stud	nufactur ly of etc	[.] ing, A hing p	dvance	d s 9	

	Overview of advanced materials used in semiconductor manufacturing, Operation and optimization of state-of-the-art manufacturing equipment, Strategies for integrating complex manufacturing processes. Case studies: Examining challenges and solutions in process integration	
	UNIT IV: Techniques for enhancing semiconductor device performance, Innovations in scaling down semiconductor technologies, Factors aRecting reliability in semiconductor manufacturing. Quality control and reliability testing procedures.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course C 730	ode: PEVL	Open Elec Course: (Y/		HM Course: (Y/N)	DC	Course:	(Y/N)	DF	E Course:	(Y/N)		
		Ν		Y	Ν			Ν				
Type of Co	ourse	Theory Cou	rse	•								
Course Ti	tle	DATA CONV	VERT	ERS								
Course Co	ordinator											
Course Ob	ojectives	Preferable in	n one	or two lines in co	ntinu	ation w	ithout b	ullet	s and nun	nbering		
Course Ou	utcomes							Cog	gnitive Le	evels		
C01	-	e DC biasing c fier configurat		ions and small sig	nal m	odel of v	various		Unders (Leve			
CO2	To understa	and gm/Id de	sign r	nethodology of va	rious	s MOS ci	rcuits		Apply (Level-III)			
CO3	-	he noise mod s MOS circuit		g and analysis pr	oced	ure asso	ociated		App (Leve)	oly		
CO4	To study st	ability condit	ions a	and various comp ack amplifiers	ensat	ion tech	niques		Anal (Leve)	yze		
Semester		7 th		r r		Autun	nn					
Contact H	ours	Lecture	Τι	utorial	Pra	ctical	Credit	S	Total Hours	Teaching		
Contact II	ours	3	1		0		4		48			
-	site course ith course	5			0		1		10			
Equivaler	t course											
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Text Book		r										
1.	Title		· · ·	g to Digital Conver	sion							
	Autho			l Pelgrom								
	Publi											
	Editio			lition, 2013								
2.	Title			standing Delta-Sig								
	Autho			ni Pavan, Richard	Schre	ier, Gab	or C. Ter	nes				
	Publi		Willey – IEEE Press									
Reference	Editio		nu EC	lition, 2017								
1.	Title	ח	ata C	onverters								
1.	Autho			o Malobreti								
	Publi											
	Editio		Springer Verlag 2007									
Course	UNIT		007									
Contents			ant	i-aliasing filters, g	zain a	and offs	et error	s. def	finitions	of		
2011001100				R, ENOB of ADC/								
				ing, Bandgap refe				r	- r var			
	UNIT			<u>, , , , , , , , , , , , , , , , , , , </u>		0						
			ACs, o	current cell desigr	ı issu	es. Prop	erties of	MOS	Switche	s, 12		
		•		rapping, sampling		-				,		
		and nonlinea			-			-				
	UNIT	'III:								12		

	Comparator architectures, metastability and yield, Clock feed through effects, switched capacitor amplifiers and offset cancellation, SAR, Flash, Pipeline and time interleaved ADC topologies and their CMOS realizations issues. Error correction procedures for ADCs.	
	UNIT IV: Delta sigma modulators, alternative modulator architectures, quantization and noise shaping, decimation filtering, implementation of Delta sigma modulators, delta sigma DACs.	12
Course	Continuous Evaluation 25%	
Assessment	Mid Semester 25%	
	End Semester 50%	

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Apply							
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Analyze							
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8							
e of FPGA-Based							
Morgan Kaufmann							
July 2010							
Field – programmable Gate Array Technology							
Stephen M. Trimberger r Springer							
and Flows							
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enges in 12							

	Compute Models and System Architectures FPGA Programming with Verilog HDL Compiling C for FPGA Streaming FPGA Applications using Simulink Block Diagrams Operating System Support for Reconfigurable Computing UNIT III:						
	Technology Mapping-FPGA Design Optimization Strategies-Datapath Composition Circuit Layout Specification on FPGAs-Path Finder: Performance- driven FPGA Routing-Retiming and Re-pipelining Techniques-Configuration Bitstream Generation-Fast Compilation Techniques	12					
	UNIT IV: Implementing Applications with FPGAs-Precision Analysis for Fixed-point Computation-Distributed Arithmetic-CORDIC Architectures for FPGA Computing-Hardware/Software Partitioning, SPIHT Image Compression- Automatic Target Recognition Systems-Multi-FPGA Systems: Logic Emulation- Floating Point Considerations-Network Packet Processing-Memory-centric Computation (Active Pages)						
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%						

Open Elective courses

Contact Hours Hours	vels ind I) e V) II) ie
Type of CourseTheory CourseCourse TitleGROWTH, FABRICATION AND MANUFACTURING OF ELECTRONIC DEVCourse CoordinatorTo provide rigorous foundation in MOS and CMOS fabrication process.Course ObjectivesTo provide rigorous foundation in MOS and CMOS fabrication process.Course OutcomesCognitive LeeC01To Understand the characterization techniques and design flow of IC technology.Understand (Level-IIC02To Analyse the monolithic fabrication techniques and monolithic components in different transistors.Analyze (Level-IIC03To Examine the Assembly and packaging of the VLSI Devices.Apply (Level-IIC04Explore the modern processing techniques in VLSI device fabrication.Evaluat (Level-VSemester6thSpringContact HoursLectureTutorialPracticalCreditsTotal Tea HoursFutorialPracticalCredits	vels ind I) e V) II) ie
Course TitleGROWTH, FABRICATION AND MANUFACTURING OF ELECTRONIC DEVCourse CoordinatorTo provide rigorous foundation in MOS and CMOS fabrication process.Course ObjectivesTo provide rigorous foundation in MOS and CMOS fabrication process.Course OutcomesCognitive LeeC01To Understand the characterization techniques and design flow of IC technology.Understand (Level-IIC02To Analyse the monolithic fabrication techniques and monolithic components in different transistors.Analyze (Level-IIC03To Examine the Assembly and packaging of the VLSI Devices.Apply (Level-IIC04Explore the modern processing techniques in VLSI device fabrication.Evaluat (Level-VSemester6thSpringContact HoursLectureTutorialPracticalCreditsTotal	vels ind I) e V) II) ie
Course Coordinator To provide rigorous foundation in MOS and CMOS fabrication process. Course Outcomes Cognitive Lege C01 To Understand the characterization techniques and design flow of IC technology. Understand (Level-II (Level-II)) C02 To Analyse the monolithic fabrication techniques and monolithic components in different transistors. Clevel-II (Level-II) C03 To Examine the Assembly and packaging of the VLSI Devices. Apply (Level-II) C04 Explore the modern processing techniques in VLSI device fabrication. Evaluat (Level-V) Semester 6 th Spring Contact Hours Lecture Tutorial Practical Credits Total Teal	vels ind I) e V) II) ie
Course ObjectivesTo provide rigorous foundation in MOS and CMOS fabrication process.Course OutcomesCognitive LeeCO1To Understand the characterization techniques and design flow of IC technology.Understand (Level-II)CO2To Analyse the monolithic fabrication techniques and monolithic components in different transistors.Analyze (Level-II)CO3To Examine the Assembly and packaging of the VLSI Devices.Apply (Level-II)CO4Explore the modern processing techniques in VLSI device fabrication.Evaluat (Level-V)Semester6thSpringContact HoursLectureTutorialPracticalCreditsHoursTotal Technology.	nd I) e V) II) re
Course OutcomesCognitive LetCO1To Understand the characterization techniques and design flow of IC technology.Understand (Level-II (Level-II)CO2To Analyse the monolithic fabrication techniques and monolithic components in different transistors.Analyze (Level-II)CO3To Examine the Assembly and packaging of the VLSI Devices.Apply (Level-III)CO4Explore the modern processing techniques in VLSI device fabrication.Evaluat (Level-V)Semester6thSpringContact HoursLectureTutorialPracticalCreditsTotalTexHours	nd I) e V) II) re
CO1To Understand the characterization techniques and design flow of IC technology.Understa (Level-IICO2To Analyse the monolithic fabrication techniques and monolithic components in different transistors.Analyze (Level-IVCO3To Examine the Assembly and packaging of the VLSI Devices.Apply (Level-IICO4Explore the modern processing techniques in VLSI device fabrication.Evaluat (Level-VSemester6thSpringContact HoursLectureTutorialPracticalCreditsContact HoursImage: Contact HoursImage: Contact HoursImage: Contact Hours	nd I) e V) II) re
CO1 technology. (Level-II) CO2 To Analyse the monolithic fabrication techniques and monolithic components in different transistors. Analyze (Level-IV) CO3 To Examine the Assembly and packaging of the VLSI Devices. Apply (Level-II) CO4 Explore the modern processing techniques in VLSI device fabrication. Evaluat (Level-V) Semester 6th Spring Contact Hours Lecture Tutorial Practical Credits Total Teal	I) e V) II)
components in different transistors. (Level-IV C03 To Examine the Assembly and packaging of the VLSI Devices. Apply (Level-II C04 Explore the modern processing techniques in VLSI device fabrication. Evaluat (Level-V Semester 6 th Spring Contact Hours Tutorial Practical Credits Total Teat Hours	V) []) :e
Or of the modern processing techniques in VLSI device fabrication. (Level-II (Level-II) CO4 Explore the modern processing techniques in VLSI device fabrication. Evaluat (Level-V Semester 6th Spring Contact Hours Credits Total Tea Hours	II) :e
CO4 Explore the modern processing techniques in VLSI device fabrication. Evaluat (Level-V Semester 6 th Spring Contact Hours Lecture Tutorial Practical Credits Total Teal	e
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Contact Hours Hours	
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3 0 0 3 36	
Prerequisite course	
codes with course	
names	
Equivalent course	
codes as per	
proposed course	
and old course	
Text Books :	
1. Title VLSI Technology	
Author S.M. Sze	
PublisherTata McGraw HillEdition1983	
2. Title Introduction to VLSI	
Author Eshraghian & Pucknell	
Publisher Tata McGraw-Hill	
Edition 2007	
Reference Books	
1. Title VLSI Fabrication Principles	
Author S.K. Gandhi	
Publisher Wiley-Blackwell	
Edition 2nd Edition 1994.	
Course UNIT I:	
ContentsMiniaturization & its impact on characterization of Electronic Systems: Introduction, Trends & Projections in IC Design & Technology. Comparison between semiconductor materials. Basics of Thick and thin Film Hybrid Technology and monolithic chips. Advantages, limitations & Classification of ICs. Bipolar & MOS Techniques: Flow chart of Bipolar, NMOS and CMOS technologies. Basics of VLSI Design & Process Simulation, SUPREM.	9
UNIT II:	9

	Monolithic Techniques: Silicon Refining for EGS, Single Silicon Wafer Preparation & Crystal Defects, Epitaxial Process, Diffusion, Ficks' Laws, Oxidation, Ion-Implantation, Photolithography, Basics of Vacuum Deposition & CVD, Etching techniques, Plasma Etching, Metallization and Isolation Techniques. Monolithic Components: Diodes and Transistors, JFETs, MOSFETs, Resistors, Capacitors, MESFETs, Basics of VLSI CMOS technology, Reliability issues in CMOS VLSI, Latching, and Electromigration.	
	UNIT III: Assembly Techniques & Packaging of VLSI Devices: Introduction to packaging, Package design considerations, VLSI Assembly techniques, Packaging fabrication technology. Surface Mount Technology (SMT): Through hole technology, Surface Mount Technology, applications & SM Components.	9
	UNIT IV: Special Techniques for Modern Processes: Self-aligned silicides, hallow junction formation, nitride oxides etc. process flows for CMOS and bipolar IC processes.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course C 602	ode: OEVL	Open E Course:		HM Course: (Y/N)	РС	Course:	(Y/N)	PE Cour	rse: (Y	Y/N)	
		Y		N	Ν			Ν			
Type of Co		Theory C									
Course Ti		ELECTR	ONIC MA	ATERIALS							
	ordinator										
Course Ob	ojectives			indamentals for nodern VLSI Devi				device	mater	ials and	
Course Ou										Levels	
CO1	Understan	stand the synthesis and properties of nanomaterials.			l	Understand (Level-II)					
CO2	Analyse mo	odelling of	composi	te materials by fi	nite e	element a	analysis.		Analyze (Level-IV)		
CO3	Differentia	te superco	nducting	materials.					App (Leve		
CO4	Understan	d the chara	cteristic	s and uses of func	tiona	al materi	als.	l	Jnders (Leve		
Semester		6 th				Spring	g				
Contact H	ours	Lecture	Τι	ıtorial	Pra	ctical	Credits	s Tota Hou		Teaching	
contact n	ours	3	0		0		3	36	10		
Equivalen codes proposed and old co	as per course										
Text Book	(S										
1.	Title		Nano: T	he Essentials							
	Auth	or	T.Prade	ep							
	Publ			cGraw-Hill							
-	Editi		2008								
2.	Title			ok of Nano science	e and	Nanote	chnology				
	Auth			rthy et al.							
	Publi			sity press							
Doforces	Editi	un	2010								
Reference 1.	Title	[Compos	site Materials							
1.	Auth	or	Composite Materials Krishan K Chawla								
	Publi		Springe								
	Editi		2 nd Ed.,								
Course	UNI		<u> </u>								
Contents			: Origin	of nano technolo	ogy, (Classifica	tion of n	ano mate	erials.		
			•	ectrical, mechani							
	Prep chem carbo	aration of nical vapou on nano tu	nano ma 1r depos bes (CN1	terials by plasma hition (CVD), Sol- Γ). Synthesis, preprese, nano biology,	a arci Gel, parat	ing, phys electro d ion of na	sical vapo deposition anotubes,	our depos n, ball m	ition, illing,	9	

	UNIT II: Composites: General characteristics of composites, composites classes, PMCs, MMCs, CMCs, CCCs, IMCs, hybrid composites, fibers and matrices, different types of fibers, whiskers, different matrices materials, polymers, metal, ceramic matrices, toughening mechanism, interfaces, blending and adhesion, composite modelling, finite element analysis and design.						
	UNIT III: Optical materials: Mechanisms of optical absorption in metals, semiconductors and insulators. Nonlinear optical materials, optical modulators, optical fibers. Display devices and materials photo emissive, photovoltaic cells, charge coupled devices (CCD), laser materials.	9					
	UNIT IV: Super conducting materials: Types of super conductors, an account of mechanism of superconductors, effects of magnetic field currents, thermal energy, energy gap, acoustic attenuation, penetration depth, BCS theory, DC and AC Josephson effects, high Tc superconductors, potential applications of superconductivity, electrical switching element, superconductor power transmission and transformers, magnetic mirror, bearings, superconductor motors, generators, SQUIDS etc.	9					
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%						

Course C	ode: OEVL	Open Ele	rtive	HM Course:	PC (Course:	(Y/N)	PE	Course	: (Y/N)	
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Type of Co	ourse	Theory Cou	rse								
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	ordinator										
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Course Ou										ve Levels	
C01		and the MOSI	ТЕТ ој	peration their inte	ernal	charact	eristics.		Und	lerstand	
										evel-II)	
CO2	To study a	mplifiers and	their	classifications.						Apply	
						• •				vel-III)	
CO3	To analyse	CMOS circuit	s and	application in me	mory	design				lerstand	
004		1 1 1 .							· · ·	evel-II)	
CO4	10 ennanc	e knowledge i	n DRA	IM Cell.						nalyze	
		1							(Le	evel-IV)	
Semester		6 th				Autur	nn				
		Lecture	Τι	ıtorial	Pra	ctical	Credits		Total	Teaching	
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	ith course										
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Equivaler											
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proposed											
and old co											
Text Bool 1.	Title		Doci	gn of Analog CMO	S Inte	ogratod	Circuite				
1.	Auth			ad Razavi	5 1110	egrateu	circuits				
		isher	-	raw Hill Educatio	n						
	Editi		2000		11						
2.	Title			, S Analog Circuit I	Desig	n					
2.	Auth			ip Allen and Doug	<u> </u>		·σ				
		isher	OUP	*	<u></u>		0				
	Editi			dition, 2011							
3.	Title			iconductor Memo	ry De	vices ar	nd Circuit	S			
	Auth	or		ieng Yu	- V						
	Publ	isher		Press							
	Editi	on	1 st e	dition							
4.	Title		Mem	ory Devices							
	Auth	or	Davi	d R. Coelho							
	Publ	isher	Kluv	ver Academic Pub	lishe	rs, Sprir	iger				
	Editi	on	1989)							
Reference											
1.	Title			ration and Modell	ing of	f the MC	S Transis	stor			
	Auth			nis Tsividis							
		isher		rd University Pre	SS						
	Editi		2 nd e	dition, 2003							
Course	UNI								-		
Contents				rs, Simple MOSFE					0		
	Capa	citance mode	I, MO	SFET basics, Devi	ice St	ructure	and Ope	ratio	n, Gene	ral	

	Considerations, MOS I/V Characteristics, Finite Output Resistance in Saturation, Transconductance, Second Order effects: body effect, Channel length modulation, Subthreshold conduction, MOS small signal models, SPICE, Short Channel Effects: DIBL, velocity saturation, hot carrier, impact ionization, surface scattering.	
	UNIT II: Amplifiers: Basic concepts, Single Stage Amplifiers: Basic Concepts, Common Source Stage: resistive load, diode connected load, current source load, triode load, source degeneration. Source Follower, Common Gate Stage, Cascode Stage. Folded cascode. Differential Amplifiers: Single Ended and Differential Operation, Basic Differential Pair, Common Mode Response, Differential Pair with MOS loads, Gilbert Cell.	9
	UNIT III: Basics of CMOS circuit design, sensing circuitry basics, Read/write assist circuitry and other peripheral circuitries, Next generation SRAM cell.	9
	UNIT IV: Introduction to DRAM, High speed DRAM architectures, Open and folded arrays organizations, Bandwidth, latency, and Cycle time, Power, Timing circuits.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

	ode: OEVL	-	Elective	HM Course:	PC	Course:	(Y/N)	PE	Course: (Y/N)		
704		Course:	(Y/N)	(Y/N)	N			NT				
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	ordinator	DATAC	UMMUN	ICATION AND NE		JKKING						
Course Ob		To build	1 fundam	ental concept of	data	charing	notworl	zina	and prot	ocols and		
Course of	Jecuves			to make able to pe								
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		the info								rstand		
CO1	network, ar				. 01	uutu, tu		01	(Level-II)			
CO2				ots of signals, mod	lulati	on scher	ne and lii	nk		ply		
	layer proto		-	0					-	el-III)		
CO3				ta communication	ns an	d their	correctio	n,		lyze		
	networks cl	lasses and	d devices	standards.					(Leve	el-IV)		
CO4	Evaluation	of Data liı	nks, Netw	orks and Transpo	ort La	yers ECI	3 providii	ng	Eval	uate		
	more focus	on Intern	iet and ne	etwork performar	ice.				(Lev	el-V)		
Semester		7 th				Autun	nn					
		Lecture	e T	utorial	Pra	ctical	Credits	5	Total	Teaching		
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Prerequis	site course						•					
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Text Book				1.0								
1.	Title			d Computer Com	muni	cations						
	Author			n Stallings								
	Publish											
2	Edition		10 th EDITION									
2.	Title Author		-	ter Networks	arall							
	Publish		AS Tan Prentic	enbaum, DJ Wethe	tidil							
	Edition			tion, 2010								
Reference												
1.	Title		Data Co	mmunication and	Net	work						
1 1	Author			z A. Forouzan								
	Publish		McGrav									
	Edition			tion, 2012								
Course	UNIT I:											
Contents	-		cation.	Networks, Prot	ocols	and	Standard	ls.	Standard	S		
				guration, Topolog				,				
				history and deve								
				OSI reference m	-		-					
	Networ	ks topol	ogies, typ	oes of networks	(LAN	, MAN,	WAN, cii	rcuit	-switched	,		
	-		, message	e switched, extran	et, int	ranet, Ir	iternet, w	vired	, wireless)		
	UNIT I		_			_				9		
				signals, Compos						_		
	layer:	line enco	oding, bl	ock encoding, s	craml	oling, a	nd Differ	rent	types of			

	transmission media. Data Link Layer services: framing, error control, flow control, medium access control. Error & Flow control mechanisms: stop and wait, Go back N and selective repeat. MAC protocols: Aloha, slotted aloha, CSMA, CSMA/CD, CSMA/CA, polling, token passing, scheduling.	
	UNIT III: Guided Media, Unguided Media, Transmission Impairments, Performance Wavelength, Shannon Capacity, Media Comparison, PSTN, Switching, Local Area Network Technology: Token Ring. Error detection (Parity, CRC), Ethernet, Fast Ethernet, Gigabit Ethernet, Personal Area Network: Bluetooth and Wireless Communications Standard: Wi-Fi (802.11) and WiMAX	9
	UNIT IV: Network layer: Internet Protocol, IPv6, ARP, DHCP, ICMP, Routing algorithms: Distance vector, Link state, Metrics, Inter-domain routing. Subnetting, Super netting, Classless addressing, Network Address Translation. Networks and devices: Network classes, Repeaters, Hub, Bridges, Switches, Routers, Gateways Brouters Routing Algorithms, Distance Vector Routing, Link State Routing, Transport layer: UDP, TCP. Connection establishment and termination, sliding window, flow and congestion control, timers, retransmission, TCP extensions, Queuing theory, Single and multiple server queuing models, Little's formula. Application Layer. Network Application services and protocols including e-mail, www, DNS, SMTP.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

	ode: OEVL	Open Elec		HM Course:	PC (Course:	(Y/N)	PE Cours	se: (Y/N)
705		Course: (Y)	/N)	<u>(Y/N)</u> N	N			N	
Type of C	nurco	-	rco	IN	IN			IN	
Course Ti		Theory Course MICRO-ELECTRONICS AND VLSI TECHNOLOGY							
	ordinator	MICKO-ELI		JNICS AND VLSI	LCI		1		
Course Ol		To educate	tha las	arners about the f	ahric	ation nr	ocess and	nrocess i	ntegration for
course or	Jeenves			manufacturing a		-		-	-
Course O	itcomes	the re desig	ii uiiu	indificite tailing a	nu en		e mouern		itive Levels
		and the conc	epts of	f clean room envi	ronm	ent for	Fabricatio	on Ui	nderstand
CO1				cept of cleaning					Level-II)
		rs for IC fabri			1				. ,
CO2	To develop	skills for sim	ulatin	g the various fab	ricati	on proce	esses.		Apply
	-			-		-		(1	Level-III)
CO3	To underst	and the proc	ess int	tegration flow for	· diffe	erent IC	fabricatio	on Ui	nderstand
	technologie	es.						(Level-II)
CO4	Examine th	e current dev	velopn	nents in VLSI tech	nolog	gy.			Analyze
		•				1		(1	Level-IV)
Semester		7 th				Autun	nn		
		Lecture	Tu	itorial	Pra	ctical	Credits	Tota	l Teaching
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	Diffusion and Oxidation, two-dimensional LOCOS simulation example, Epitaxy, Epitaxial doping model, Lithography, Optical projection lithography, Electron-beam lithography, Etching and deposition, future trends.						
	UNIT III: Transistors and layouts - Transistors, Wires and Vias, Design Rules, Layout Design and Stick Diagrams - example, Logic Gate – Pseudo NMOS, DCVS, Domino. Delay through Resistive Interconnect. CMOS Inverter: Basic Circuit and DC Operation – DC Characteristics.						
	UNIT IV: Inverter Switching Characteristics- Static behavior- Switching threshold, Noise Margin, CMOS Inverter Dynamic Behavior- capacitances, propagation delay - High-to-Low time, Low to High time, Sources of Power Consumption, Power Consumption Static and dynamic. Logic Gate - Switch Logic.	9					
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%						

	Code: OEVL	-		HM Course:	PC Course:	(Y/N)	PE Course	:: (Y/N)		
706		Course: (Y/N)	(Y/N)	N		NT			
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Type of C		2	Theory Course EMBEDDED AND REAL TIME OPERATING SYSTEMS							
Course T		FWRFDD	ED ANL	O REAL TIME OPI	ERATING SYS	STEMS				
	oordinator	T. 1. 11.1.4	1					11.1		
Course O	bjectives			ept and understar perating systems			oles of Embec	ided system		
Course O	utcomes						Cognitive I	Levels		
CO1			nd the Real-Life applications of Embedded System, Real Understan ng Systems (RTOS). (Level-II							
CO2				and scheduling	Task Oper	rations	`	lyze		
02	-	es and Mess			, lask ope	au0115,		el-IV)		
CO3	To Analyz	e the kerne	l objects	s in RTOS Service	s, Timer and	l Timer	Ana	lyze		
	Services, I	/O Subsyste	ms.				(Leve	el-IV)		
CO4	Evaluate	the Mem	ory M	lanagement, Sy	nchronizatio	n and	Eval	uate		
	Communic	ation, Dead	locks				(Lev	el-V)		
Semester	•	6 th			Sprin	g				
		Lecture	Τι	ıtorial	Practical	Credit	s Total	Teaching		
Contact H	lours						Hours			
		3	0		0	3	36			
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codes w names	vith course									
Equivale	nt course									
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and old c										
Text Boo	ks	1								
1.	Title		Real T	'ime Concepts for	Embedded S	ystems				
	Auth	or	Qing L	,i						
	Publ	isher								
	Editi	on								
2.	Title		Embe	dded Systems- Ar	chitecture, P	rogramm	ing and Desi	gn		
	Auth	or	Rajkai	mal						
	Publ	isher	TMH							
	Editi	on	2007							
Referenc			1							
1.	Title			dded Linux: Hard	ware, Softwa	re and In	iterfacing			
	Auth			aig Hollabaugh						
		isher		on-Wesley Profes	sional					
	Editi		2002							
Course	UNI				D . 17	. .	6 -			
Contents		-		nbedded system,	Basics of De	veloping	tor Embedd	led		
	-		-	em Initialization.		Jar O	ianta Cristi	9		
		-		Defining RTOS,						
				, Defining a Task				ISK		
	UNI		icture, S	ynchronization, C	ommunicati	ni aliu U	mean ency.			
			hores (Operations and U	so Defining	Massage	Allalla State	9		
				tions and Use.	se, Deminig	message	Queue, sidle	,		
	UNI		, opera					9		
	UNI									

	Other Kernel Objects: Pipes, Event Registers, Signals, Condition Variables, Building Blocks, Component Configuration, Basic I/O Concepts, I/O Subsystem, Port-mapped v/s Memory mapped I/O and DMA, Exceptions and Interrupts, Applications, Processing of Exceptions and Spurious Interrupts, Real Time Clocks, Programmable Timers, Timer Interrupt Service Routines (ISR), Soft Timers, Operations, RT Linux, Micro C/OS-II, Vx Works, Embedded Linux, Tiny OS, and Basic Concepts of Android OS.	
	UNIT IV: Memory management, Dynamic Memory Allocation in Embedded Systems, Fixed size memory management in Embedded systems, Blocking v/s Non- blocking memory functions, Synchronizations and Communications, Resource Classification, Deadlocks Detection and Recovery, Priority Inversions.	9
Course Assessment	Continuous Evaluation 25% Mid Semester 25% End Semester 50%	

Course Co CSVB 306		Allied Engineering Course: (Y/N)	HM Course: (Y/N)	DC (Course:	(Y/N)	DI	E Course: (Y/N)
		Y	N	N			Ν	
Type of C	ourse	Theory Course	and Lab	•				
Course Ti	tle	DATA STRUCT	URE AND PROGRA	MMI	NG			
Course Co	ordinator							
Course Ol	ojectives	programming. ' skills in stude	The goals of the control of the cont	ourse ove th	are to neir pro	develop oficiency	the in	ation in computer basic programming applying the basic to their field of
Course Ou	utcomes						Cog	gnitive Levels
CO1	Recognize their charae		erent data structu	res ar	nd unde	erstand		Understand (Level-II)
CO2		-	ons for maintain associated algorit	-				Understand (Level-II)
CO3		ry and general tr	tures including st ee structures, sear					Apply (Level-III)
CO4	Design, ana searching t	•	e different algorit	hms f	or sorti	ng and		Evaluate (Level-V)
Semester		3 rd			Autur	nn		
Contact H	ours	Lecture	ſutorial	Pra	Practical Credit		S	Total Teaching Hours
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-	site course ith course			1		•		
Equivaler codes proposed and old co	as per course							
Text Bool	KS							
1.	Title	I	In Introduction to I	Data S	tructur	es with A	Appli	cations
	Autho	or 7	rembley & Sorenso	on				
	Publi	sher 7	ЪН					
	Editio	on 2	E/E, 1991					
2.	Title	I	oata Structures usin	ng C a	nd C++			
	Autho	or 7	`anenbaum & Auge	nsteir	ı			

	Publisher	Pearson							
	Edition	2/E, 2007							
3.	Title	The C PROGRAMMING LANGUAGE							
	Author	B.W. Kernighan & D.M. Richie							
	Publisher Prentice Hall								
	Edition	2/E, 1988							
Reference Bool	ks								
1.	Title	Fundamentals of Data Structures							
	Author	E. Horowitz and S. Sahni							
	Publisher	Computer Science Press							
	Edition	2 nd Edition, 2008							
2.	Title	Let Us C							
	Author	Y. Kanetkar							
	Publisher	Infinity Science Press							
	Edition	13 th Edition, 2012							
Course Contents	UNIT I: INTRODU STRUCTURES	CTION TO COMPUTER PROGRAMMING AND DATA							
	Introduction to programming language, Basics of C, Basic Data types – int, float, double, char, Bool, Void. Arithmetic and logical operators: precedence and associativity. Flow of Control- Conditional statements- If-else, Switch-case constructs, Loops- While, do-while, for. 08								
	Definition, Characteristics, Creation and manipulation of data structures, Operations on data structures, Types of data structures. Introduction to algorithms, Asymptotic notations, Analysis of algorithms, Time and Space complexity.								
	UNIT II: ARRAY AN	D LINKED LISTS							
	Arrays, Dynamic memory allocation, one-dimensional array, multi- dimensional array, types of arrays, operations on arrays, row major representation, column major representation, Searching Methods, Linear Search, Binary Search.								
	LINEAR LISTS, Sequential and Linked Representations of Linear Lists, Comparison of Insertion, Deletion and Search Operations for Sequential and Linked Lists, Doubly Linked Lists, Circular Lists, Applications of Lists.								
	UNIT III: STACKS A	ND QUEUES							
	STACKS: Sequential and Linked Implementations, Representative Applications such as Recursion: Tail Recursion, non-tail recursion, nested recursion, indirect recursion, Expression Evaluation Viz., Infix, Prefix and Postfix, Parenthesis Matching, Towers of Hanoi.								
		ntation of Queues-array and linked list, Operations of eue, Priority Queue, Dequeue, Applications of Queues.							

	UNIT IV: GRAPHS AND TREES							
	GRAPHS: Definition, Terminology, Directed and Undirected Graphs, Properties, Connectivity in Graphs, Applications, Adjacency Matrix and Linked Adjacency Chains, Graph Traversal, Breadth First and Depth First Traversal, Spanning Trees, Shortest Path and Transitive Closure, Activity							
	Networks, Topological Sort and Critical Paths.	08						
	TREES: Binary Trees and Their Properties, Terminology, Sequential and Linked Implementations, Tree Traversal Methods and Algorithms, Complete Binary Trees, General Trees, Binary Search Trees, AVL Trees, Threaded Trees, Heaps, Heap Implementation, Insertion and Deletion Operations, Heapsort. MULTIWAY TREES: M-Way Search Trees, B Trees, Search, Insert and Delete Operations, Height of B-Tree, 2-3 Trees.							
	UNIT V: SORTING							
	SORTING: Sorting Methods, Bubble Sort, Selection Sort, Quick Sort, Radix Sort, Bucket Sort, Dictionaries, Hashing, Analysis of Collision Resolution Techniques, Character Strings and Different String Operations. Algorithm design techniques: Greedy programming, Dynamic programming	08						
Course	Continuous Evaluation 25%							
Assessment	Mid Semester 25%							
	End Semester 50%							
Tentative List	To be displayed at the beginning of the semester by the concerned course In-Ch	arge.						
of Experiments	Introduction to Programming Logic Building							
	Basic Concepts of a Computer Programming Language							
	Implementation of sequential constructs							
	Implementation of selection constructs							
	Implementation of Iterative constructs							
	 Implementation of functions (normal functions, recursive function parameter passing methods) 	ons and						
	 Implementation of Array and its applications 							
	Implementation of Stack and its applications							
	Implementation of Queue and its applications							
	Implementation of Link List and its applications							
	 Implementation of Trees and its applications 							
	• Implementation of Graph and its applications							